



IRF Series Data Sheet

The IRF Data Sheet describes 32 devices, 28 N-Channel and 4 P-Channel, all contained in the TO-204AA or TO-204AE package. This data sheet is arranged to show common tabular and graphical information between devices.

Absolute maximum ratings and parametric data are presented in tabular format with devices grouped according to generically shared parameters. For each parametric rating, devices are categorized by N and P channel and listed in alpha-numeric order. The conditions specified for a given parametric test are provided in the right hand column of each table.

Graphical information is grouped by devices in

alpha-numeric order. Where the information is device specific, we have assigned a numeric character for the graph and an alpha character to a given device. (See Table A below). Where graphs are polarity specific as in figures 10, 12, 14 and 15, we have indicated N-Channel or P-Channel. The Thermal Impedance Graph (Fig. 11) is the only exception where a graph is common to both N-Channel and P-Channel devices since the thermal impedance is only dependent on the die size and package.

In Table A below, a legend is provided cross referencing the part number to its assigned alpha code. A given device will retain this alpha code for each device specific graph.


Table A

DEVICE	ALPHA DESIGNATION	DEVICE	ALPHA DESIGNATION
IRF034	a	IRF460	q
IRF044	b	IRFAC30	r
IRF054	c	IRFAC40	s
IRF130	d	IRFAE30	t
IRF140	e	IRFAE40	u
IRF150	f	IRFAE50	v
IRF230	g	IRFAF30	w
IRF240	h	IRFAF40	x
IRF250	i	IRFAF50	y
IRF330	j	IRFAG30	z
IRF340	k	IRFAG40	aa
IRF350	l	IRFAG540	bb
IRF360	m	IRF9130	cc
IRF430	n	IRF9140	dd
IRF440	o	IRF9230	ee
IRF450	p	IRF9240	ff



HEXFET, Mil-Qualified

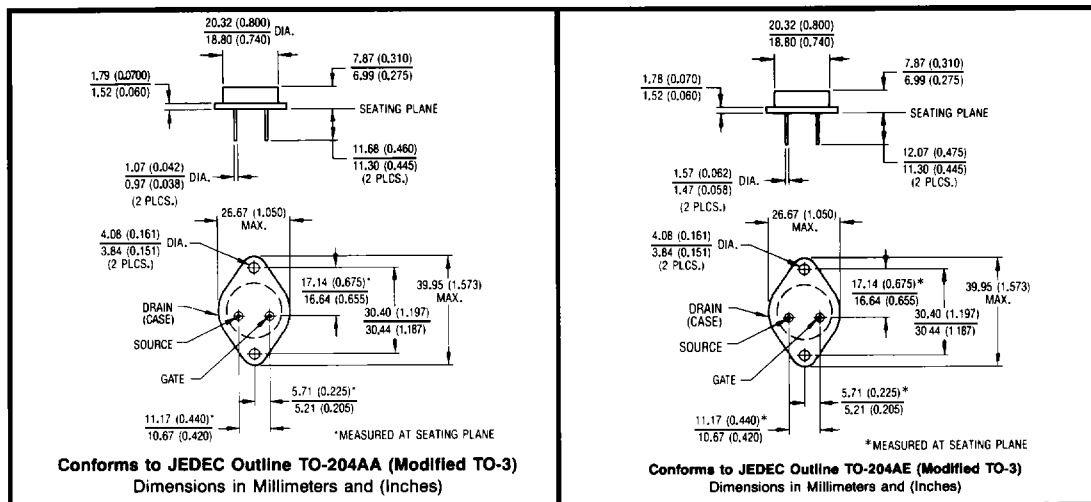
T03/HEXFET/N-Channel

Part Numbers			Hexfet Cross Reference	Voltage	Current T _c = 25°C (A)	MIL-S-19500	Qualification	Case Style	
JEDEC	JANTX	JANTXV							
2N6756	JANTX2N6756	JANTXV2N6756	IRF130	100V	14.0	/542	19500-488-81	TO-204AA TO-3 	
2N6758	JANTX2N6758	JANTXV2N6758	IRF230	200V	9.0	/542	19500-488-81		
2N6760	JANTX2N6760	JANTXV2N6760	IRF330	400V	5.5	/542	19500-488-81		
2N6762	JANTX2N6762	JANTXV2N6762	IRF430	500V	4.5	/542	19500-488-81		
2N6764	JANTX2N6764	JANTXV2N6764	IRF150	100V	38.0	/543	19500-490-81		
2N6766	JANTX2N6766	JANTXV2N6766	IRF250	200V	30.0	/543	19500-490-81		
2N6768	JANTX2N6768	JANTXV2N6768	IRF350	400V	14.0	/543	19500-960-82		
2N6770	JANTX2N6770	JANTXV2N6770	IRF450	500V	12.0	/543	19500-960-82		
T03/HEXFET/P-Channel									
2N6804	JANTX2N6804	JANTXV2N6804	IRF9130	-100V	-12.0	/562	19500-811-86		
2N6806	JANTX2N6806	JANTXV2N6806	IRF9230	-200V	-6.5	/562	19500-811-86		

FOR OTHER GOVERNMENT/SPACE QUALIFIED PRODUCTS REFER TO SECTION E.

RADIATION HARDENED

For Radiation Hardened HEXFETs contained in the TO-204AA/TO-204AE package outline, refer to the RAD HARD SECTION Pages H-1 to H-74.



INTERNATIONAL RECTIFIER

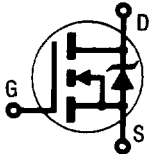


REPETITIVE AVALANCHE AND dv/dt RATED

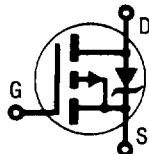
HEXFET[®] TRANSISTORS

IRF SERIES

IRF034 THRU IRFAG50
IRF9130 THRU IRF9240



N-CHANNEL



P-CHANNEL

Description

The HEXFET[®] technology is the key to International Rectifier's advanced line of power MOSFET transistors. The efficient geometry and unique processing of this latest "State of the Art" design achieves: very low on-state resistance combined with high transconductance; superior reverse energy and diode recovery dv/dt capability.

The HEXFET transistors also feature all of the well established advantages of MOSFETs such as voltage control, very fast switching, ease of paralleling and temperature stability of the electrical parameters.

They are well suited for applications such as switching power supplies, motor controls, inverters, choppers, audio amplifiers and high energy pulse circuits.

Features

- Repetitive Avalanche Ratings
- Dynamic dv/dt Rating
- Hermetically Sealed
- Simple Drive Requirements
- Ease of Paralleling

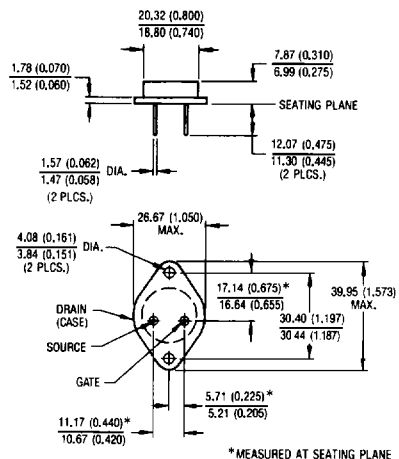
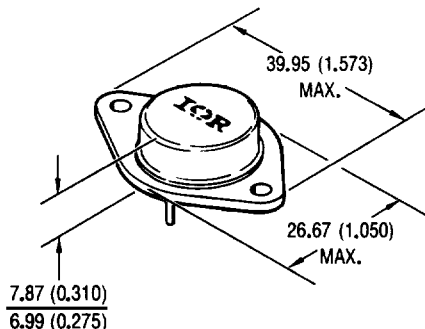
Product Summary N-Channel

Characteristic	IRF034 thru IRFAG50	Units
BV _{DSS}	60 to 1000	V
R _{DS(on)}	0.022 to 6.5	Ω
I _D	1.5 to 45	A

Product Summary P-Channel

Characteristic	IRF9130 and IRF9240	Units
BV _{DSS}	-100 and -200	V
R _{DS(on)}	0.20 and 0.80	Ω
I _D	-6.5 and -18	A

CASE STYLE AND DIMENSIONS



Conforms to JEDEC Outline TO-204AA & TO-204AE (TO-3)
Dimensions in Millimeters and (Inches)



N-Channel — Absolute Maximum Ratings

Parameter	Part Number				Units
	IRF034	IRF044	IRF054	IRF130	
$I_D @ V_{GS} = 0V, T_C = 25^\circ C$	25	44	45*	14	A
$I_D @ V_{GS} = 0V, T_C = 100^\circ C$	16	27	31	9.0	
I_{DM}	100	176	220	56	
$P_D @ T_C = 25^\circ C$	75	125	150	75	W
	0.60	1.0	1.2	0.60	W/K ⑤
V_{GS}	±20				V
E_{AS}	19	340	480	75	mJ
I_{AR}	—	—	—	14	A
E_{AR}	—	—	—	7.5	mJ
dv/dt	4.5	4.5	4.5	5.5	V/ns
T_J T_{STG}	-55 to 150				°C
	300 (0.63 in. (1.6 mm) from case for 10s)				
	11.5 (typical)				
					g

* Current limited by pin diameter

N-Channel — Absolute Maximum Ratings (continued)

Parameter	Part Number				Units
	IRF140	IRF150	IRF230	IRF240	
$I_D @ V_{GS} = 0V, T_C = 25^\circ C$	28	38	9.0	18	A
$I_D @ V_{GS} = 0V, T_C = 100^\circ C$	20	24	6.0	11	
I_{DM}	112	152	36	72	
$P_D @ T_C = 25^\circ C$	125	150	75	125	W
	1.0	1.2	0.6	1.0	W/K ⑤
V_{GS}	±20				V
E_{AS}	250	150	54	450	mJ
I_{AR}	28	38	9.0	18	A
E_{AR}	12.5	15	7.5	12.5	mJ
dv/dt	5.5	5.5	5.0	5.0	V/ns
T_J T_{STG}	-55 to 150				°C
	300 (0.63 in. (1.6 mm) from case for 10s)				
	11.5 (typical)				
					g

Notes – See page I-34.

N-Channel — Absolute Maximum Ratings (continued)

Parameter	Part Number				Units
	IRF250	IRF330	IRF340	IRF350	
$I_D @ V_{GS} = 0V,$ $T_C = 25^\circ C$	30	5.5	10	14	A
$I_D @ V_{GS} = 0V,$ $T_C = 100^\circ C$	19	3.5	6.0	9.0	
I_{DM}	120	22	40	56	
$P_D @ T_C = 25^\circ C$	150	75	125	150	W
	1.2	0.6	1.0	1.2	W/K ^⑤
V_{GS}	± 20				V
E_{AS}	200	1.7	5.7	11.3	mJ
I_{AR}	30	5.5	10	14	A
E_{AR}	15	—	—	15	mJ
dv/dt	5.0	4.0	4.0	4.0	V/ns
T_J T_{STG}	-55 to 150				°C
	300 (0.63 in. (1.6 mm) from case for 10s)				
	11.5 (typical)				
	11.5 (typical)				g

N-Channel — Absolute Maximum Ratings (continued)

Parameter	Part Number				Units
	IRF360	IRF430	IRF440	IRF450	
$I_D @ V_{GS} = 0V,$ $T_C = 25^\circ C$	25	4.5	8.0	12	A
$I_D @ V_{GS} = 0V,$ $T_C = 100^\circ C$	16	3.0	5.0	7.75	
I_{DM}	100	18	32	48	
$P_D @ T_C = 25^\circ C$	300	75	125	150	W
	2.4	0.6	1.0	1.2	W/K ^⑤
V_{GS}	± 20				V
E_{AS}	980	1.1	3.6	8.0	mJ
I_{AR}	25	4.5	8.0	12	A
E_{AR}	30	—	—	—	mJ
dv/dt	4.0	3.5	3.5	3.5	V/ns
T_J T_{STG}	-55 to 150				°C
	300 (0.63 in. (1.6 mm) from case for 10s)				
	11.5 (typical)				
	11.5 (typical)				g

Notes — See page I-34.

N-Channel — Absolute Maximum Ratings (continued)

Parameter	Part Number				Units
	IRF460	IRFAC30	IRFAC40	IRFAE30	
$I_D @ V_{GS} = 0V,$ $T_C = 25^\circ C$	21	3.6	6.2	3.1	A
$I_D @ V_{GS} = 0V,$ $T_C = 100^\circ C$	14	2.3	3.9	2.0	
I_{DM}	84	14	25	12	
$P_D @ T_C = 25^\circ C$	300	75	125	75	W
	2.4	0.6	1.0	0.6	W/K ^⑤
V_{GS}	±20				V
E_{AS}	1200	180	570	100	mJ
I_{AR}	21	3.6	6.2	3.1	A
E_{AR}	30	7.5	12.5	7.5	mJ
dv/dt	3.5	3.0	3.0	2.0	V/ns
T_J T_{STG}	-55 to 150				°C
	300 (0.63 in. (1.6 mm) from case for 10s)				
	11.5 (typical)				
					g

N-Channel — Absolute Maximum Ratings (continued)

Parameter	Part Number				Units
	IRFAE40	IRFAE50	IRFAF30	IRFAF40	
$I_D @ V_{GS} = 0V,$ $T_C = 25^\circ C$	4.8	7.1	2.0	4.3	A
$I_D @ V_{GS} = 0V,$ $T_C = 100^\circ C$	3.0	4.5	1.7	2.7	
I_{DM}	19	28	8.0	17	
$P_D @ T_C = 25^\circ C$	125	150	75	125	W
	1.0	1.2	0.6	1.0	W/K ^⑤
V_{GS}	±20				V
E_{AS}	550	830	100	530	mJ
I_{AR}	4.8	7.1	2.0	4.3	A
E_{AR}	12.5	15	7.5	12.5	mJ
dv/dt	2.0	2.0	1.5	1.5	V/ns
T_J T_{STG}	-55 to 150				°C
	300 (0.63 in. (1.6 mm) from case for 10s)				
	11.5 (typical)				
					g

Notes — See page I-34.

N-Channel — Absolute Maximum Ratings (continued)

Parameter	Part Number				Units
	IRFAF50	IRFAG30	IRFAG40	IRFAG50	
$I_D @ V_{GS} = 0V,$ $T_C = 25^\circ C$ Continuous Drain Current	6.2	2.3	3.9	5.6	A
$I_D @ V_{GS} = 0V,$ $T_C = 100^\circ C$ Continuous Drain Current	4.0	1.5	2.5	3.5	
I_{DM} Pulsed Drain Current ①	25	9.2	16	22	
$P_D @ T_C = 25^\circ C$ Max. Power Dissipation	150	75	125	150	W
Linear Derating Factor	1.2	0.6	1.0	1.2	W/K ⑤
V_{GS} Gate-to-Source Voltage	±20				V
E_{AS} Single Pulse Avalanche Energy ② (See Fig. 12)	870	110	530	860	mJ
I_{AR} Avalanche Current ① (See E_{AR})	6.2	2.3	3.9	5.6	A
E_{AR} Repetitive Avalanche Energy ① (See Fig. 15)	15	7.5	12.5	15	mJ
dv/dt Peak Diode Recovery dv/dt ③ (See Fig. 15)	1.5	1.0	1.0	1.0	V/ns
T_J T_{STG} Operating Junction and Storage Temperature Range	-55 to 150				°C
Lead Temperature	300 (0.63 in. (1.6 mm) from case for 10s)				
Weight	11.5 (typical)				

P-Channel — Absolute Maximum Ratings

Parameter	Part Number				Units
	IRF9130	IRF9140	IRF9230	IRF9240	
$I_D @ V_{GS} = 0V,$ $T_C = 25^\circ C$ Continuous Drain Current	-11	-18	-6.5	-11	A
$I_D @ V_{GS} = 0V,$ $T_C = 100^\circ C$ Continuous Drain Current	-7.0	-11	-4.0	-7.0	
I_{DM} Pulsed Drain Current ①	-50	-72	-28	-44	
$P_D @ T_C = 25^\circ C$ Max. Power Dissipation	75	125	75	125	W
Linear Derating Factor	0.6	1.0	0.6	1.0	W/K ⑤
V_{GS} Gate-to-Source Voltage	±20				V
E_{AS} Single Pulse Avalanche Energy ② (See Fig. 12)	81	500	66	500	mJ
I_{AR} Avalanche Current ① (See E_{AR})	-11	-18	-6.5	-11	A
E_{AR} Repetitive Avalanche Energy ① (See Fig. 15)	7.5	12.5	7.5	12.5	mJ
dv/dt Peak Diode Recovery dv/dt ③ (See Fig. 15)	-5.5	-5.5	-5.0	-5.0	V/ns
T_J T_{STG} Operating Junction and Storage Temperature Range	-55 to 150				°C
Lead Temperature	300 (0.63 in. (1.6 mm) from case for 10s)				
Weight	11.5 (typical)				

Notes – See page I-34.



Electrical Characteristics @ $T_C = 25^\circ\text{C}$ (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
BV _{DSS} Drain-to-Source Breakdown Voltage	N-Channel	IRF034	60	—	—	V	V _{GS} = 0V, I _D = 1.0 mA
		IRF044	60	—	—		
		IRF054	60	—	—		
		IRF130	100	—	—		
		IRF140	100	—	—		
		IRF150	100	—	—		
		IRF230	200	—	—		
		IRF240	200	—	—		
		IRF250	200	—	—		
		IRF330	400	—	—		
		IRF340	400	—	—		
		IRF350	400	—	—		
		IRF360	400	—	—		
		IRF430	500	—	—		
		IRF440	500	—	—		
		IRF450	500	—	—		
		IRF460	500	—	—		
		IRFAC30	600	—	—		
		IRFAC40	600	—	—		
		IRFAE30	800	—	—		
		IRFAE40	800	—	—		
		IRFAE50	800	—	—		
		IRFAF30	900	—	—		
	IRFAF40	900	—	—			
	IRFAF50	900	—	—			
IRFAG30	1000	—	—				
IRFAG40	1000	—	—				
IRFAG50	1000	—	—				
	P-Channel	IRF9130	-100	—	—	V _{GS} = 0V, I _D = -1.0 mA	
		IRF9140	-100	—	—		
		IRF9230	-200	—	—		
		IRF9240	-200	—	—		

Notes – See page I-34.



Electrical Characteristics @ $T_C = 25^\circ\text{C}$ (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
$\Delta BV_{DSS}/\Delta T_J$ Temperature Coefficient of Breakdown Voltage	N-Channel	IRF034	—	0.68	—	V/°C	Reference to 25°C, $I_D = 1.0\text{ mA}$
		IRF044	—	0.68	—		
		IRF054	—	0.68	—		
		IRF130	—	0.13	—		
		IRF140	—	0.13	—		
		IRF150	—	0.13	—		
		IRF230	—	0.29	—		
		IRF240	—	0.29	—		
		IRF250	—	0.29	—		
		IRF330	—	0.46	—		
		IRF340	—	0.46	—		
		IRF350	—	0.46	—		
		IRF360	—	0.46	—		
		IRF430	—	0.78	—		
		IRF440	—	0.78	—		
		IRF450	—	0.78	—		
		IRF460	—	0.78	—		
		IRFAC30	—	0.70	—		
		IRFAC40	—	0.70	—		
		IRFAE30	—	0.98	—		
		IRFAE40	—	0.98	—		
		IRFAE50	—	0.98	—		
		IRFAF30	—	1.2	—		
	IRFAF40	—	1.2	—			
	IRFAF50	—	1.2	—			
	IRFAG30	—	1.4	—			
	IRFAG40	—	1.4	—			
IRFAG50	—	1.4	—				
P-Channel	IRF9130	—	-0.087	—	Reference to 25°C, $I_D = -1.0\text{ mA}$		
	IRF9140	—	-0.087	—			
	IRF9230	—	-0.20	—			
	IRF9240	—	-0.20	—			

Notes – See page I-34.

IRF Series Devices



Electrical Characteristics @ T_C = 25°C (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
R _{DS(on)} Static Drain-to-Source On-State Resistance ④	N-Channel	IRF034	—	—	0.050	Ω	I _D = 16A
			—	—	0.058		I _D = 25A
		IRF044	—	—	0.028		I _D = 27A
			—	—	0.032		I _D = 44A
		IRF054	—	—	0.022		I _D = 31A
			—	—	0.025		I _D = 45A
		IRF130	—	—	0.18		I _D = 9.0A
			—	—	0.21		I _D = 14A
		IRF140	—	—	0.077		I _D = 20A
			—	—	0.089		I _D = 28A
		IRF150	—	—	0.055		I _D = 24A
			—	—	0.065		I _D = 38A
		IRF230	—	—	0.40		I _D = 6.0A
			—	—	0.49		I _D = 9.0A
		IRF240	—	—	0.18		I _D = 11A
			—	—	0.21		I _D = 18A
		IRF250	—	—	0.085		I _D = 19A
			—	—	0.090		I _D = 30A
		IRF330	—	—	1.00		I _D = 3.5A
			—	—	1.22		I _D = 5.5A
		IRF340	—	—	0.55		I _D = 6.0A
			—	—	0.63		I _D = 10A
		IRF350	—	—	0.300		I _D = 9.0A
			—	—	0.400		I _D = 14A
		IRF360	—	—	0.20		I _D = 16A
			—	—	0.23		I _D = 25A
		IRF430	—	—	1.50		I _D = 3.0A
			—	—	1.80		I _D = 4.5A
		IRF440	—	—	0.85		I _D = 5.0A
			—	—	0.98		I _D = 8.0A
		IRF450	—	—	0.400		I _D = 7.75A
			—	—	0.500		I _D = 12A
		IRF460	—	—	0.27		I _D = 14A
			—	—	0.31		I _D = 21A
		IRFAC30	—	—	2.2		I _D = 2.3A
			—	—	2.5		I _D = 3.6A
		IRFAC40	—	—	1.2		I _D = 3.9A
			—	—	1.4		I _D = 6.2A
		IRFAE30	—	—	3.2		I _D = 2.0A
			—	—	3.7		I _D = 3.1A
		IRFAE40	—	—	2.0		I _D = 3.0A
			—	—	2.3		I _D = 4.8A
		IRFAE50	—	—	1.2		I _D = 4.5A
			—	—	1.4		I _D = 7.1A
		IRFAF30	—	—	4.0		I _D = 1.7A
			—	—	4.6		I _D = 2.0A
		IRFAF40	—	—	2.5		I _D = 2.7A
			—	—	2.9		I _D = 4.3A
		IRFAF50	—	—	1.6		I _D = 4.0A
			—	—	1.85		I _D = 6.2A
		IRFAG30	—	—	5.6		I _D = 1.5A
			—	—	6.5		I _D = 2.3A
		IRFAG40	—	—	3.5		I _D = 2.5A
			—	—	4.0		I _D = 3.9A
		IRFAG50	—	—	2.0		I _D = 3.5A
			—	—	2.3		I _D = 5.6A
P-Channel	IRF9130	—	—	0.3	I _D = -7.0A		
		—	—	0.35	I _D = -11A		
	IRF9140	—	—	0.2	I _D = -11A		
		—	—	0.23	I _D = -18A		
	IRF9230	—	—	0.80	I _D = -4.0A		
		—	—	0.92	I _D = -6.5A		
	IRF9240	—	—	0.5	I _D = -7.0A		
		—	—	0.58	I _D = -11A		

Notes – See page I-34.



Electrical Characteristics @ T_C = 25°C (Unless Otherwise Specified) continued

Parameter			Part Number	Min.	Typ.	Max.	Units	Test Conditions
V _{GS(th)}	Gate Threshold Voltage	N-Channel	ALL	2.0	—	4.0	V	V _{DS} = V _{GS} , I _D = 250 mA
		P-Channel	ALL	-2.0	—	-4.0		V _{DS} = V _{GS} , I _D = -250 mA
g _{fs}	Forward Transconductance	N-Channel	IRF034	9.3	—	—	S (Ω)	I _{DS} = 16A
			IRF044	17	—	—		I _{DS} = 27A
			IRF054	20	—	—		I _{DS} = 31A
			IRF130	4.6	—	—		I _{DS} = 9.0A
			IRF140	9.1	—	—		I _{DS} = 20A
			IRF150	9.0	—	—		I _{DS} = 24A
			IRF230	3.0	—	—		I _{DS} = 6.0A
			IRF240	6.1	—	—		I _{DS} = 11A
			IRF250	9.0	—	—		I _{DS} = 19A
			IRF330	2.9	—	—		I _{DS} = 3.5A
			IRF340	4.9	—	—		I _{DS} = 6.0A
			IRF350	6.0	—	—		I _{DS} = 9.0A
			IRF360	14	—	—		I _{DS} = 16A
			IRF430	2.7	—	—		I _{DS} = 3.0A
			IRF440	4.7	—	—		I _{DS} = 5.0A
			IRF450	5.5	—	—		I _{DS} = 7.75A
			IRF460	13	—	—		I _{DS} = 14A
			IRFAC30	2.4	—	—		I _{DS} = 2.3A
			IRFAC40	4.7	—	—		I _{DS} = 3.9A
			IRFAE30	2.5	—	—		I _{DS} = 2.0A
			IRFAE40	3.9	—	—		I _{DS} = 3.0A
			IRFAE50	5.9	—	—		I _{DS} = 4.5A
			IRFAF30	2.3	—	—		I _{DS} = 1.7A
			IRFAF40	3.6	—	—		I _{DS} = 2.7A
		IRFAF50	4.9	—	—	I _{DS} = 4.0A		
		IRFAG30	2.1	—	—	I _{DS} = 1.5A		
		IRFAG40	3.3	—	—	I _{DS} = 2.5A		
		IRFAG50	5.2	—	—	I _{DS} = 3.5A		
		P-Channel	IRF9130	3.0	—	—	I _{DS} = -7.0A	
			IRF9140	6.2	—	—	I _{DS} = -11A	
			IRF9230	2.0	—	—	I _{DS} = -4.0A	
			IRF9240	4.0	—	—	I _{DS} = -7.0A	
I _{DSS}	Zero Gate Voltage Drain Current	N-Channel	ALL	—	—	25	μA	V _{DS} = 0.8 x Max. Rating V _{GS} = 0V
		P-Channel	ALL	—	—	-25		V _{DS} = 0.8 x Max. Rating V _{GS} = 0V, T _J = 125°C
I _{DSS}	Zero Gate Voltage Drain Current	N-Channel	ALL	—	—	250	μA	V _{DS} = 0.8 x Max. Rating V _{GS} = 0V, T _J = 125°C
		P-Channel	ALL	—	—	-250		V _{DS} = 0.8 x Max. Rating V _{GS} = 0V, T _J = 125°C
I _{GSS}	Gate-to-Source Leakage Forward	N-Channel	ALL	—	—	100	nA	V _{GS} = 20V
		P-Channel	ALL	—	—	-100		V _{GS} = -20V
I _{GSS}	Gate-to-Source Leakage Reverse	N-Channel	ALL	—	—	-100	nA	V _{GS} = -20V
		P-Channel	ALL	—	—	100		V _{GS} = 20V

Notes – See page I-34.



Electrical Characteristics @ T_C = 25°C (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
Q _g Total Gate Charge	N-Channel	IRF034	21	—	47	nC	I _D = 25A
		IRF044	39	—	88		I _D = 44A
		IRF054	80	—	180		I _D = 45A
		IRF130	12	—	35		I _D = 14A
		IRF140	30	—	59		I _D = 28A
		IRF150	50	—	125		I _D = 38A
		IRF230	16	—	39		I _D = 9.0A
		IRF240	32	—	60		I _D = 18A
		IRF250	55	—	115		I _D = 30A
		IRF330	17	—	39		I _D = 5.5A
		IRF340	32	—	65		I _D = 10A
		IRF350	52	—	110		I _D = 14A
		IRF360	96	—	210		I _D = 25A
		IRF430	16	—	40		I _D = 4.5A
		IRF440	27.3	—	68.5		I _D = 8.0A
		IRF450	55	—	120		I _D = 12A
		IRF460	84	—	190		I _D = 21A
		IRFAC30	16	—	38		I _D = 3.6A
		IRFAC40	26	—	60		I _D = 6.2A
		IRFAE30	30	—	69		I _D = 3.1A
		IRFAE40	48	—	110		I _D = 4.8A
		IRFAE50	84	—	190		I _D = 7.1A
		IRFAF30	29	—	66		I _D = 2.0A
		IRFAF40	53	—	120		I _D = 4.3A
	IRFAF50	80	—	180	I _D = 6.2A		
	IRFAG30	30	—	68	I _D = 2.3A		
	IRFAG40	53	—	120	I _D = 3.9A		
	IRFAG50	88	—	200	I _D = 5.6A		
	P-Channel	IRF9130	15	—	29	I _D = -11A	
		IRF9140	31	—	60	I _D = -18A	
		IRF9230	8	—	31	I _D = -6.5A	
		IRF9240	28	—	60	I _D = -11A	

V_{GS} = 10V
 V_{DS} = 0.5 x Max. Rating
 See Fig. 6 and 14

V_{GS} = -10V
 V_{DS} = 0.5 x Max Rating

Notes – See page I-34.



Electrical Characteristics @ $T_C = 25^\circ\text{C}$ (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
Q _{gs} Gate-to-Source Charge	N-Channel	IRF034	4.4	—	10	nC	I _D = 25A
		IRF044	6.7	—	15		I _D = 44A
		IRF054	20	—	45		I _D = 45A
		IRF130	2.5	—	10		I _D = 14A
		IRF140	2.4	—	12		I _D = 28A
		IRF150	8	—	22		I _D = 38A
		IRF230	3.0	—	5.7		I _D = 9.0A
		IRF240	2.2	—	10.6		I _D = 18A
		IRF250	8	—	22		I _D = 30A
		IRF330	2.0	—	6.0		I _D = 5.5A
		IRF340	2.2	—	10		I _D = 10A
		IRF350	5.0	—	18		I _D = 14A
		IRF360	11	—	28		I _D = 25A
		IRF430	2.0	—	6.0		I _D = 4.5A
		IRF440	2.0	—	12.5		I _D = 8.0A
		IRF450	5.0	—	19		I _D = 12A
		IRF460	12	—	27		I _D = 21A
		IRFAC30	2.0	—	4.6		I _D = 3.6A
		IRFAC40	3.6	—	8.3		I _D = 6.2A
		IRFAE30	3.1	—	7.1		I _D = 3.1A
		IRFAE40	5.3	—	12		I _D = 4.8A
		IRFAE50	6.6	—	15		I _D = 7.1A
		IRFAF30	3.2	—	7.2		I _D = 2.0A
		IRFAF40	4.8	—	11		I _D = 4.3A
	IRFAF50	7.5	—	17	I _D = 6.2A		
	IRFAG30	2.5	—	6.3	I _D = 2.3A		
	IRFAG40	5.3	—	12	I _D = 3.9A		
	IRFAG50	8.8	—	20	I _D = 5.6A		
	P-Channel	IRF9130	1.0	—	7.1	I _D = -11A	
		IRF9140	3.7	—	13	I _D = -18A	
		IRF9230	0.8	—	7.0	I _D = -6.5A	
		IRF9240	3.0	—	15	I _D = -11A	

V_{GS} = 10V
 V_{DS} = 0.5 x Max. Rating
 See Fig. 6 and 14

V_{GS} = -10V
 V_{DS} = 0.5 x Max. Rating

Notes – See page I-34.



Electrical Characteristics @ $T_C = 25^\circ\text{C}$ (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
Q _{gd} Gate-to-Drain ("Miller") Charge	N-Channel	IRF034	9.7	—	22	nC	I _D = 25A
		IRF044	18	—	52		I _D = 44A
		IRF054	34	—	105		I _D = 45A
		IRF130	5.0	—	15		I _D = 14A
		IRF140	12	—	30.7		I _D = 28A
		IRF150	25	—	65		I _D = 38A
		IRF230	8.0	—	20		I _D = 9.0A
		IRF240	14	—	38		I _D = 18A
		IRF250	30	—	60		I _D = 30A
		IRF330	8.0	—	20		I _D = 5.5A
		IRF340	14	—	41		I _D = 10A
		IRF350	25	—	65		I _D = 14A
		IRF360	53	—	120		I _D = 25A
		IRF430	8.0	—	20		I _D = 4.5A
		IRF440	11	—	42		I _D = 8.0A
		IRF450	27	—	70		I _D = 12A
		IRF460	60	—	135		I _D = 21A
		IRFAC30	7.5	—	17		I _D = 3.6A
		IRFAC40	13	—	30		I _D = 6.2A
		IRFAE30	17	—	40		I _D = 3.1A
		IRFAE40	30	—	68		I _D = 4.8A
		IRFAE50	48	—	110		I _D = 7.1A
		IRFAF30	16	—	37		I _D = 2.0A
		IRFAF40	30	—	68		I _D = 4.3A
	IRFAF50	48	—	110	I _D = 6.2A		
	IRFAG30	16	—	36	I _D = 2.3A		
	IRFAG40	29	—	66	I _D = 3.9A		
	IRFAG50	48	—	110	I _D = 5.6A		
	P-Channel	IRF9130	2.0	—	21	I _D = -11A	
		IRF9140	7.0	—	35.2	I _D = -18A	
IRF9230		5.0	—	17	I _D = -6.5A		
IRF9240		4.5	—	38	I _D = -11A		

V_{GS} = 10V
V_{DS} = 0.5 x Max. Rating
See Fig. 6 and 14

V_{GS} = -10V
V_{DS} = 0.5 x Max. Rating

Notes – See page I-34.



Electrical Characteristics @ T_C = 25°C (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
t _{d(on)} Turn-On Delay Time See Fig. 10	N-Channel	IRF034	—	—	21	ns	V _{DD} = 30V, I _D = 25A, R _G = 7.5Ω
		IRF044	—	—	23		V _{DD} = 30V, I _D = 44A, R _G = 9.1Ω
		IRF054	—	—	33		V _{DD} = 30V, I _D = 45A, R _G = 2.35Ω
		IRF130	—	—	35		V _{DD} = 50V, I _D = 14A, R _G = 7.5Ω
		IRF140	—	—	21		V _{DD} = 50V, I _D = 28A, R _G = 9.1Ω
		IRF150	—	—	35		V _{DD} = 50V, I _D = 38A, R _G = 2.35Ω
		IRF230	—	—	35		V _{DD} = 100V, I _D = 9.0A, R _G = 7.5Ω
		IRF240	—	—	20		V _{DD} = 100V, I _D = 18A, R _G = 9.1Ω
		IRF250	—	—	35		V _{DD} = 100V, I _D = 30A, R _G = 2.35Ω
		IRF330	—	—	30		V _{DD} = 200V, I _D = 5.5A, R _G = 7.5Ω
		IRF340	—	—	25		V _{DD} = 200V, I _D = 10A, R _G = 9.1Ω
		IRF350	—	—	35		V _{DD} = 200V, I _D = 14A, R _G = 2.35Ω
		IRF360	—	—	33		V _{DD} = 200V, I _D = 25A, R _G = 2.35Ω
		IRF430	—	—	30		V _{DD} = 250V, I _D = 4.5A, R _G = 7.5Ω
		IRF440	—	—	21		V _{DD} = 250V, I _D = 8.0A, R _G = 9.1Ω
		IRF450	—	—	35		V _{DD} = 250V, I _D = 12A, R _G = 2.35Ω
		IRF460	—	—	35		V _{DD} = 250V, I _D = 21A, R _G = 2.35Ω
		IRFAC30	—	—	17		V _{DD} = 300V, I _D = 3.6A, R _G = 7.5Ω
		IRFAC40	—	—	20		V _{DD} = 300V, I _D = 6.2A, R _G = 9.1Ω
		IRFAE30	—	—	23		V _{DD} = 400V, I _D = 3.1A, R _G = 7.5Ω
	IRFAE40	—	—	24	V _{DD} = 400V, I _D = 4.8A, R _G = 9.1Ω		
	IRFAE50	—	—	32	V _{DD} = 400V, I _D = 7.1A, R _G = 2.35Ω		
	IRFAF30	—	—	21	V _{DD} = 400V*, I _D = 2.0A, R _G = 7.5Ω		
	IRFAF40	—	—	24	V _{DD} = 400V*, I _D = 4.3A, R _G = 9.1Ω		
	IRFAF50	—	—	33	V _{DD} = 400V*, I _D = 6.2A, R _G = 2.35Ω		
	IRFAG30	—	—	23	V _{DD} = 400V*, I _D = 2.3A, R _G = 7.5Ω		
	IRFAG40	—	—	30	V _{DD} = 400V*, I _D = 3.9A, R _G = 9.1Ω		
	IRFAG50	—	—	30	V _{DD} = 400V*, I _D = 5.6A, R _G = 2.35Ω		
P-Channel	IRF9130	—	—	60	V _{DD} = -50V, I _D = -11A, R _G = 7.5Ω		
	IRF9140	—	—	35	V _{DD} = -50V, I _D = -18A, R _G = 9.1Ω		
	IRF9230	—	—	50	V _{DD} = -100V, I _D = -6.5A, R _G = 7.5Ω		
	IRF9240	—	—	35	V _{DD} = -100V, I _D = -11A, R _G = 9.1Ω		

*Equipment Limitation

Notes – See page I-34.



Electrical Characteristics @ T_C = 25°C (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
t _r Rise Time See Fig. 10	N-Channel	IRF034	—	—	110	ns	V _{DD} = 30V, I _D = 25A, R _G = 7.5Ω
		IRF044	—	—	130		V _{DD} = 30V, I _D = 44A, R _G = 9.1Ω
		IRF054	—	—	180		V _{DD} = 30V, I _D = 45A, R _G = 2.35Ω
		IRF130	—	—	80		V _{DD} = 50V, I _D = 14A, R _G = 7.5Ω
		IRF140	—	—	145		V _{DD} = 50V, I _D = 28A, R _G = 9.1Ω
		IRF150	—	—	190		V _{DD} = 50V, I _D = 38A, R _G = 2.35Ω
		IRF230	—	—	80		V _{DD} = 100V, I _D = 9.0A, R _G = 7.5Ω
		IRF240	—	—	152		V _{DD} = 100V, I _D = 18A, R _G = 9.1Ω
		IRF250	—	—	190		V _{DD} = 100V, I _D = 30A, R _G = 2.35Ω
		IRF330	—	—	40		V _{DD} = 200V, I _D = 5.5A, R _G = 7.5Ω
		IRF340	—	—	92		V _{DD} = 200V, I _D = 10A, R _G = 9.1Ω
		IRF350	—	—	190		V _{DD} = 200V, I _D = 14A, R _G = 2.35Ω
		IRF360	—	—	140		V _{DD} = 200V, I _D = 25A, R _G = 2.35Ω
		IRF430	—	—	40		V _{DD} = 250V, I _D = 4.5A, R _G = 7.5Ω
		IRF440	—	—	73		V _{DD} = 250V, I _D = 8.0A, R _G = 9.1Ω
		IRF450	—	—	190		V _{DD} = 250V, I _D = 12A, R _G = 2.35Ω
		IRF460	—	—	120		V _{DD} = 250V, I _D = 21A, R _G = 2.35Ω
		IRFAC30	—	—	20		V _{DD} = 300V, I _D = 3.6A, R _G = 7.5Ω
		IRFAC40	—	—	27		V _{DD} = 300V, I _D = 6.2A, R _G = 9.1Ω
		IRFAE30	—	—	32		V _{DD} = 400V, I _D = 3.1A, R _G = 7.5Ω
		IRFAE40	—	—	42		V _{DD} = 400V, I _D = 4.8A, R _G = 9.1Ω
		IRFAE50	—	—	68		V _{DD} = 400V, I _D = 7.1A, R _G = 2.35Ω
		IRFAF30	—	—	30		V _{DD} = 400V*, I _D = 2.0A, R _G = 7.5Ω
		IRFAF40	—	—	39		V _{DD} = 400V*, I _D = 4.3A, R _G = 9.1Ω
	IRFAF50	—	—	66	V _{DD} = 400V*, I _D = 6.2A, R _G = 2.35Ω		
	IRFAG30	—	—	42	V _{DD} = 400V*, I _D = 2.3A, R _G = 7.5Ω		
	IRFAG40	—	—	50	V _{DD} = 400V*, I _D = 3.9A, R _G = 9.1Ω		
	IRFAG50	—	—	44	V _{DD} = 400V*, I _D = 5.6A, R _G = 2.35Ω		
	P-Channel	IRF9130	—	—	140		V _{DD} = -50V, I _D = -11A, R _G = 7.5Ω
		IRF9140	—	—	85		V _{DD} = -50V, I _D = -18A, R _G = 9.1Ω
		IRF9230	—	—	100		V _{DD} = -100V, I _D = -6.5A, R _G = 7.5Ω
		IRF9240	—	—	85		V _{DD} = -100V, I _D = -11A, R _G = 9.1Ω

*Equipment Limitation

Notes – See page I-34.



Electrical Characteristics @ T_C = 25°C (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
t _{d(off)} Turn-Off Delay Time See Fig. 10	N-Channel	IRF034	—	—	53	ns	V _{DD} = 30V, I _D = 25A, R _G = 7.5Ω
		IRF044	—	—	81		V _{DD} = 30V, I _D = 44A, R _G = 9.1Ω
		IRF054	—	—	100		V _{DD} = 30V, I _D = 45A, R _G = 2.35Ω
		IRF130	—	—	60		V _{DD} = 50V, I _D = 14A, R _G = 7.5Ω
		IRF140	—	—	21		V _{DD} = 50V, I _D = 28A, R _G = 9.1Ω
		IRF150	—	—	170		V _{DD} = 50V, I _D = 38A, R _G = 2.35Ω
		IRF230	—	—	60		V _{DD} = 100V, I _D = 9.0A, R _G = 7.5Ω
		IRF240	—	—	58		V _{DD} = 100V, I _D = 18A, R _G = 9.1Ω
		IRF250	—	—	170		V _{DD} = 100V, I _D = 30A, R _G = 2.35Ω
		IRF330	—	—	80		V _{DD} = 200V, I _D = 5.5A, R _G = 7.5Ω
		IRF340	—	—	79		V _{DD} = 200V, I _D = 10A, R _G = 9.1Ω
		IRF350	—	—	170		V _{DD} = 200V, I _D = 14A, R _G = 2.35Ω
		IRF360	—	—	120		V _{DD} = 200V, I _D = 25A, R _G = 2.35Ω
		IRF430	—	—	80		V _{DD} = 250V, I _D = 4.5A, R _G = 7.5Ω
		IRF440	—	—	72		V _{DD} = 250V, I _D = 8.0A, R _G = 9.1Ω
		IRF450	—	—	170		V _{DD} = 250V, I _D = 12A, R _G = 2.35Ω
		IRF460	—	—	130		V _{DD} = 250V, I _D = 21A, R _G = 2.35Ω
		IRFAC30	—	—	53		V _{DD} = 300V, I _D = 3.6A, R _G = 7.5Ω
		IRFAC40	—	—	83		V _{DD} = 300V, I _D = 6.2A, R _G = 9.1Ω
		IRFAE30	—	—	120		V _{DD} = 400V, I _D = 3.1A, R _G = 7.5Ω
		IRFAE40	—	—	170		V _{DD} = 400V, I _D = 4.8A, R _G = 9.1Ω
		IRFAE50	—	—	78		V _{DD} = 400V, I _D = 7.1A, R _G = 2.35Ω
		IRFAF30	—	—	140		V _{DD} = 400V*, I _D = 2.0A, R _G = 7.5Ω
		IRFAF40	—	—	170		V _{DD} = 400V*, I _D = 4.3A, R _G = 9.1Ω
	IRFAF50	—	—	200	V _{DD} = 400V*, I _D = 6.2A, R _G = 2.35Ω		
	IRFAG30	—	—	210	V _{DD} = 400V*, I _D = 2.3A, R _G = 7.5Ω		
	IRFAG40	—	—	170	V _{DD} = 400V*, I _D = 3.9A, R _G = 9.1Ω		
	IRFAG50	—	—	210	V _{DD} = 400V*, I _D = 5.6A, R _G = 2.35Ω		
	P-Channel	IRF9130	—	—	140		V _{DD} = -50V, I _D = -11A, R _G = 7.5Ω
		IRF9140	—	—	85		V _{DD} = -50V, I _D = -18A, R _G = 9.1Ω
IRF9230		—	—	100	V _{DD} = -100V, I _D = -6.5A, R _G = 7.5Ω		
IRF9240		—	—	85	V _{DD} = -100V, I _D = -11A, R _G = 9.1Ω		

*Equipment Limitation

Notes – See page I-34.



Electrical Characteristics @ $T_C = 25^\circ\text{C}$ (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
t_f Fall Time See Fig. 10	N-Channel	IRF034	—	—	80	ns	$V_{DD} = 30V, I_D = 25A, R_G = 7.5\Omega$
		IRF044	—	—	79		$V_{DD} = 30V, I_D = 44A, R_G = 9.1\Omega$
		IRF054	—	—	100		$V_{DD} = 30V, I_D = 45A, R_G = 2.35\Omega$
		IRF130	—	—	45		$V_{DD} = 50V, I_D = 14A, R_G = 7.5\Omega$
		IRF140	—	—	105		$V_{DD} = 50V, I_D = 28A, R_G = 9.1\Omega$
		IRF150	—	—	130		$V_{DD} = 50V, I_D = 38A, R_G = 2.35\Omega$
		IRF230	—	—	40		$V_{DD} = 100V, I_D = 9.0A, R_G = 7.5\Omega$
		IRF240	—	—	67		$V_{DD} = 100V, I_D = 18A, R_G = 9.1\Omega$
		IRF250	—	—	130		$V_{DD} = 100V, I_D = 30A, R_G = 2.35\Omega$
		IRF330	—	—	35		$V_{DD} = 200V, I_D = 5.5A, R_G = 7.5\Omega$
		IRF340	—	—	58		$V_{DD} = 200V, I_D = 10A, R_G = 9.1\Omega$
		IRF350	—	—	130		$V_{DD} = 200V, I_D = 14A, R_G = 2.35\Omega$
		IRF360	—	—	99		$V_{DD} = 200V, I_D = 25A, R_G = 2.35\Omega$
		IRF430	—	—	30		$V_{DD} = 250V, I_D = 4.5A, R_G = 7.5\Omega$
		IRF440	—	—	51		$V_{DD} = 250V, I_D = 8.0A, R_G = 9.1\Omega$
		IRF450	—	—	130		$V_{DD} = 250V, I_D = 12A, R_G = 2.35\Omega$
		IRF460	—	—	98		$V_{DD} = 250V, I_D = 21A, R_G = 2.35\Omega$
		IRFAC30	—	—	21		$V_{DD} = 300V, I_D = 3.6A, R_G = 7.5\Omega$
		IRFAC40	—	—	30		$V_{DD} = 300V, I_D = 6.2A, R_G = 9.1\Omega$
		IRFAE30	—	—	44		$V_{DD} = 400V, I_D = 3.1A, R_G = 7.5\Omega$
		IRFAE40	—	—	44		$V_{DD} = 400V, I_D = 4.8A, R_G = 9.1\Omega$
		IRFAE50	—	—	24		$V_{DD} = 400V, I_D = 7.1A, R_G = 2.35\Omega$
		IRFAF30	—	—	47		$V_{DD} = 400V^*, I_D = 2.0A, R_G = 7.5\Omega$
		IRFAF40	—	—	44		$V_{DD} = 400V^*, I_D = 4.3A, R_G = 9.1\Omega$
	IRFAF50	—	—	57	$V_{DD} = 400V^*, I_D = 6.2A, R_G = 2.35\Omega$		
	IRFAG30	—	—	60	$V_{DD} = 400V^*, I_D = 2.3A, R_G = 7.5\Omega$		
	IRFAG40	—	—	50	$V_{DD} = 400V^*, I_D = 3.9A, R_G = 9.1\Omega$		
	IRFAG50	—	—	60	$V_{DD} = 400V^*, I_D = 5.6A, R_G = 2.35\Omega$		
	P-Channel	IRF9130	—	—	140	$V_{DD} = -50V, I_D = -11A, R_G = 7.5\Omega$	
		IRF9140	—	—	65	$V_{DD} = -50V, I_D = -18A, R_G = 9.1\Omega$	
		IRF9230	—	—	80	$V_{DD} = -100V, I_D = -6.5A, R_G = 7.5\Omega$	
		IRF9240	—	—	65	$V_{DD} = -100V, I_D = -11A, R_G = 9.1\Omega$	

*Equipment Limitation

Notes – See page I-34.

Electrical Characteristics @ $T_C = 25^\circ\text{C}$ (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions	
L_D Internal Drain Inductance	N-Channel	All	—	5.0	—	nH	Measured from the drain lead, 6 mm (0.15 in.) from package to center of die.	Modified MOSFET symbol showing the internal inductances.
L_S Internal Source Inductance			—	13	—			
L_D Internal Drain Inductance	P-Channel	All	—	5.0	—	nH	Measured from the drain lead, 6 mm (0.15 in.) from package to center of die.	Modified MOSFET symbol showing the internal inductances.
L_S Internal Source Inductance			—	13	—			
C_{iss} Input Capacitance	N-Channel	IRF034	—	1300	—	pF	V _{GS} = 0V, V _{DS} = 25V f = 1.0 MHz See Fig. 5	
		IRF044	—	2400	—			
		IRF054	—	4600	—			
		IRF130	—	650	—			
		IRF140	—	1660	—			
		IRF150	—	3700	—			
		IRF230	—	600	—			
		IRF240	—	1300	—			
		IRF250	—	3500	—			
		IRF330	—	620	—			
		IRF340	—	1400	—			
		IRF350	—	2600	—			
		IRF360	—	4200	—			
		IRF430	—	610	—			
		IRF440	—	1300	—			
		IRF450	—	2700	—			
		IRF460	—	4300	—			
		IRFAC30	—	630	—			
		IRFAC40	—	1300	—			
		IRFAE30	—	950	—			
		IRFAE40	—	1700	—			
		IRFAE50	—	2800	—			
	IRFAF30	—	1000	—				
	IRFAF40	—	1500	—				
	IRFAF50	—	2700	—				
	IRFAG30	—	980	—				
	IRFAG40	—	1700	—				
	IRFAG50	—	2400	—				
	P-Channel	IRF9130	—	860	—		V _{GS} = 0V, V _{DS} = -25V f = 1.0 MHz See Fig. 5	
		IRF9140	—	1400	—			
		IRF9230	—	700	—			
		IRF9240	—	1200	—			

Notes – See page I-34.



Electrical Characteristics @ $T_C = 25^\circ\text{C}$ (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
C_{oss} Output Capacitance	N-Channel	IRF034	—	650	—	pF	$V_{GS} = 0V, V_{DS} = 25V$ $f = 1.0\text{ MHz}$ See Fig. 5
		IRF044	—	1100	—		
		IRF054	—	2000	—		
		IRF130	—	250	—		
		IRF140	—	550	—		
		IRF150	—	1100	—		
		IRF230	—	250	—		
		IRF240	—	400	—		
		IRF250	—	700	—		
		IRF330	—	200	—		
		IRF340	—	350	—		
		IRF350	—	680	—		
		IRF360	—	900	—		
		IRF430	—	135	—		
		IRF440	—	310	—		
		IRF450	—	600	—		
		IRF460	—	1000	—		
		IRFAC30	—	80	—		
		IRFAC40	—	160	—		
		IRFAE30	—	170	—		
		IRFAE40	—	230	—		
		IRFAE50	—	400	—		
		IRFAF30	—	200	—		
	IRFAF40	—	190	—			
	IRFAF50	—	500	—			
	IRFAG30	—	140	—			
	IRFAG40	—	250	—			
IRFAG50	—	240	—				
P-Channel	IRF9130	—	350	—	$V_{GS} = 0V, V_{DS} = -25V$ $f = 1.0\text{ MHz}$ See Fig. 5		
	IRF9140	—	600	—			
	IRF9230	—	200	—			
	IRF9240	—	570	—			

Notes – See page I-34.



Electrical Characteristics @ $T_C = 25^\circ\text{C}$ (Unless Otherwise Specified) continued

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
C_{rss} Reverse Transfer Capacitance	N-Channel	IRF034	—	100	—	pF	$V_{GS} = 0V, V_{DS} = 25V$ $f = 1.0\text{ MHz}$ See Fig. 5
		IRF044	—	230	—		
		IRF054	—	340	—		
		IRF130	—	44	—		
		IRF140	—	120	—		
		IRF150	—	200	—		
		IRF230	—	80	—		
		IRF240	—	130	—		
		IRF250	—	110	—		
		IRF330	—	75	—		
		IRF340	—	230	—		
		IRF350	—	250	—		
		IRF360	—	400	—		
		IRF430	—	65	—		
		IRF440	—	120	—		
		IRF450	—	240	—		
		IRF460	—	250	—		
		IRFAC30	—	15	—		
		IRFAC40	—	45	—		
		IRFAE30	—	80	—		
	IRFAE40	—	96	—			
	IRFAE50	—	200	—			
	IRFAF30	—	98	—			
	IRFAF40	—	72	—			
	IRFAF50	—	200	—			
	IRFAG30	—	50	—			
IRFAG40	—	100	—				
IRFAG50	—	80	—				
P-Channel	IRF9130	—	125	—	$V_{GS} = 0V, V_{DS} = -25V$ $f = 1.0\text{ MHz}$ See Fig. 5		
	IRF9140	—	200	—			
	IRF9230	—	40	—			
	IRF9240	—	81	—			

Notes – See page I-34.



Electrical Characteristics @ $T_C = 25^\circ\text{C}$ (Unless Otherwise Specified) continued

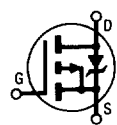
Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
C _{DC} Drain-to-Case Capacitance	N-Channel	ALL	—	12	—	pF	V _{GS} = 0V, V _{DS} = 25V f = 1.0 MHz See Fig. 5
	P-Channel	ALL	—	12	—		V _{GS} = 0V, V _{DS} = -25V f = 1.0 MHz See Fig. 5

Notes – See page I-34.



Source-Drain Diode Ratings and Characteristics

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
I _S Continuous Source Current (Body Diode)	N-Channel	IRF034	—	—	25	A	Modified MOSFET symbol showing the integral reverse p-n junction rectifier.
		IRF044	—	—	44		
		IRF054	—	—	45*		
		IRF130	—	—	14		
		IRF140	—	—	28		
		IRF150	—	—	38		
		IRF230	—	—	9.0		
		IRF240	—	—	18		
		IRF250	—	—	30		
		IRF330	—	—	5.5		
		IRF340	—	—	10		
		IRF350	—	—	14		
		IRF360	—	—	25		
		IRF430	—	—	4.5		
		IRF440	—	—	8.0		
		IRF450	—	—	12		
		IRF460	—	—	21		
		IRFAC30	—	—	3.6		
		IRFAC40	—	—	6.2		
		IRFAE30	—	—	3.1		
		IRFAE40	—	—	4.8		
		IRFAE50	—	—	7.1		
		IRFAF30	—	—	2.8		
		IRFAF40	—	—	4.3		
	IRFAF50	—	—	6.2			
	IRFAG30	—	—	2.3			
	IRFAG40	—	—	3.9			
	IRFAG50	—	—	5.6			
	P-Channel	IRF9130	—	—	-11		
		IRF9140	—	—	-18		
		IRF9230	—	—	-6.5		
		IRF9240	—	—	-11		

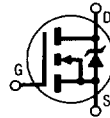


*I_S current limited by pin diameter

Notes – See page I-34.

Source-Drain Diode Ratings and Characteristics (continued)

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
ISM Pulse Source Current (Body Diode) ①	N-Channel	IRF034	—	—	100	A	Modified MOSFET symbol showing the integral reverse p-n junction rectifier.
		IRF044	—	—	176		
		IRF054	—	—	220		
		IRF130	—	—	56		
		IRF140	—	—	112		
		IRF150	—	—	152		
		IRF230	—	—	36		
		IRF240	—	—	72		
		IRF250	—	—	120		
		IRF330	—	—	22		
		IRF340	—	—	40		
		IRF350	—	—	56		
		IRF360	—	—	100		
		IRF430	—	—	18		
		IRF440	—	—	32		
		IRF450	—	—	48		
		IRF460	—	—	84		
		IRFAC30	—	—	14		
		IRFAC40	—	—	25		
		IRFAE30	—	—	12		
		IRFAE40	—	—	19		
		IRFAE50	—	—	28		
		IRFAF30	—	—	8.0		
		IRFAF40	—	—	17		
	IRFAF50	—	—	25			
	IRFAG30	—	—	9.2			
	IRFAG40	—	—	16			
	IRFAG50	—	—	22			
	P-Channel	IRF9130	—	—	-50		
		IRF9140	—	—	-72		
		IRF9230	—	—	-28		
		IRF9240	—	—	-44		



Notes – See page I-34.



Source-Drain Diode Ratings and Characteristics (continued)

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
V _{SD} Diode Forward Voltage	N-Channel	IRF034	—	—	1.8	V	I _S = 25A
		IRF044	—	—	2.5		I _S = 44A
		IRF054	—	—	2.5		I _S = 45A
		IRF130	—	—	1.5		I _S = 14A
		IRF140	—	—	1.5		I _S = 28A
		IRF150	—	—	1.8		I _S = 38A
		IRF230	—	—	1.4		I _S = 9.0A
		IRF240	—	—	1.5		I _S = 18A
		IRF250	—	—	1.9		I _S = 30A
		IRF330	—	—	1.4		I _S = 5.5A
		IRF340	—	—	1.5		I _S = 10A
		IRF350	—	—	1.7		I _S = 14A
		IRF360	—	—	1.8		I _S = 25A
		IRF430	—	—	1.4		I _S = 4.5A
		IRF440	—	—	1.5		I _S = 8.0A
		IRF450	—	—	1.7		I _S = 12A
		IRF460	—	—	1.8		I _S = 21A
		IRFAC30	—	—	1.6		I _S = 3.6A
		IRFAC40	—	—	1.1		I _S = 6.2A
		IRFAE30	—	—	1.8		I _S = 3.1A
		IRFAE40	—	—	1.8		I _S = 4.8A
		IRFAE50	—	—	1.8		I _S = 7.1A
		IRFAF30	—	—	1.8		I _S = 2.0A
		IRFAF40	—	—	1.8		I _S = 4.3A
	IRFAF50	—	—	1.8	I _S = 6.2A		
	IRFAG30	—	—	1.8	I _S = 2.3A		
	IRFAG40	—	—	1.8	I _S = 3.9A		
	IRFAG50	—	—	1.8	I _S = 5.6A		
	P-Channel	IRF9130	—	—	-4.7	I _S = -11A	
		IRF9140	—	—	-4.2	I _S = -18A	
IRF9230		—	—	-6.0	I _S = -6.5A		
IRF9240		—	—	-4.6	I _S = -11A		

T_J = 25°C, V_{GS} = 0V ⊕

Notes – See page I-34.



Source-Drain Diode Ratings and Characteristics (continued)

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
t_{rr} Reverse Recovery Time	N-Channel	IRF034	—	—	220	ns	$I_F = 25A$
		IRF044	—	—	220		$I_F = 44A$
		IRF054	—	—	280		$I_F = 45A$
		IRF130	—	—	300		$I_F = 14A$
		IRF140	—	—	400		$I_F = 28A$
		IRF150	—	—	500		$I_F = 38A$
		IRF230	—	—	500		$I_F = 9.0A$
		IRF240	—	—	500		$I_F = 18A$
		IRF250	—	—	950		$I_F = 30A$
		IRF330	—	—	700		$I_F = 5.5A$
		IRF340	—	—	600		$I_F = 10A$
		IRF350	—	—	1200		$I_F = 14A$
		IRF360	—	—	1000		$I_F = 25A$
		IRF430	—	—	900		$I_F = 4.5A$
		IRF440	—	—	700		$I_F = 8.0A$
		IRF450	—	—	1600		$I_F = 12A$
		IRF460	—	—	580		$I_F = 21A$
		IRFAC30	—	—	810		$I_F = 3.6A$
		IRFAC40	—	—	940		$I_F = 6.2A$
		IRFAE30	—	—	800		$I_F = 3.1A$
		IRFAE40	—	—	1300		$I_F = 4.8A$
		IRFAE50	—	—	1600		$I_F = 7.1A$
		IRFAF30	—	—	730		$I_F = 2.0A$
		IRFAF40	—	—	1100		$I_F = 4.3A$
	IRFAF50	—	—	1500	$I_F = 6.2A$		
	IRFAG30	—	—	470	$I_F = 2.3A$		
	IRFAG40	—	—	1000	$I_F = 3.9A$		
	IRFAG50	—	—	1200	$I_F = 5.6A$		
P-Channel	IRF9130	—	—	250	$I_F = -11A$		
	IRF9140	—	170	280	$I_F = -18A$		
	IRF9230	—	—	400	$I_F = -6.5A$		
	IRF9240	—	270	440	$I_F = -11A$		

$T_J = 25^\circ C, di/dt \leq 100 A/\mu s$
 $V_{DD} \leq 50V$

$T_J = 25^\circ C, di/dt \leq -100 A/\mu s$ ④
 $V_{DD} \leq -50V$

Notes – See page I-34.

Source-Drain Diode Ratings and Characteristics (continued)

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
Q _{RR} Reverse Recovery Charge	N-Channel	IRF034	—	—	9.6	μC	I _F = 25A
		IRF044	—	—	1.6		I _F = 44A
		IRF054	—	—	2.2		I _F = 45A
		IRF130	—	—	3.0		I _F = 14A
		IRF140	—	—	2.9		I _F = 28A
		IRF150	—	—	2.9		I _F = 38A
		IRF230	—	—	6.0		I _F = 9.0A
		IRF240	—	—	5.3		I _F = 18A
		IRF250	—	—	9.0		I _F = 30A
		IRF330	—	—	6.2		I _F = 5.5A
		IRF340	—	—	5.6		I _F = 10A
		IRF350	—	—	11		I _F = 14A
		IRF360	—	—	16		I _F = 25A
		IRF430	—	—	7.0		I _F = 4.5A
		IRF440	—	—	8.9		I _F = 8.0A
		IRF450	—	—	14		I _F = 12A
		IRF460	—	—	8.1		I _F = 21A
		IRFAC30	—	—	4.2		I _F = 3.6A
		IRFAC40	—	—	8.0		I _F = 6.2A
		IRFAE30	—	—	3.6		I _F = 3.1A
		IRFAE40	—	—	8.5		I _F = 4.8A
		IRFAE50	—	—	13		I _F = 7.1A
		IRFAF30	—	—	3.0		I _F = 2.0A
	IRFAF40	—	—	6.7	I _F = 4.3A		
	IRFAF50	—	—	11	I _F = 6.2A		
	IRFAG30	—	—	1.7	I _F = 2.3A		
	IRFAG40	—	—	5.6	I _F = 3.9A		
IRFAG50	—	—	8.4	I _F = 5.6A			
	P-Channel	IRF9130	—	—	3.0		I _F = -11A
		IRF9140	—	—	3.6		I _F = -18A
		IRF9230	—	—	4.0		I _F = -6.5A
		IRF9240	—	—	7.2		I _F = -11A
t _{on} Forward Turn-On Time	ALL	Intrinsic turn-on time is negligible. Turn-on speed is substantially controlled by L _S + L _D					

Notes – See page I-34.



Thermal Resistance and Case Style

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
R _{thJC} Junction-to-Case	N-Channel	IRF034	—	—	1.67	K/W ^⑤	
		IRF044	—	—	1.0		
		IRF054	—	—	0.83		
		IRF130	—	—	1.67		
		IRF140	—	—	1.0		
		IRF150	—	—	0.83		
		IRF230	—	—	1.67		
		IRF240	—	—	1.0		
		IRF250	—	—	0.83		
		IRF330	—	—	1.67		
		IRF340	—	—	1.0		
		IRF350	—	—	0.83		
		IRF360	—	—	0.42		
		IRF430	—	—	1.67		
		IRF440	—	—	1.0		
		IRF450	—	—	0.83		
		IRF460	—	—	0.42		
		IRFAC30	—	—	1.67		
		IRFAC40	—	—	1.0		
		IRFAE30	—	—	1.67		
		IRFAE40	—	—	1.0		
		IRFAE50	—	—	0.83		
		IRFAF30	—	—	1.67		
		IRFAF40	—	—	1.0		
	IRFAF50	—	—	0.83			
	IRFAG30	—	—	1.67			
	IRFAG40	—	—	1.0			
	IRFAG50	—	—	0.83			
	P-Channel	IRF9130	—	—	1.67		
		IRF9140	—	—	1.0		
		IRF9230	—	—	1.67		
		IRF9240	—	—	1.0		

Notes – See page I-34.



Thermal Resistance and Case Style (continued)

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
R _{thCS} Case-to-Sink	N-Channel	IRF034	—	0.12	—	K/W ^⑤	Mounting surface flat, smooth, and greased.
		IRF044	—	0.12	—		
		IRF054	—	0.12	—		
		IRF130	—	0.12	—		
		IRF140	—	0.12	—		
		IRF150	—	0.12	—		
		IRF230	—	0.12	—		
		IRF240	—	0.12	—		
		IRF250	—	0.12	—		
		IRF330	—	0.12	—		
		IRF340	—	0.12	—		
		IRF350	—	0.12	—		
		IRF360	—	0.12	—		
		IRF430	—	0.12	—		
		IRF440	—	0.12	—		
		IRF450	—	0.12	—		
		IRF460	—	0.12	—		
		IRFAC30	—	0.12	—		
		IRFAC40	—	0.12	—		
		IRFAE30	—	0.12	—		
	IRFAE40	—	0.12	—			
	IRFAE50	—	0.12	—			
	IRFAF30	—	0.12	—			
	IRFAF40	—	0.12	—			
	IRFAF50	—	0.12	—			
	IRFAG30	—	0.12	—			
	IRFAG40	—	0.12	—			
	IRFAG50	—	0.12	—			
P-Channel	IRF9130	—	0.12	—			
	IRF9140	—	0.12	—			
	IRF9230	—	0.12	—			
	IRF9240	—	0.12	—			

Notes – See page I-34.





Thermal Resistance and Case Style (continued)

Parameter		Part Number	Min.	Typ.	Max.	Units	Test Conditions
R _{thJA} Junction-to-Ambient	N-Channel	IRF034	—	—	30	K/W ^⑤	Typical socket mount
		IRF044	—	—	30		
		IRF054	—	—	30		
		IRF130	—	—	30		
		IRF140	—	—	30		
		IRF150	—	—	30		
		IRF230	—	—	30		
		IRF240	—	—	30		
		IRF250	—	—	30		
		IRF330	—	—	30		
		IRF340	—	—	30		
		IRF350	—	—	30		
		IRF360	—	—	30		
		IRF430	—	—	30		
		IRF440	—	—	30		
		IRF450	—	—	30		
		IRF460	—	—	30		
		IRFAC30	—	—	30		
		IRFAC40	—	—	30		
		IRFAE30	—	—	30		
		IRFAE40	—	—	30		
		IRFAE50	—	—	30		
		IRFAF30	—	—	30		
		IRFAF40	—	—	30		
		IRFAF50	—	—	30		
		IRFAG30	—	—	30		
		IRFAG40	—	—	30		
		IRFAG50	—	—	30		
	P-Channel	IRF9130	—	—	30		
		IRF9140	—	—	30		
		IRF9230	—	—	30		
		IRF9240	—	—	30		

Notes – See page I-34.



Thermal Resistance and Case Style (continued)

Case Style	Part Number	TO-204AA	TO-204AE	
N-Channel	IRF034		X	
	IRF044		X	
	IRF054		X	
	IRF130	X		
	IRF140		X	
	IRF150		X	
	IRF230	X		
	IRF240		X	
	IRF250		X	
	IRF330	X		
	IRF340	X		
	IRF350	X		
	IRF360		X	
	IRF430	X		
	IRF440	X		
	IRF450	X		
	IRF460		X	
	IRFAC30	X		
	IRFAC40	X		
	IRFAE30	X		
	IRFAE40	X		
	IRFAE50	X		
	IRFAF30	X		
	IRFAF40	X		
	IRFAF50	X		
	IRFAG30	X		
	IRFAG40	X		
	IRFAG50	X		
	IRF9130	X		
	P-Channel	IRF9140	X	
		IRF9230	X	
		IRF9240	X	

Notes – See page I-34.



Notes:

- ① Repetitive rating: pulse width limited by max. junction temperature (See Figure 11)
- ② See Table 1 for individual devices conditions
- ③ See Table 1 for individual devices conditions
- ④ Pulse width $\leq 300 \mu\text{s}$; duty cycle $\leq 2\%$
- ⑤ $K/W = ^\circ\text{C/W}$
 $W/K = \text{W}/^\circ\text{C}$

**Table 1 — Notes ② and ③ for IRF034 to IRFAG50 — N-Channel
IRF9130 to IRF9240 — P-Channel**

Device	Note ②	Note ③
IRF034	@ $V_{DD} = 25\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 35 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 25\text{A}$	$I_{SD} \leq 25\text{A}$, $di/dt \leq 200 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 7.5\Omega$
IRF044	@ $V_{DD} = 25\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 200 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 44\text{A}$	$I_{SD} \leq 44\text{A}$, $di/dt \leq 250 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 9.1\Omega$
IRF054	@ $V_{DD} = 25\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 280 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 45\text{A}$	$I_{SD} \leq 45\text{A}$, $di/dt \leq 200 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 2.35\Omega$
IRF130	@ $V_{DD} = 50\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 570 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 14\text{A}$	$I_{SD} \leq 14\text{A}$, $di/dt \leq 140 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 7.5\Omega$
IRF140	@ $V_{DD} = 25\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 480 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 28\text{A}$	$I_{SD} \leq 28\text{A}$, $di/dt \leq 170 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 9.1\Omega$
IRF150	@ $V_{DD} = 50\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 160 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 38\text{A}$	$I_{SD} \leq 38\text{A}$, $di/dt \leq 300 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 2.35\Omega$
IRF230	@ $V_{DD} = 50\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 1.0 \text{mH}$, $R_G = 25\Omega$, Peak $I_L = 9.0\text{A}$	$I_{SD} \leq 9.0\text{A}$, $di/dt \leq 120 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 7.5\Omega$
IRF240	@ $V_{DD} = 50\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 2.1 \text{mH}$, $R_G = 25\Omega$, Peak $I_L = 18\text{A}$	$I_{SD} \leq 18\text{A}$, $di/dt \leq 160 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 9.1\Omega$
IRF250	@ $V_{DD} = 50\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 330 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 30\text{A}$	$I_{SD} \leq 30\text{A}$, $di/dt \leq 190 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 2.35\Omega$
IRF330	@ $V_{DD} = 50\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 100 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 5.5\text{A}$	$I_{SD} \leq 5.5\text{A}$, $di/dt \leq 90 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 7.5\Omega$
IRF340	@ $V_{DD} = 50\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 100 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 10\text{A}$	$I_{SD} \leq 10\text{A}$, $di/dt \leq 120 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 9.1\Omega$
IRF350	@ $V_{DD} = 50\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 100 \mu\text{H}$, $R_G = 25\Omega$, Peak $I_L = 14\text{A}$	$I_{SD} \leq 14\text{A}$, $di/dt \leq 145 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 2.35\Omega$
IRF360	@ $V_{DD} = 50\text{V}$, Starting $T_J = 25^\circ\text{C}$, $L \geq 2.8 \text{mH}$, $R_G = 25\Omega$, Peak $I_L = 25\text{A}$	$I_{SD} \leq 25\text{A}$, $di/dt \leq 170 \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ\text{C}$ Suggested $R_G = 2.35\Omega$

Table 1 — (continued)

Device	Note ②	Note ③
IRF430	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 100 μH, R _G = 25Ω, Peak I _L = 4.5A	I _{SD} ≤ 4.5A, di/dt ≤ 75 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 7.5Ω
IRF440	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 100 μH, R _G = 25Ω, Peak I _L = 8.0A	I _{SD} ≤ 8.0A, di/dt ≤ 100 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 9.1Ω
IRF450	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 100 μH, R _G = 25Ω, Peak I _L = 12A	I _{SD} ≤ 12A, di/dt ≤ 130 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 2.35Ω
IRF460	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 4.9 mH, R _G = 25Ω, Peak I _L = 21A	I _{SD} ≤ 21A, di/dt ≤ 160 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 2.35Ω
IRFAC30	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 25 mH, R _G = 25Ω, Peak I _L = 3.6A	I _{SD} ≤ 3.6A, di/dt ≤ 60 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 7.5Ω
IRFAC40	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 27 mH, R _G = 25Ω, Peak I _L = 6.2A	I _{SD} ≤ 6.2A, di/dt ≤ 80 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 9.1Ω
IRFAE30	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 20 mH, R _G = 25Ω, Peak I _L = 3.1A	I _{SD} ≤ 3.1A, di/dt ≤ 100 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 7.5Ω
IRFAE40	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 45 mH, R _G = 25Ω, Peak I _L = 4.8A	I _{SD} ≤ 4.8A, di/dt ≤ 120 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 9.1Ω
IRFAF30	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 47 mH, R _G = 25Ω, Peak I _L = 2.0A	I _{SD} ≤ 2.0A, di/dt ≤ 90 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 7.5Ω
IRFAF40	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 54 mH, R _G = 25Ω, Peak I _L = 4.3A	I _{SD} ≤ 4.3A, di/dt ≤ 110 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 9.1Ω
IRFAF50	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 43 mH, R _G = 25Ω, Peak I _L = 6.2A	I _{SD} ≤ 6.2A, di/dt ≤ 130 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 2.35Ω
IRFAG30	@ V _{DD} = 50V, Starting T _J = 25°C, L ≥ 40 mH, R _G = 25Ω, Peak I _L = 2.3A	I _{SD} ≤ 2.3A, di/dt ≤ 80 A/μs, V _{DD} ≤ BV _{DSS} , T _J ≤ 150°C Suggested R _G = 7.5Ω

Table 1 — (continued)

Device	Note ②	Note ③
IRFAG40	@ $V_{DD} = 50V$, Starting $T_J = 25^\circ C$, $L \geq 66 \text{ mH}$, $R_G = 25\Omega$, Peak $I_L = 3.9A$	$I_{SD} \leq 3.9A$, $di/dt \leq 100 A/\mu s$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ C$ Suggested $R_G = 9.1\Omega$
IRFAG50	@ $V_{DD} = 50V$, Starting $T_J = 25^\circ C$, $L \geq 52 \text{ mH}$, $R_G = 25\Omega$, Peak $I_L = 5.6A$	$I_{SD} \leq 5.6A$, $di/dt \leq 120 A/\mu s$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ C$ Suggested $R_G = 2.35\Omega$
IRF9130	@ $V_{DD} = -25V$, Starting $T_J = 25^\circ C$, $L \geq 1.0 \text{ mH}$, $R_G = 25\Omega$, Peak $I_L = -11A$	$I_{SD} \leq -11A$, $di/dt \leq -140 A/\mu s$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ C$ Suggested $R_G = 7.5\Omega$
IRF9140	@ $V_{DD} = -25V$, Starting $T_J = 25^\circ C$, $L \geq 2.3 \text{ mH}$, $R_G = 25\Omega$, Peak $I_L = -18A$	$I_{SD} \leq -18A$, $di/dt \leq -100 A/\mu s$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ C$ Suggested $R_G = 9.1\Omega$
IRF9230	@ $V_{DD} = -50V$, Starting $T_J = 25^\circ C$, $L \geq 2.3 \text{ mH}$, $R_G = 25\Omega$, Peak $I_L = -6.5A$	$I_{SD} \leq -6.5A$, $di/dt \leq -120 A/\mu s$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ C$ Suggested $R_G = 7.5\Omega$
IRF9240	@ $V_{DD} = -50V$, Starting $T_J = 25^\circ C$, $L \geq 6.2 \text{ mH}$, $R_G = 25\Omega$, Peak $I_L = -11A$	$I_{SD} \leq -11A$, $di/dt \leq -150 A/\mu s$, $V_{DD} \leq BV_{DSS}$, $T_J \leq 150^\circ C$ Suggested $R_G = 9.1\Omega$

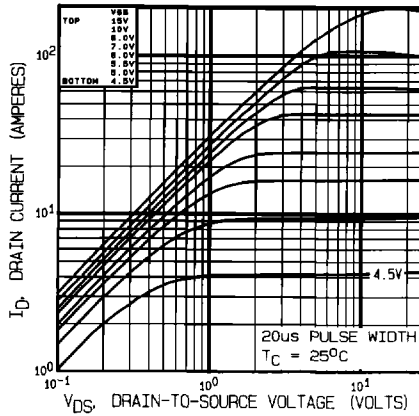


Fig. 1a - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF034

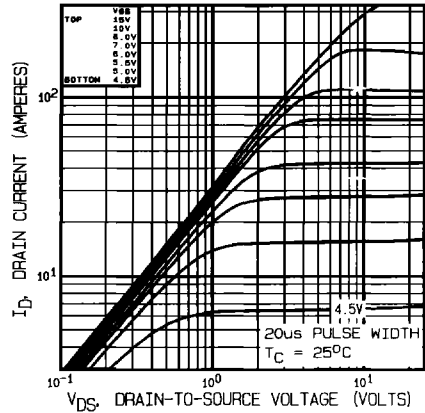


Fig. 1b - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF044

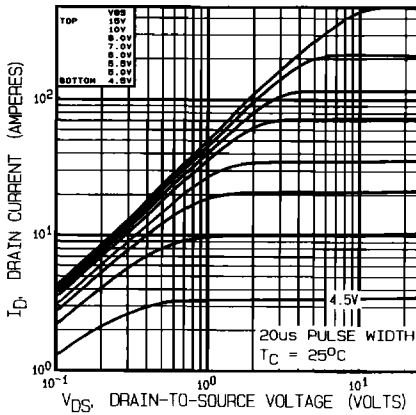


Fig. 1c - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF54

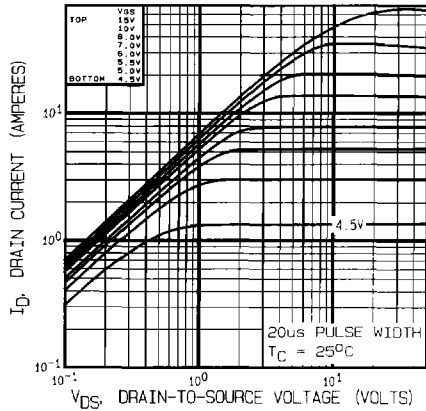


Fig. 1d - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF130

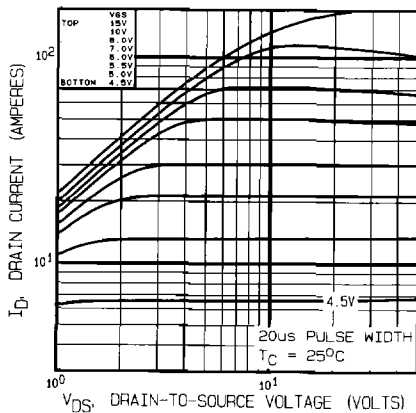


Fig. 1e - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF140

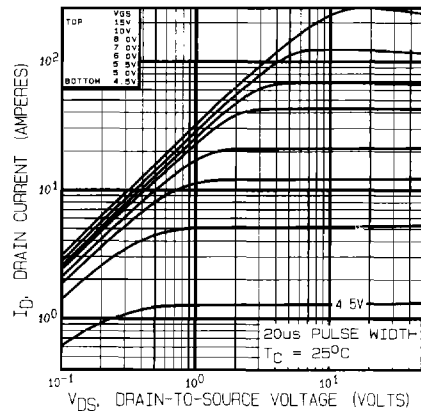


Fig. 1f - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF150

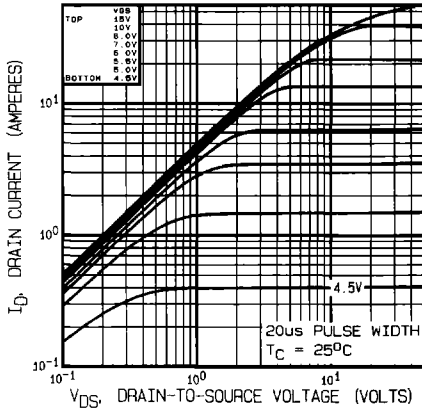


Fig. 1g - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF230

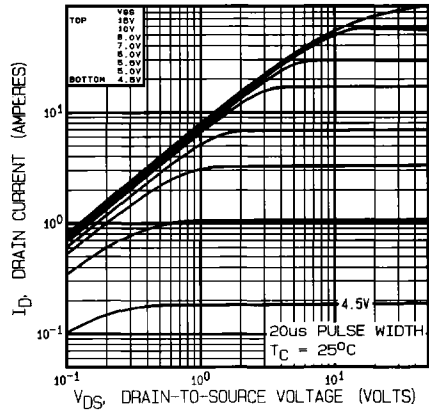


Fig. 1h - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF240

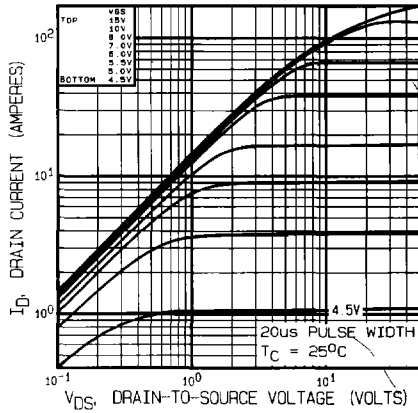


Fig. 1i - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF250

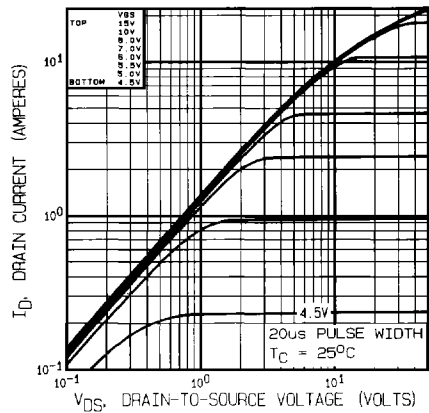


Fig. 1j - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF330

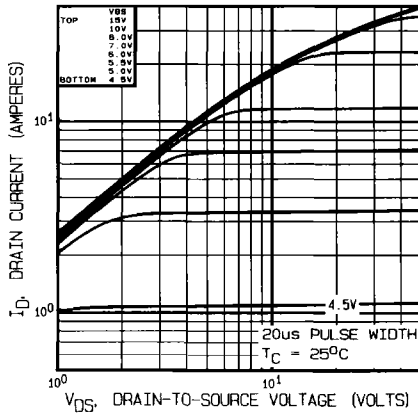


Fig. 1k - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF340

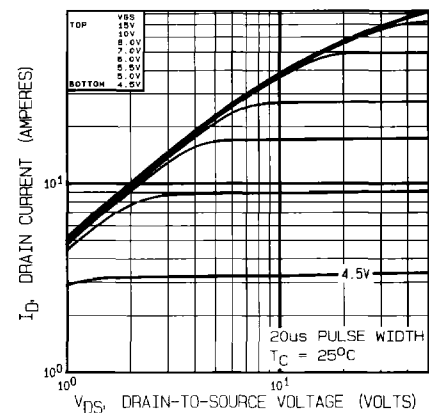


Fig. 1l - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF350

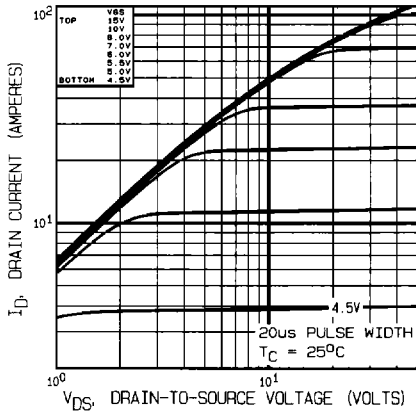


Fig. 1m - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF360

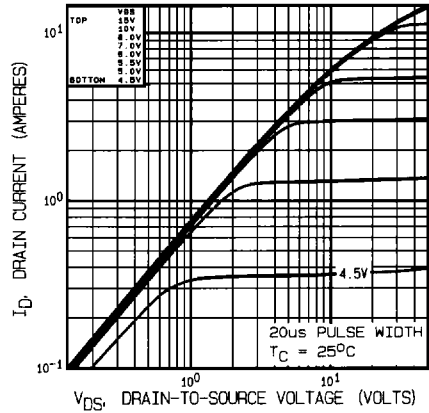


Fig. 1n - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF430

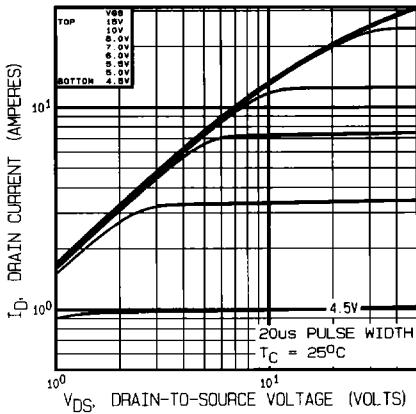


Fig. 1o - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF440

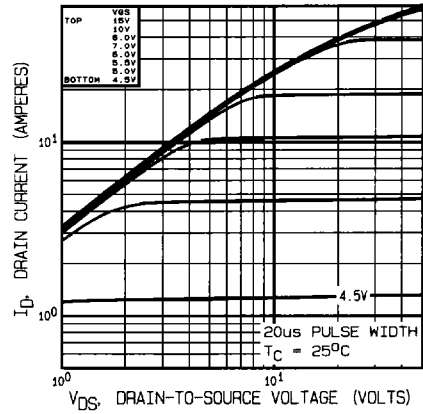


Fig. 1p - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF450

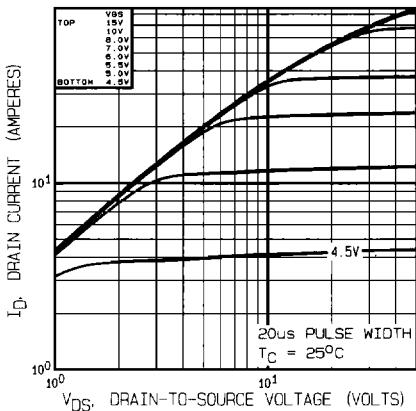


Fig. 1q - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF460

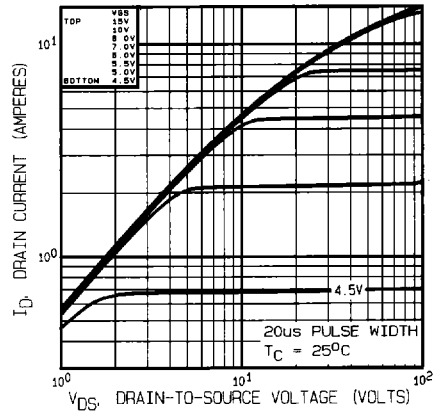


Fig. 1r - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAC30

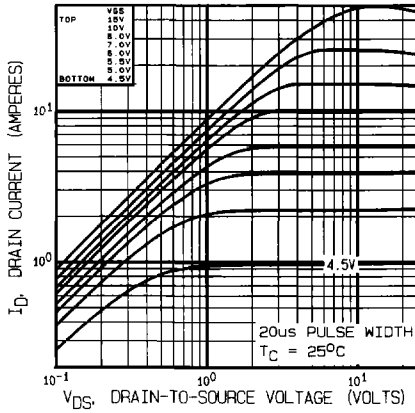


Fig. 1a - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAC40

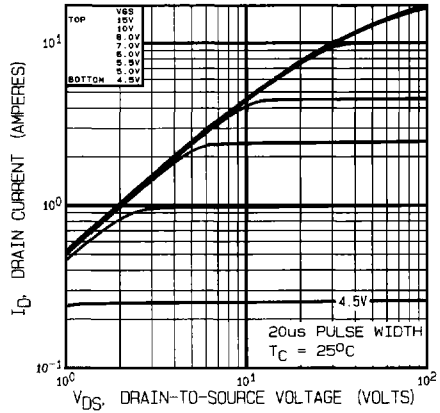


Fig. 1t - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAE30

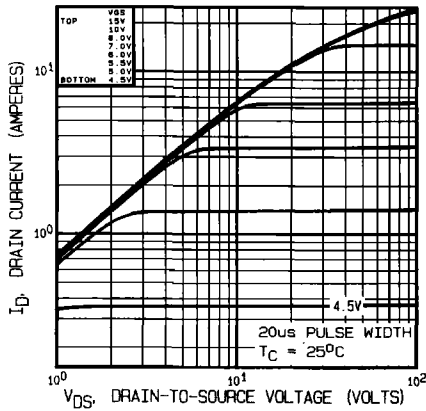


Fig. 1u - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAE40

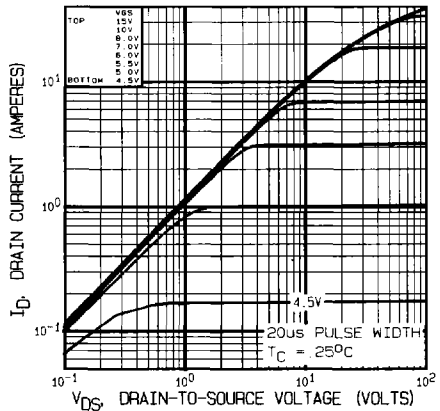


Fig. 1v - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAE50

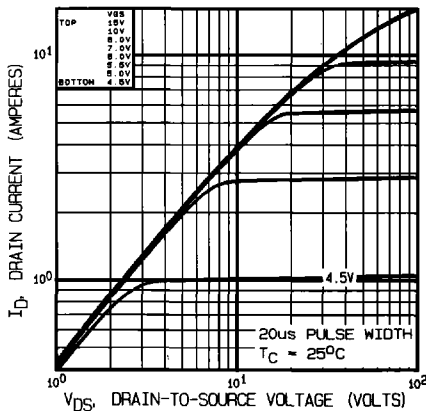


Fig. 1w - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAF30

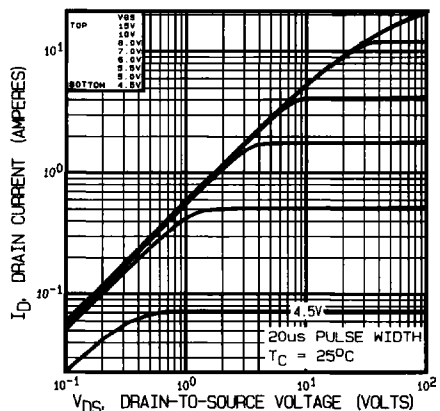


Fig. 1x - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAF40

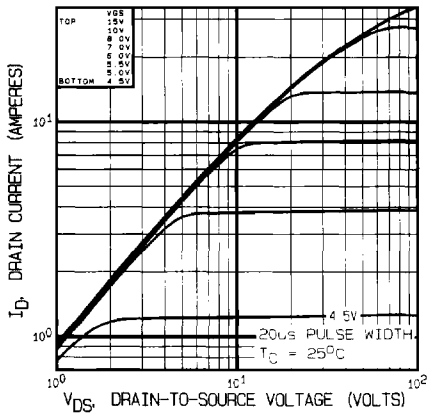


Fig. 1y - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAF50

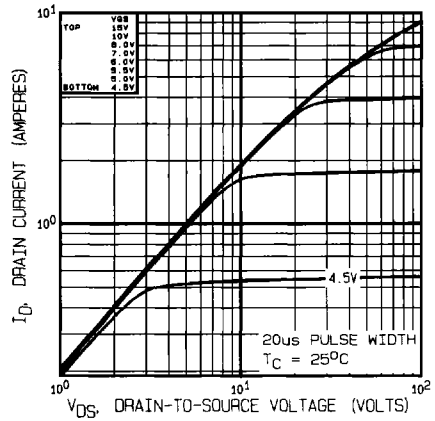


Fig. 1z - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAG30

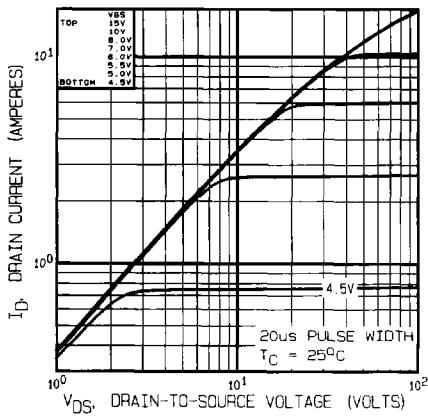


Fig. 1aa - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAG40

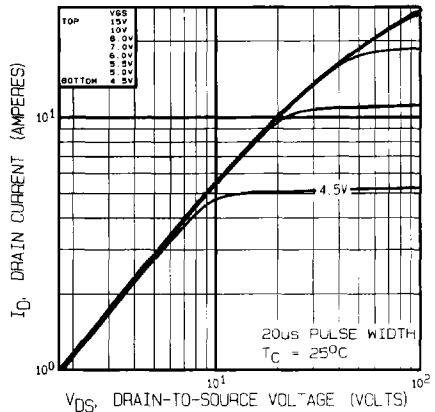


Fig. 1bb - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRFAG50

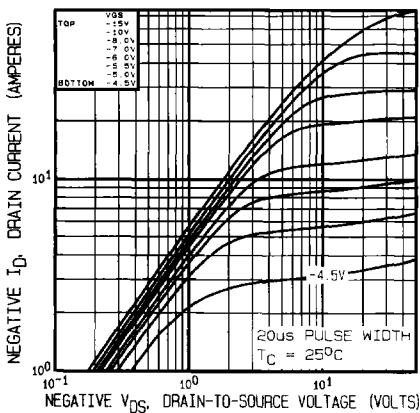


Fig. 1cc - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF9130

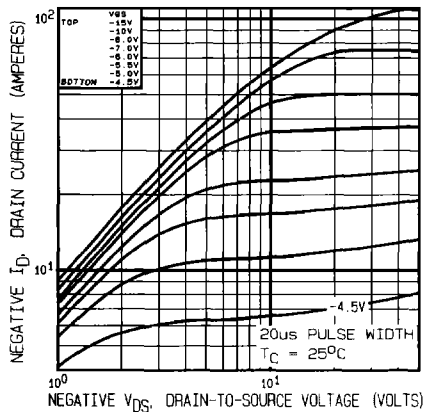


Fig. 1dd - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF9140

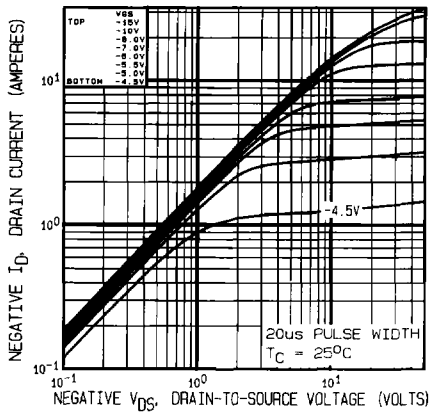


Fig. 1ee - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF9230

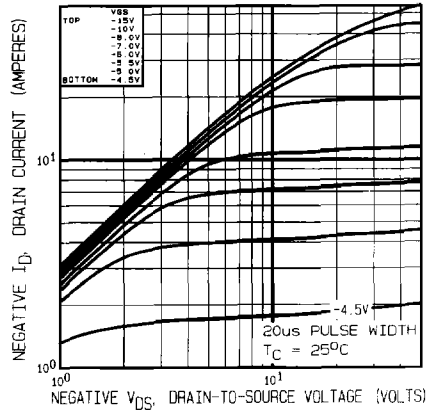


Fig. 1ff - Typical Output Characteristics, $T_C = 25^\circ\text{C}$
IRF9240

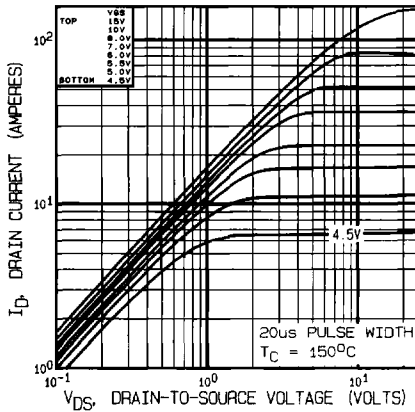


Fig. 2a - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF034

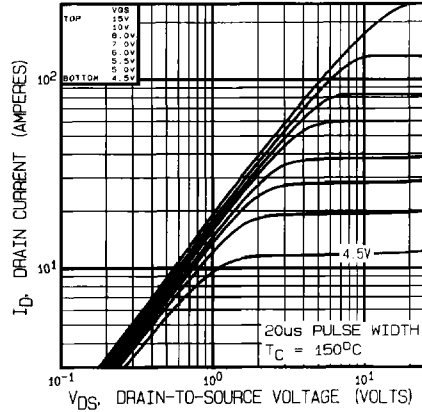


Fig. 2b - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF044

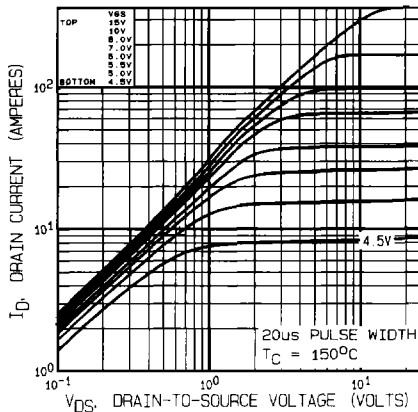


Fig. 2c - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF054

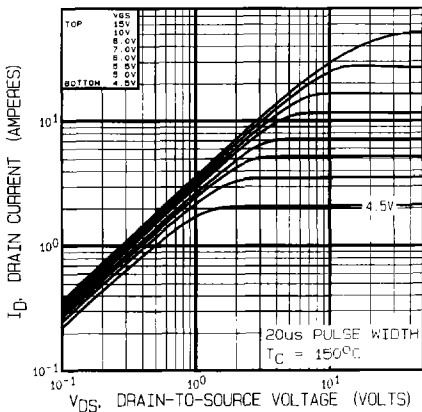
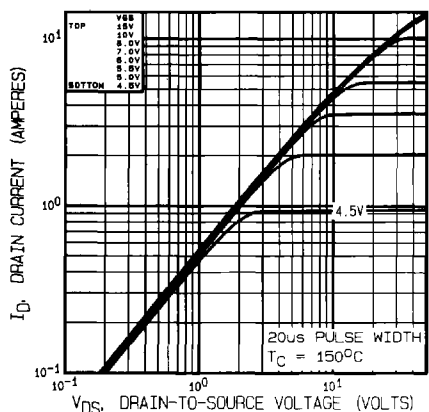
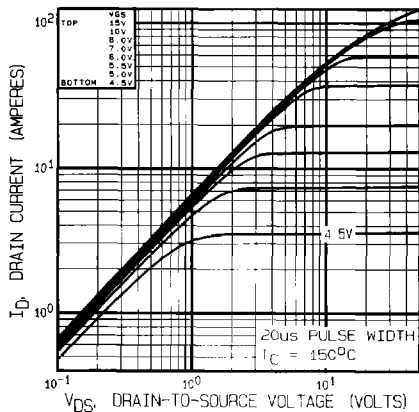
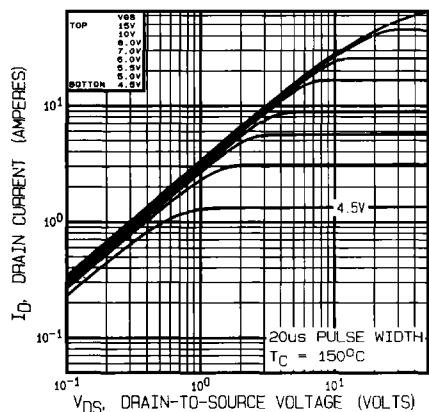
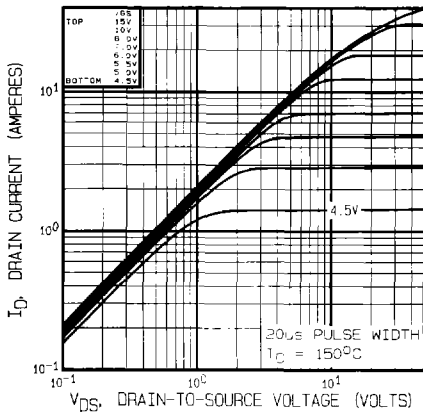
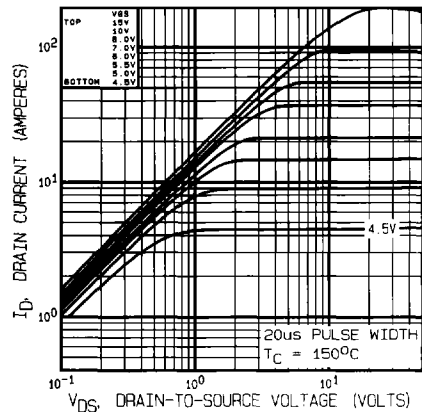
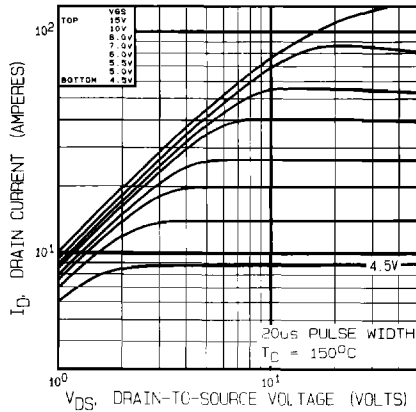


Fig. 2d - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF130



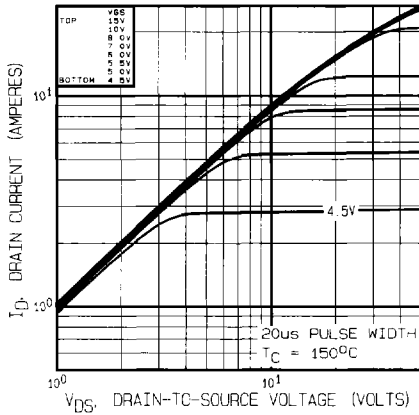


Fig. 2k - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF340

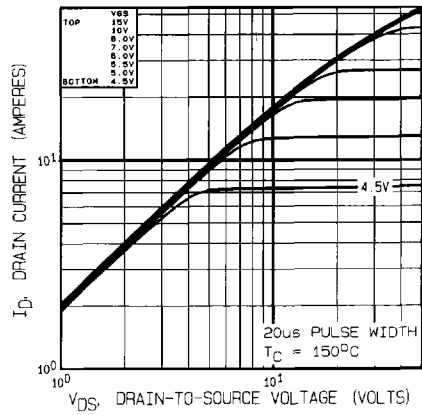


Fig. 2l - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF350

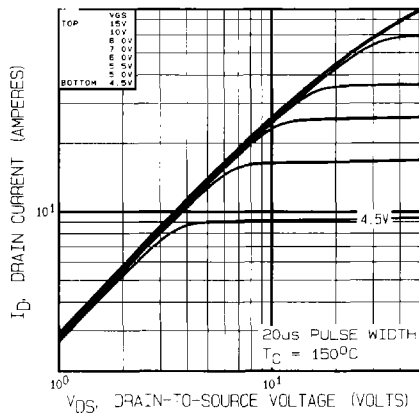


Fig. 2m - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF360

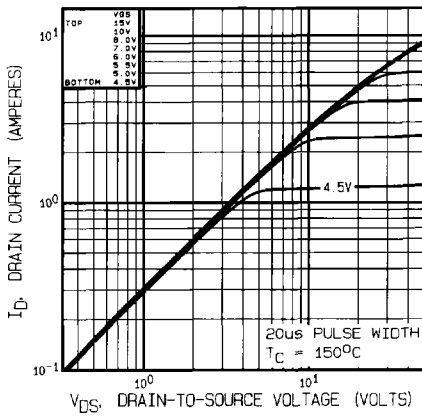


Fig. 2n - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF430

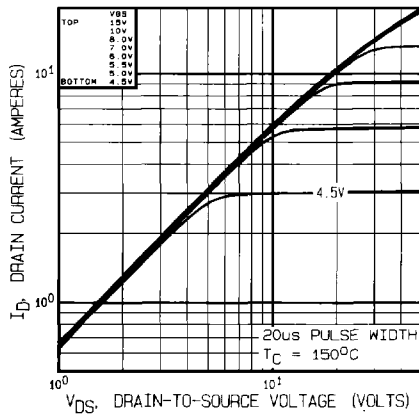


Fig. 2o - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF440

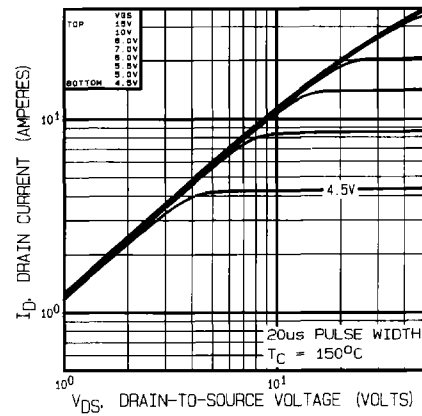


Fig. 2p - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF450

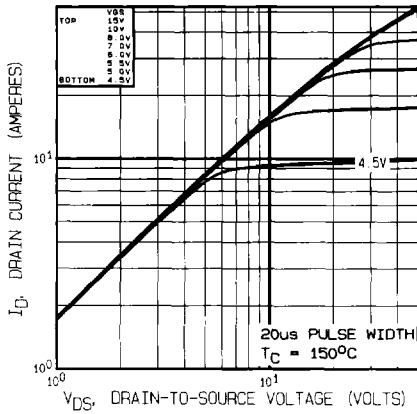


Fig. 2q - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF460

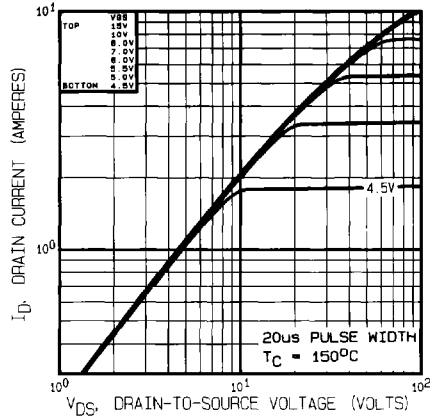


Fig. 2r - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRFAC30

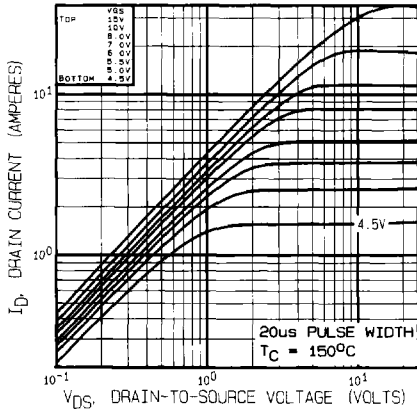


Fig. 2s - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRFAC40

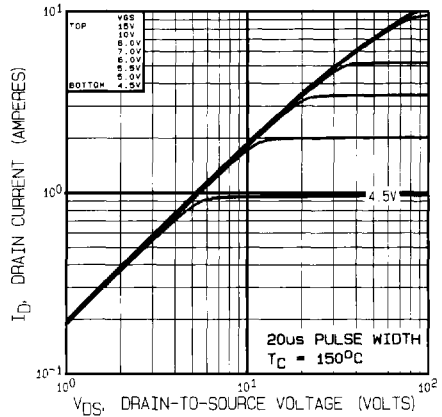


Fig. 2t - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRFAE30

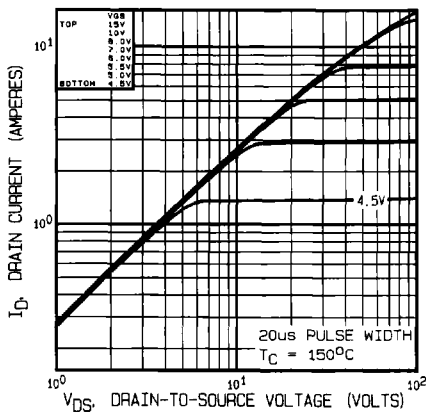


Fig. 2u - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRFAE40

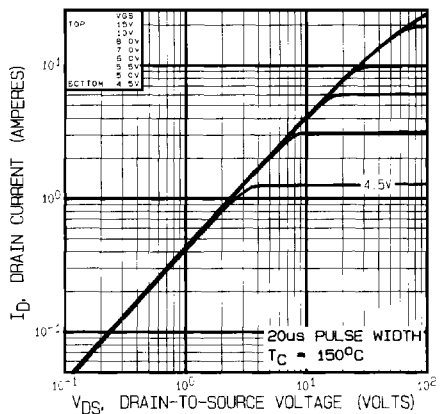
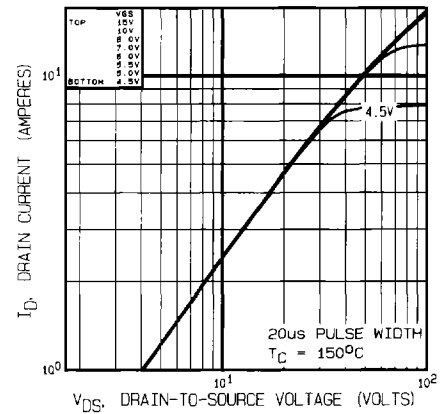
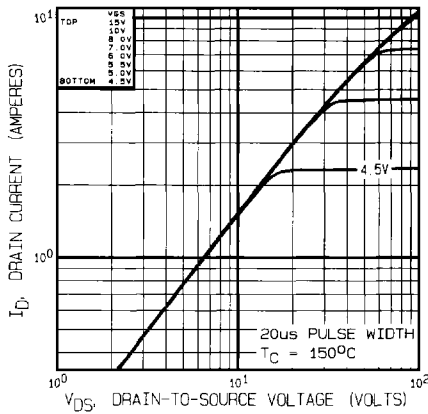
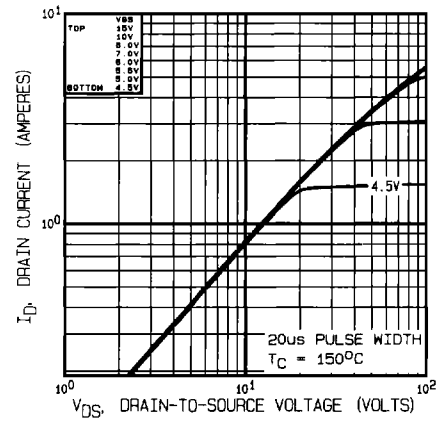
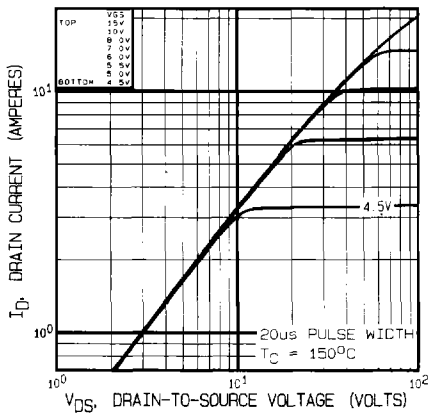
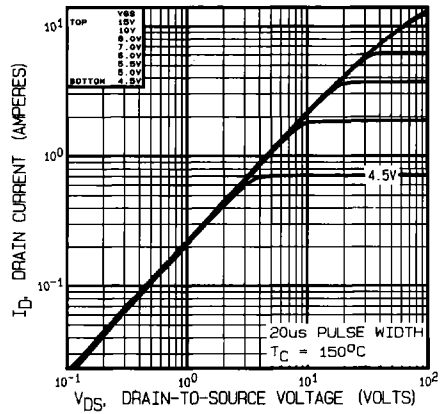
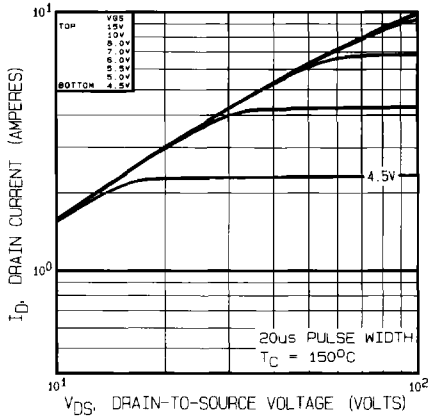


Fig. 2v - Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRFAE50



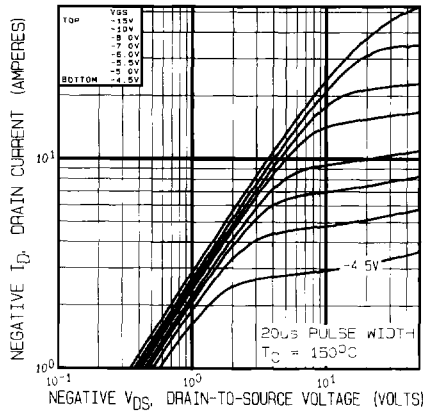


Fig. 2cc – Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF9130

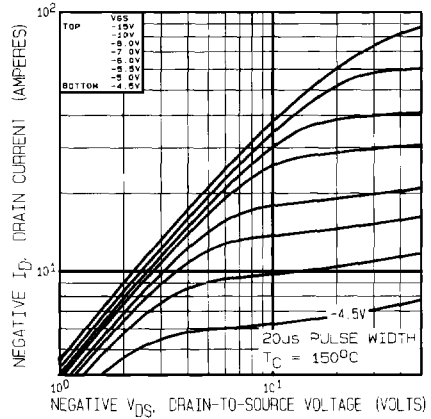


Fig. 2dd – Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF9140

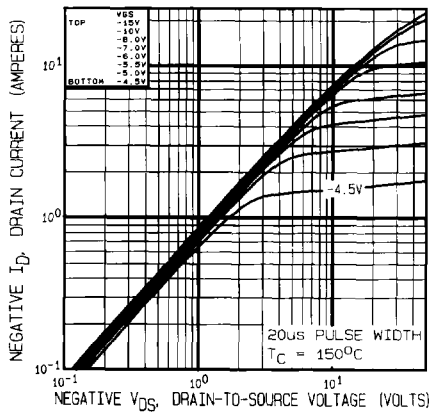


Fig. 2ee – Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF9230

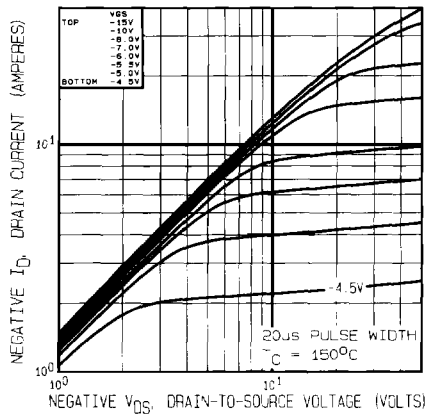


Fig. 2ff – Typical Output Characteristics, $T_C = 150^\circ\text{C}$
IRF9240

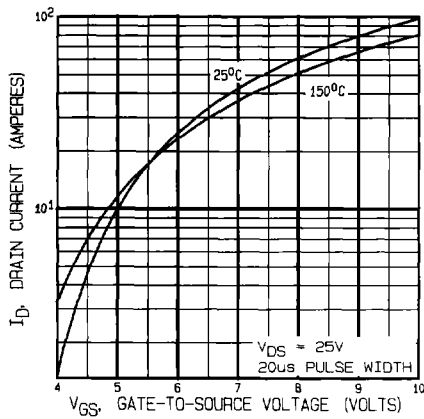


Fig. 3a – Typical Transfer Characteristics
IRF034

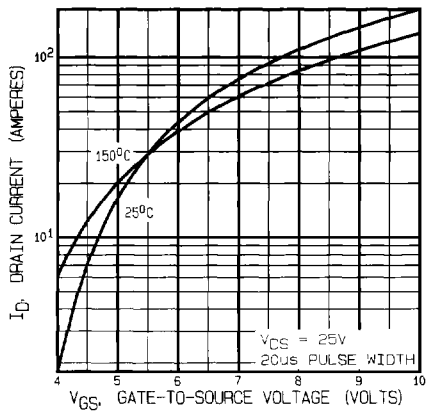


Fig. 3b – Typical Transfer Characteristics
IRF044

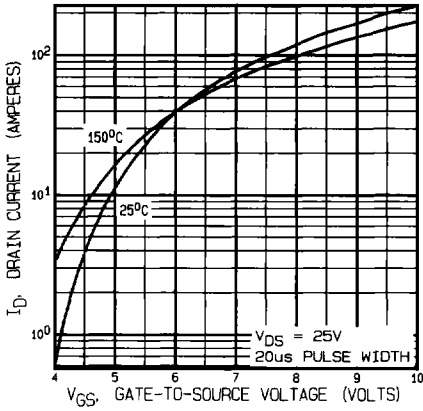


Fig. 3c - Typical Transfer Characteristics IRF054

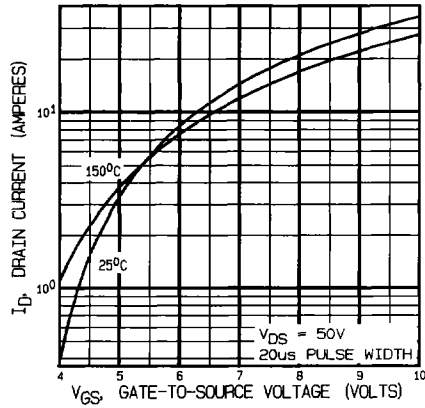


Fig. 3d - Typical Transfer Characteristics IRF130

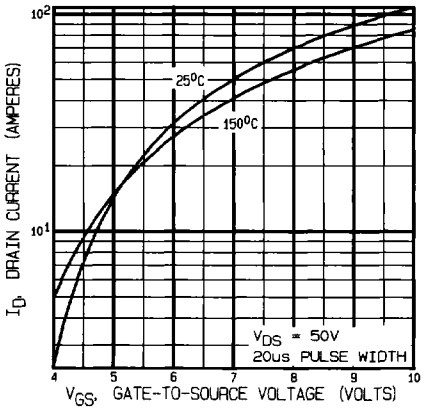


Fig. 3e - Typical Transfer Characteristics IRF140

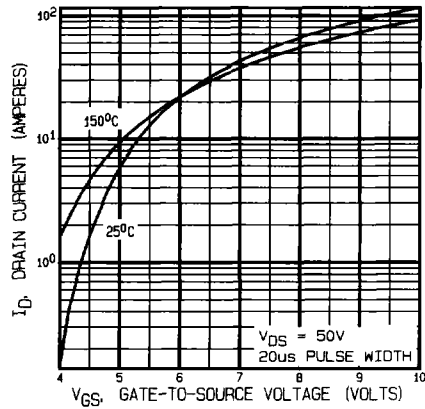


Fig. 3f - Typical Transfer Characteristics IRF150

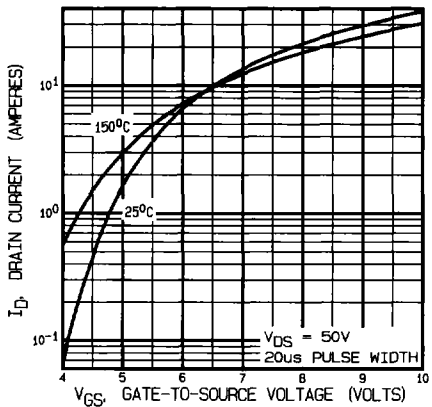


Fig. 3g - Typical Transfer Characteristics IRF230

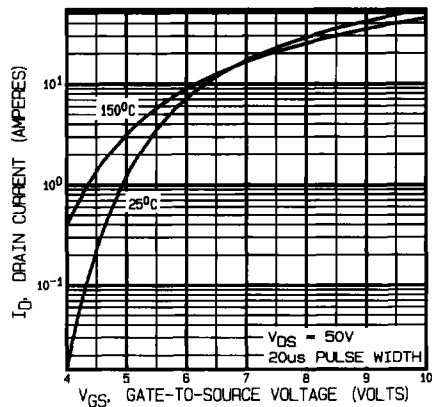
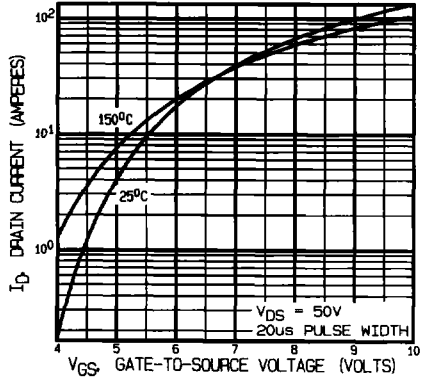
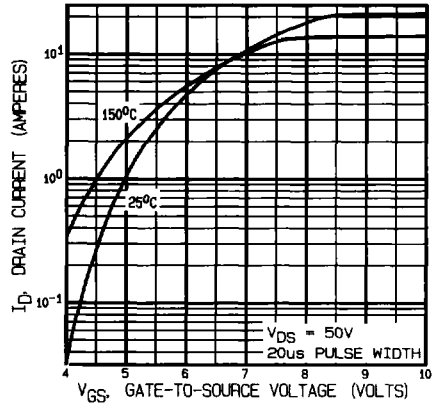


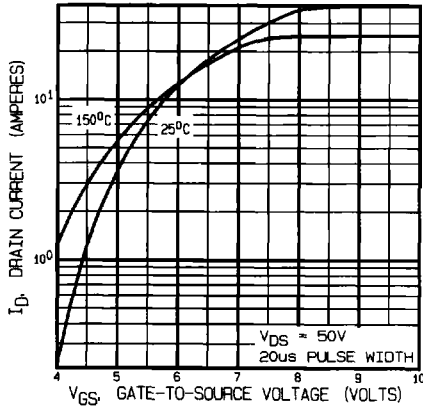
Fig. 3h - Typical Transfer Characteristics IRF240



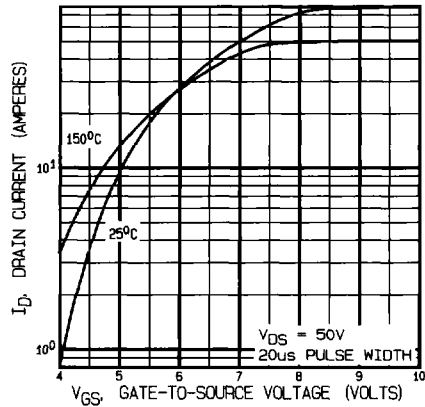
**Fig. 3i - Typical Transfer Characteristics
IRF250**



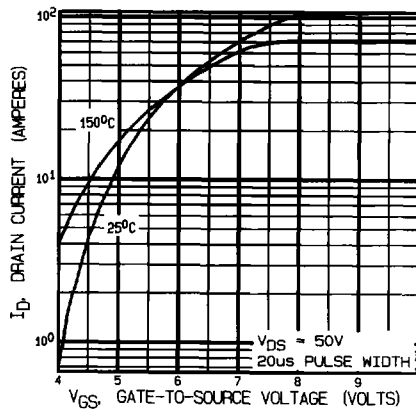
**Fig. 3j - Typical Transfer Characteristics
IRF330**



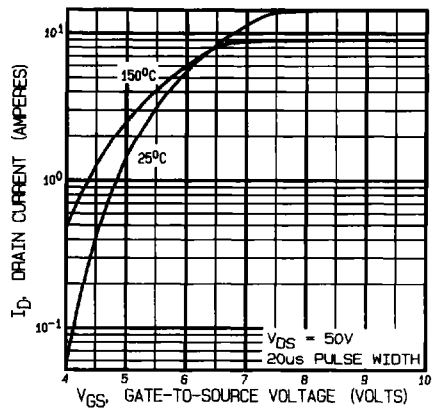
**Fig. 3k - Typical Transfer Characteristics
IRF340**



**Fig. 3l - Typical Transfer Characteristics
IRF350**



**Fig. 3m - Typical Transfer Characteristics
IRF360**



**Fig. 3n - Typical Transfer Characteristics
IRF430**

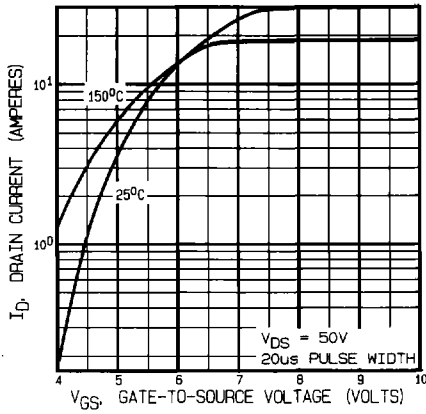


Fig. 3o - Typical Transfer Characteristics
IRF440

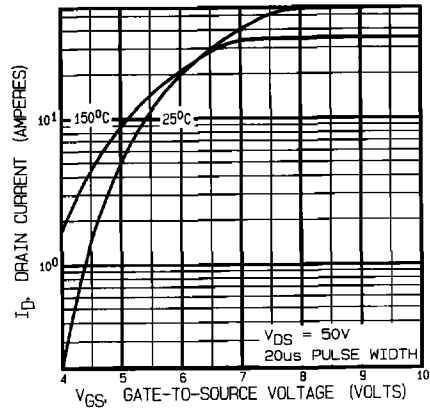


Fig. 3p - Typical Transfer Characteristics
IRF450

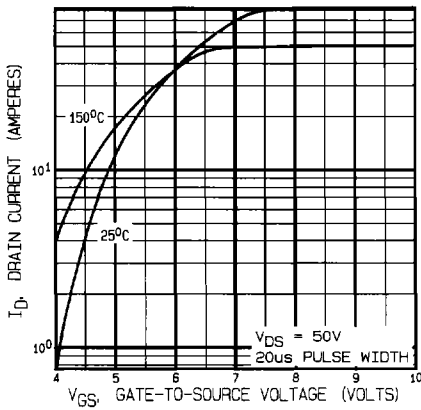


Fig. 3q - Typical Transfer Characteristics
IRF460

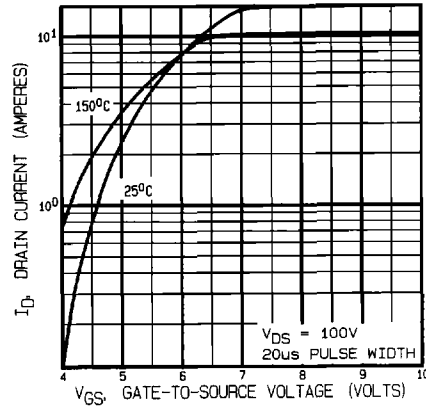


Fig. 3r - Typical Transfer Characteristics
IRFAC30

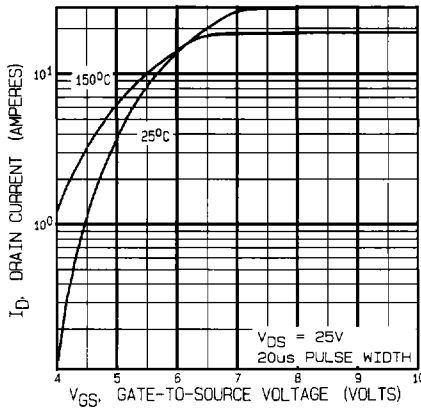


Fig. 3s - Typical Transfer Characteristics
IRFAC40

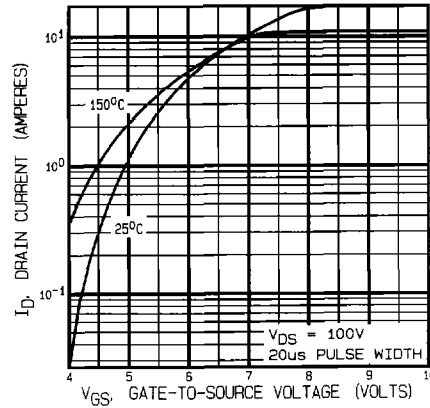


Fig. 3t - Typical Transfer Characteristics
IRFAE30

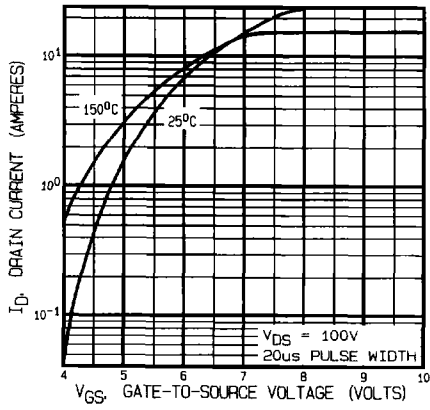


Fig. 3u - Typical Transfer Characteristics IRFAE40

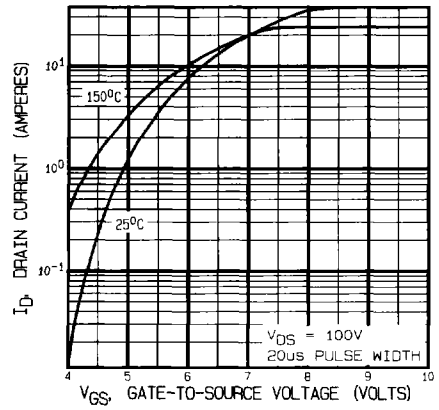


Fig. 3v - Typical Transfer Characteristics IRFAE50

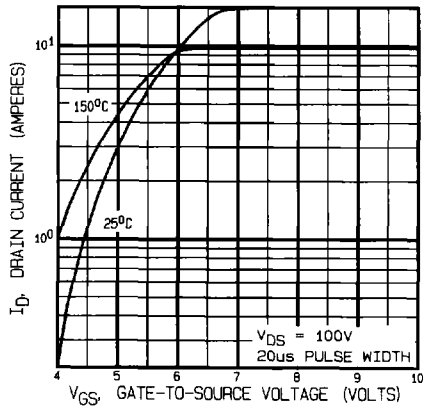


Fig. 3w - Typical Transfer Characteristics IRFAF30

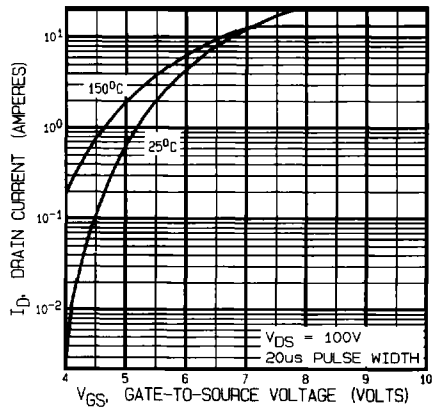


Fig. 3x - Typical Transfer Characteristics IRFAF40

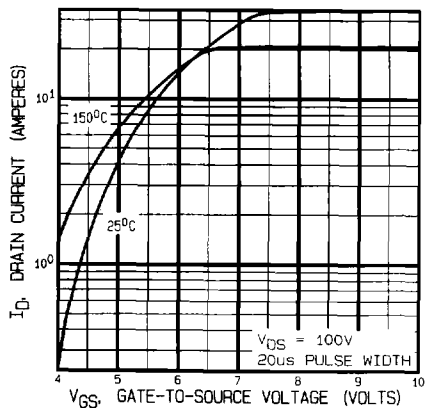


Fig. 3y - Typical Transfer Characteristics IRFAF50

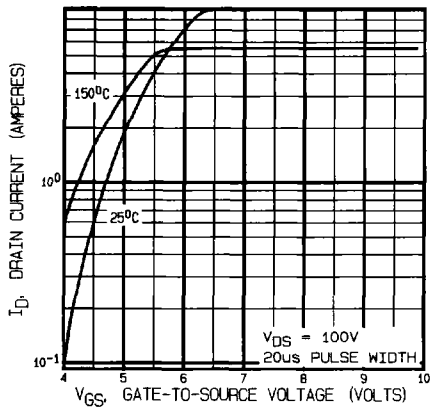


Fig. 3z - Typical Transfer Characteristics IRFAG30

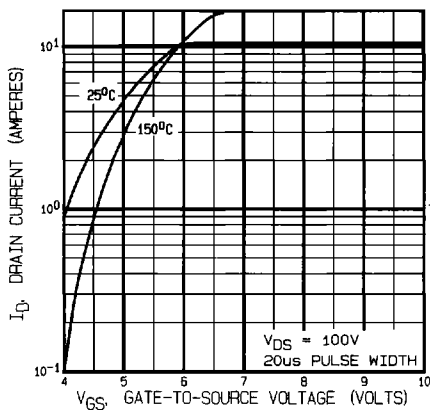


Fig. 3aa - Typical Transfer Characteristics IRFAG40

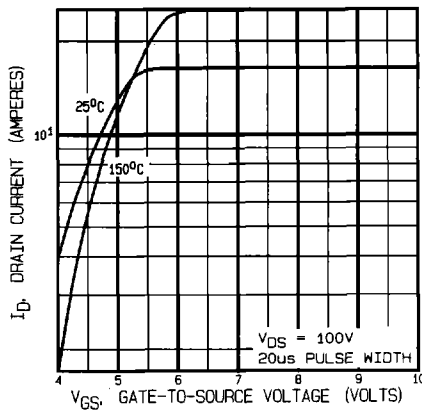


Fig. 3bb - Typical Transfer Characteristics IRFAG50

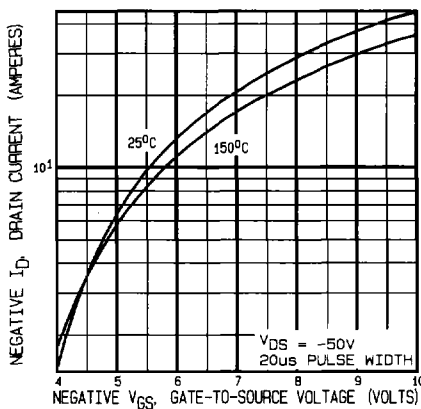


Fig. 3cc - Typical Transfer Characteristics IRF9130

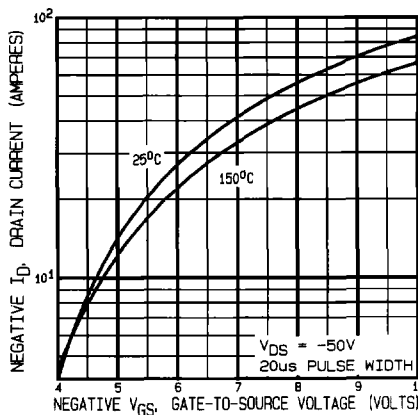


Fig. 3dd - Typical Transfer Characteristics IRF9140

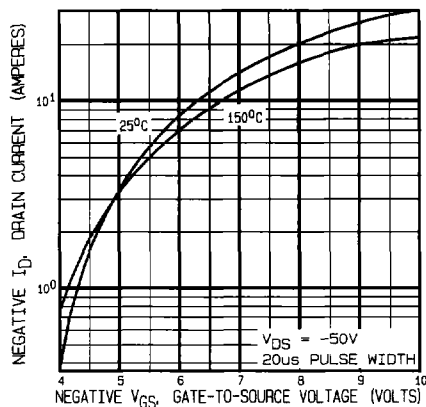


Fig. 3ee - Typical Transfer Characteristics IRF9230

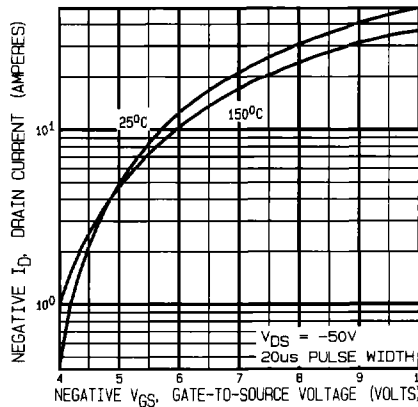


Fig. 3ff - Typical Transfer Characteristics IRF9240

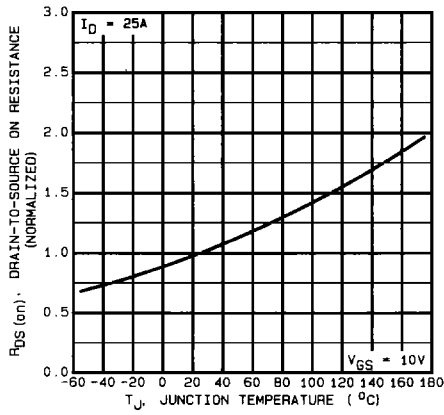


Fig. 4a – Normalized On-Resistance Vs. Temperature
IRF034

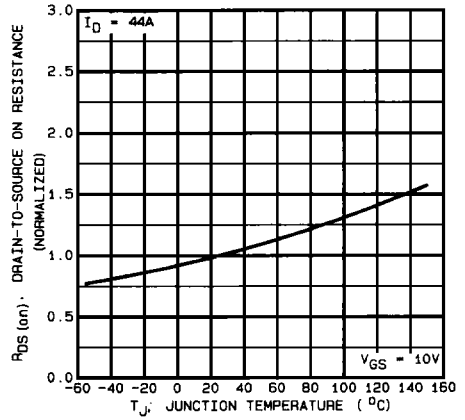


Fig. 4b – Normalized On-Resistance Vs. Temperature
IRF044

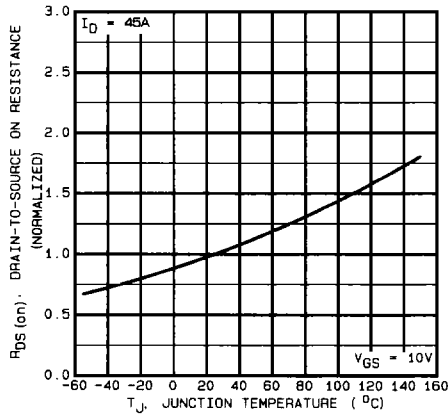


Fig. 4c – Normalized On-Resistance Vs. Temperature
IRF054

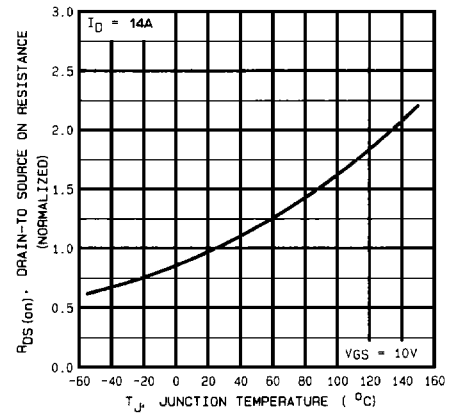


Fig. 4d – Normalized On-Resistance Vs. Temperature
IRF130

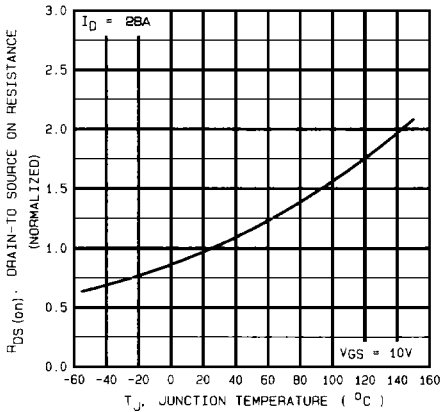


Fig. 4e – Normalized On-Resistance Vs. Temperature
IRF140

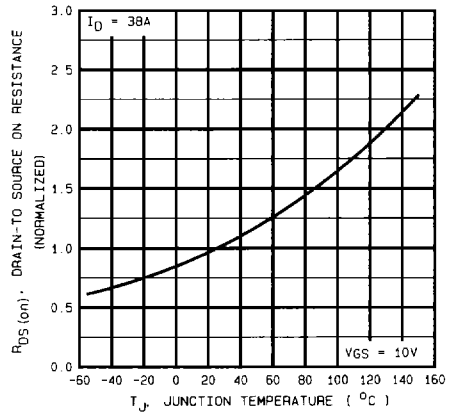


Fig. 4f – Normalized On-Resistance Vs. Temperature
IRF150

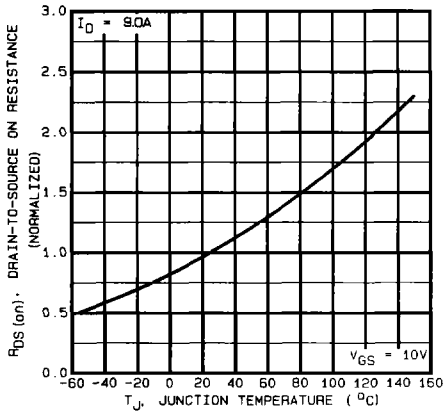


Fig. 4g – Normalized On-Resistance Vs. Temperature IRF230

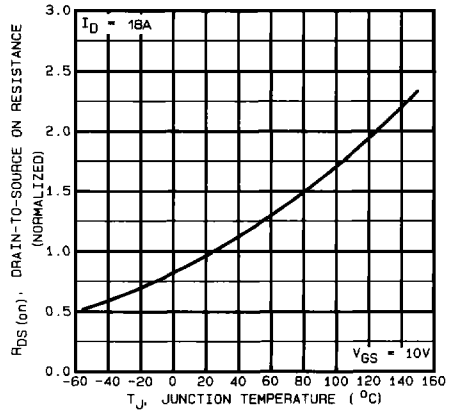


Fig. 4h – Normalized On-Resistance Vs. Temperature IRF240

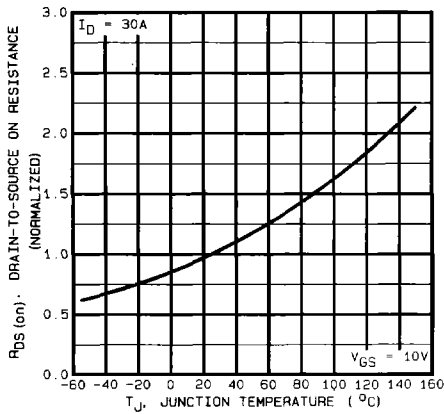


Fig. 4i – Normalized On-Resistance Vs. Temperature IRF250

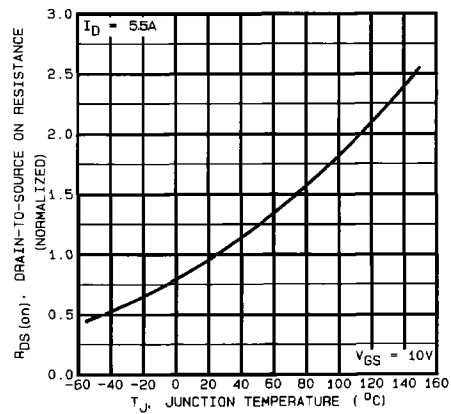


Fig. 4j – Normalized On-Resistance Vs. Temperature IRF330

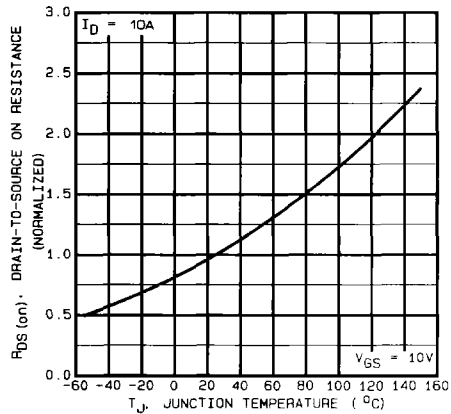


Fig. 4k – Normalized On-Resistance Vs. Temperature IRF340

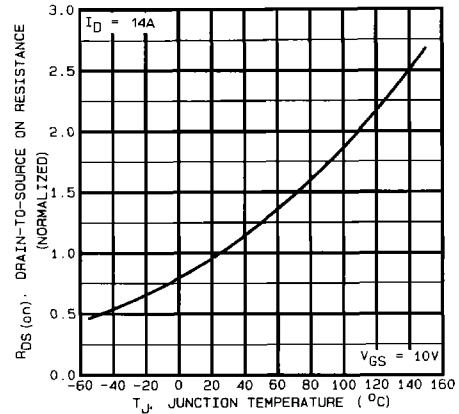


Fig. 4l – Normalized On-Resistance Vs. Temperature IRF350

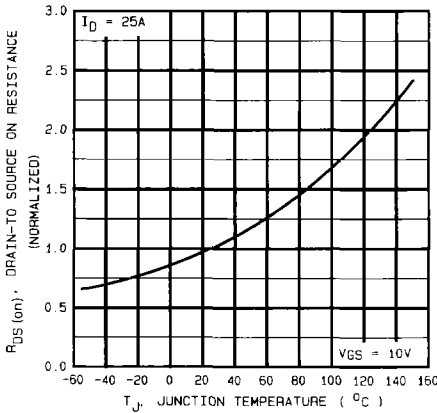


Fig. 4m – Normalized On-Resistance Vs. Temperature
IRF360

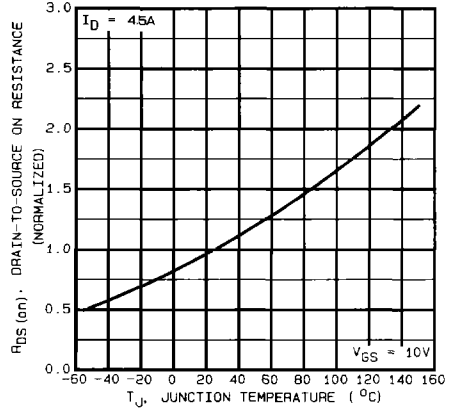


Fig. 4n – Normalized On-Resistance Vs. Temperature
IRF430

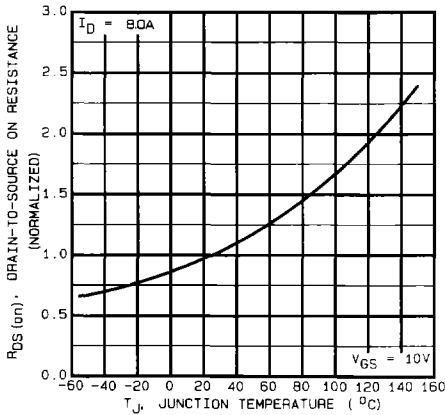


Fig. 4o – Normalized On-Resistance Vs. Temperature
IRF440

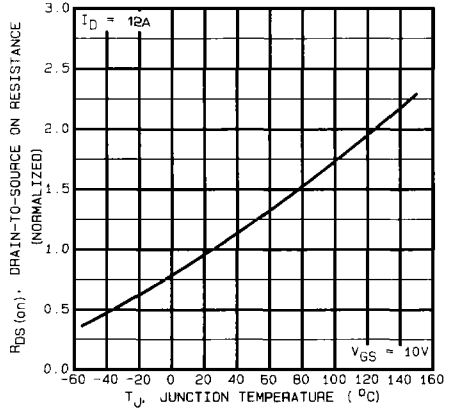


Fig. 4p – Normalized On-Resistance Vs. Temperature
IRF450

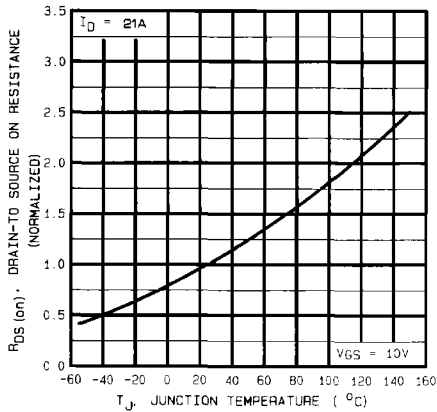


Fig. 4q – Normalized On-Resistance Vs. Temperature
IRF460

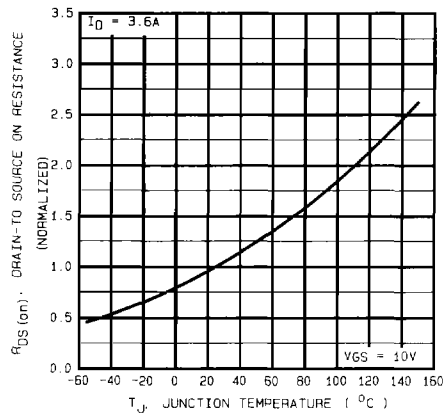


Fig. 4r – Normalized On-Resistance Vs. Temperature
IRFAC30

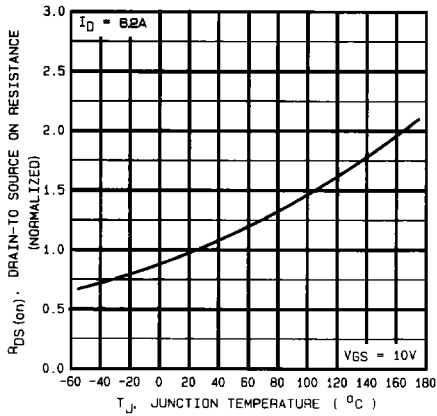


Fig. 4s – Normalized On-Resistance Vs. Temperature IRFAC40

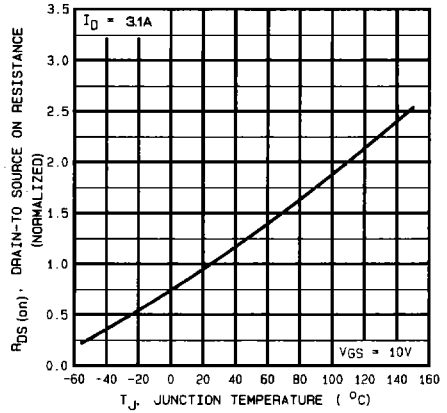


Fig. 4t – Normalized On-Resistance Vs. Temperature IRFAE30

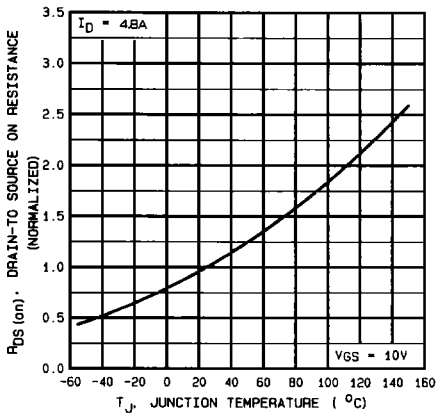


Fig. 4u – Normalized On-Resistance Vs. Temperature IRFAE40

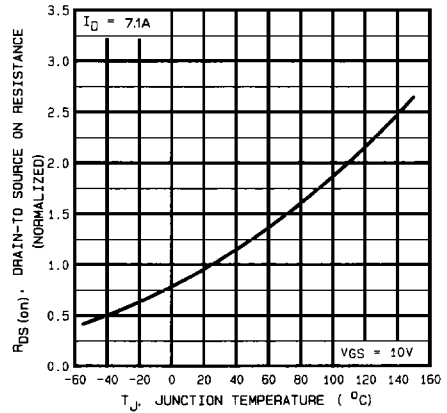


Fig. 4v – Normalized On-Resistance Vs. Temperature IRFAE50

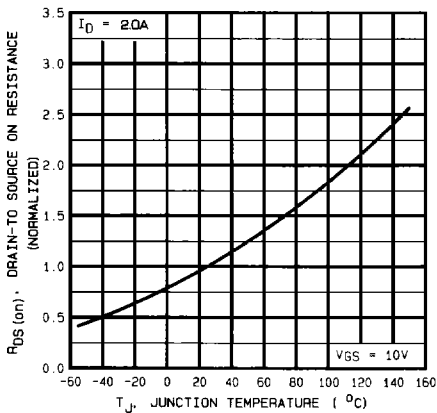


Fig. 4w – Normalized On-Resistance Vs. Temperature IRFAF30

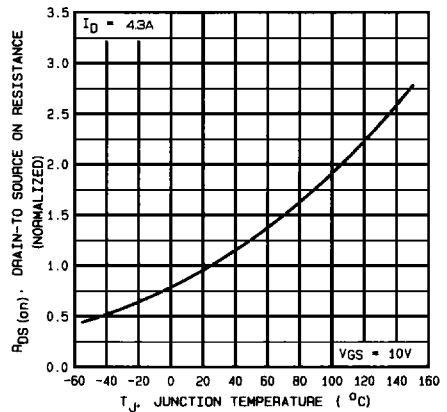


Fig. 4x – Normalized On-Resistance Vs. Temperature IRFAF40

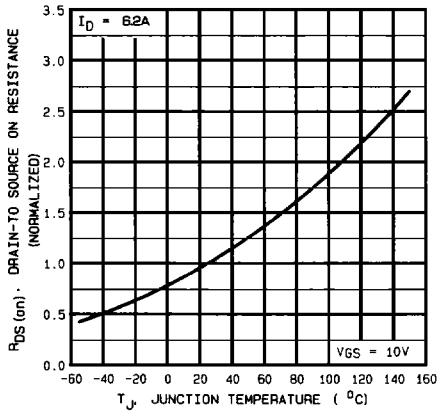


Fig. 4y – Normalized On-Resistance Vs. Temperature IRFAF50

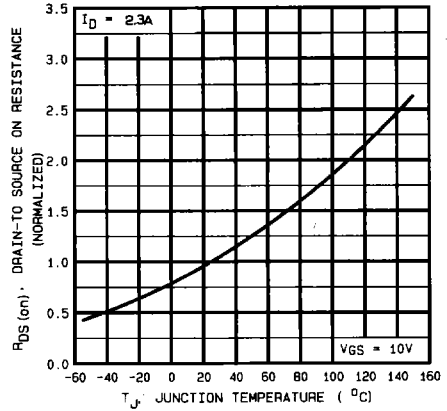


Fig. 4z – Normalized On-Resistance Vs. Temperature IRFAG30

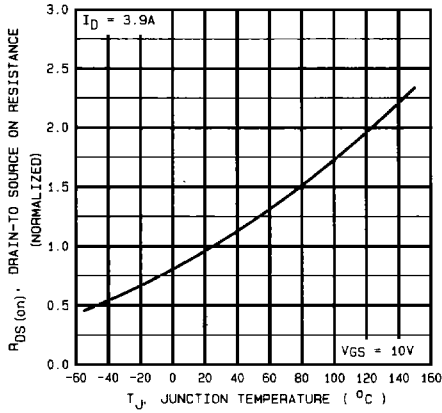


Fig. 4aa – Normalized On-Resistance Vs. Temperature IRFAG40

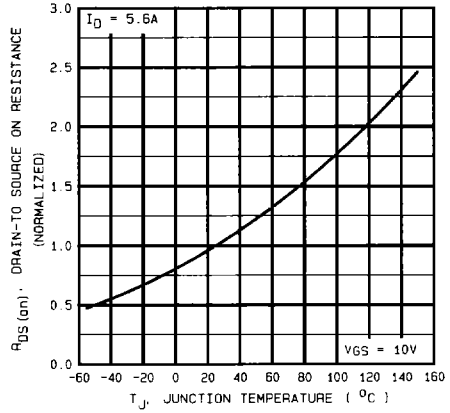


Fig. 4bb – Normalized On-Resistance Vs. Temperature IRFAG50

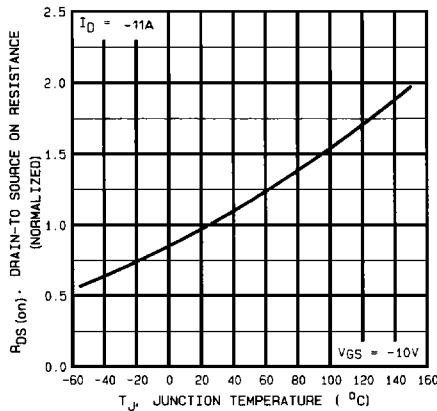


Fig. 4cc – Normalized On-Resistance Vs. Temperature IRF9130

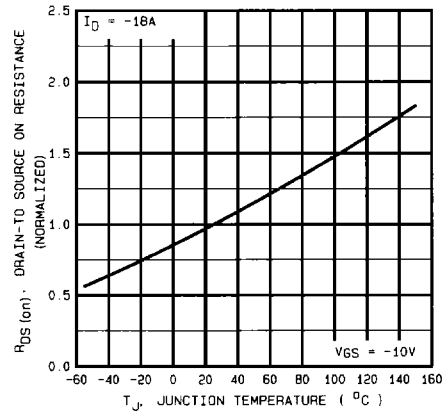


Fig. 4dd – Normalized On-Resistance Vs. Temperature IRF9140

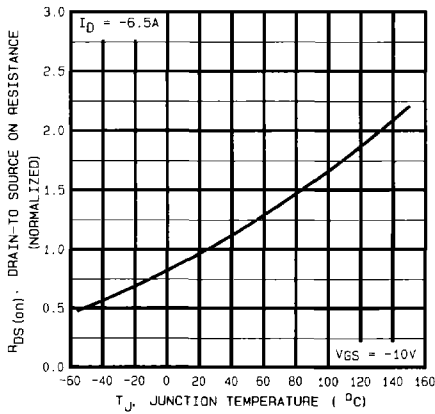


Fig. 4ee - Normalized On-Resistance Vs. Temperature
IRF9230

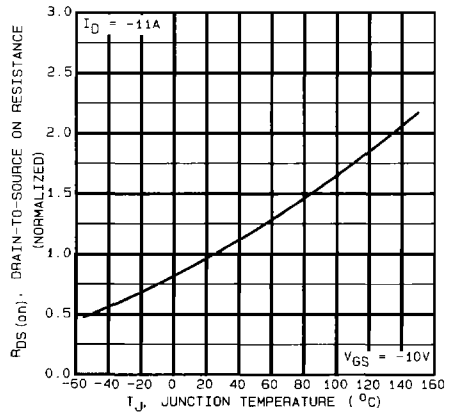


Fig. 4ff - Normalized On-Resistance Vs. Temperature
IRF9240

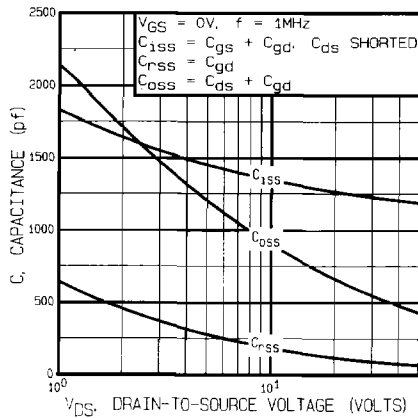


Fig. 5a - Typical Capacitance Vs. Drain-to-Source Voltage
IRF034

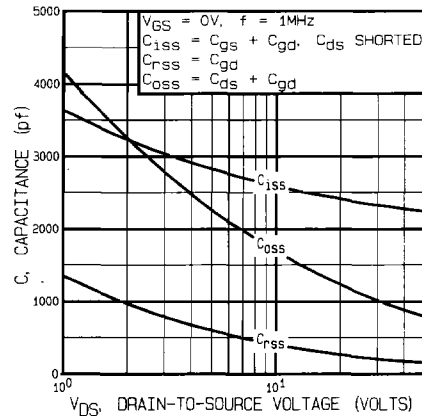


Fig. 5b - Typical Capacitance Vs. Drain-to-Source Voltage
IRF044

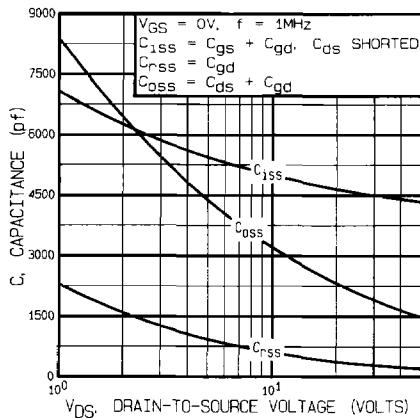


Fig. 5c - Typical Capacitance Vs. Drain-to-Source Voltage
IRF054

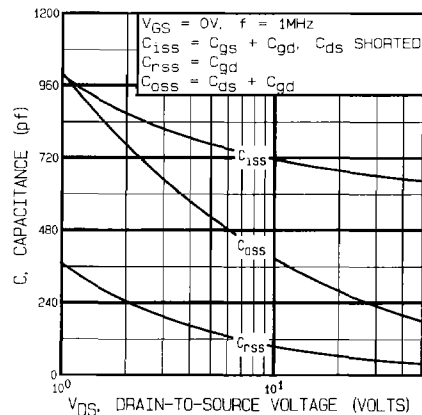


Fig. 5d - Typical Capacitance Vs. Drain-to-Source Voltage
IRF130

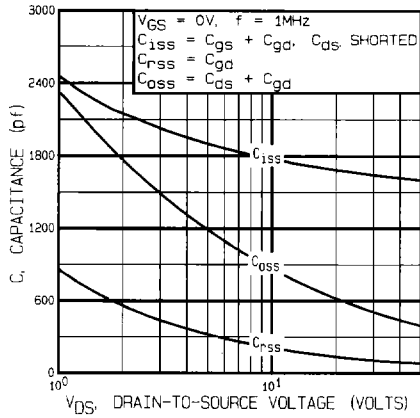


Fig. 5e - Typical Capacitance Vs. Drain-to-Source Voltage
IRF140

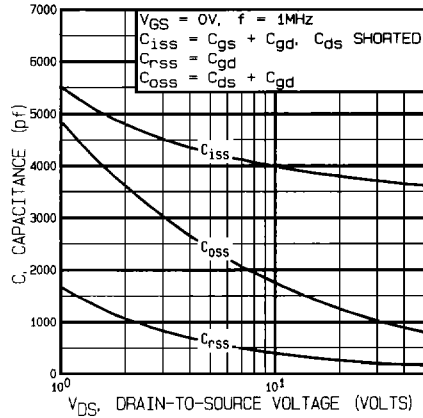


Fig. 5f - Typical Capacitance Vs. Drain-to-Source Voltage
IRF150

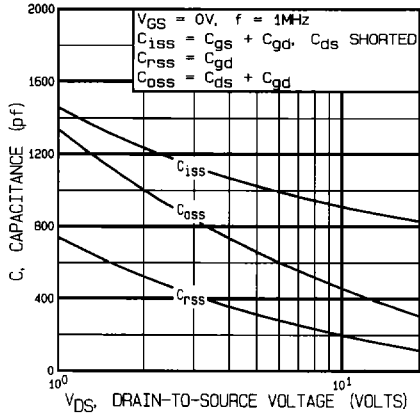


Fig. 5g - Typical Capacitance Vs. Drain-to-Source Voltage
IRF230

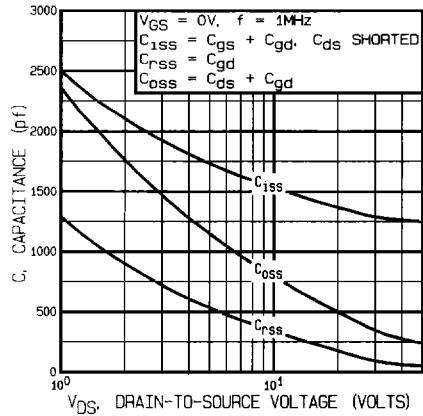


Fig. 5h - Typical Capacitance Vs. Drain-to-Source Voltage
IRF240

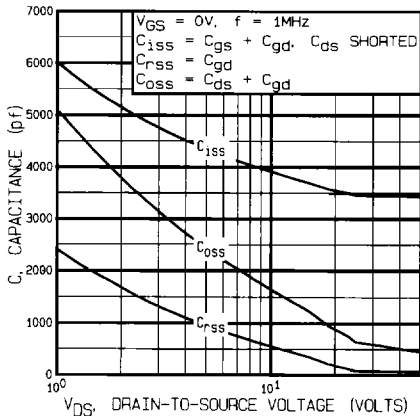


Fig. 5i - Typical Capacitance Vs. Drain-to-Source Voltage
IRF250

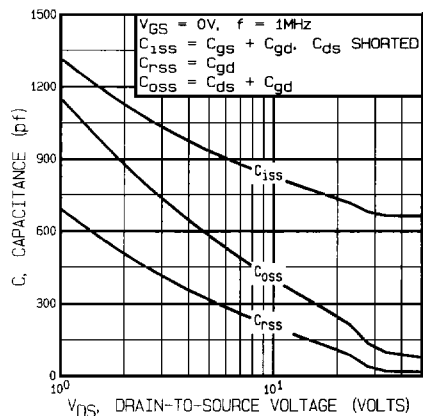


Fig. 5j - Typical Capacitance Vs. Drain-to-Source Voltage
IRF330

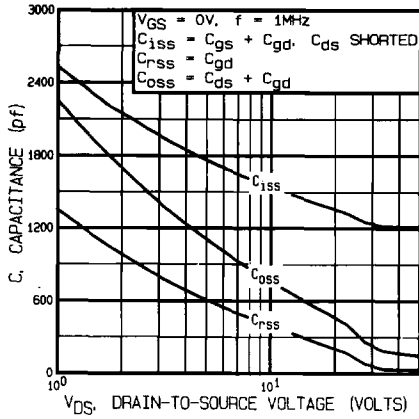


Fig. 5k - Typical Capacitance Vs. Drain-to-Source Voltage
IRF340

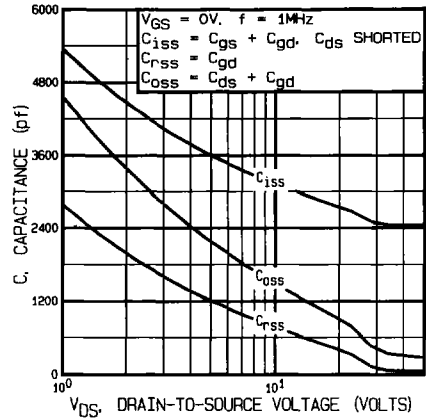


Fig. 5l - Typical Capacitance Vs. Drain-to-Source Voltage
IRF350

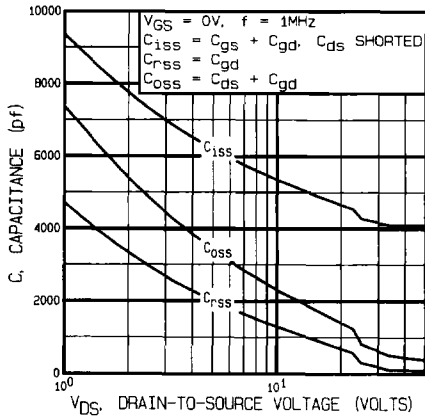


Fig. 5m - Typical Capacitance Vs. Drain-to-Source Voltage
IRF360

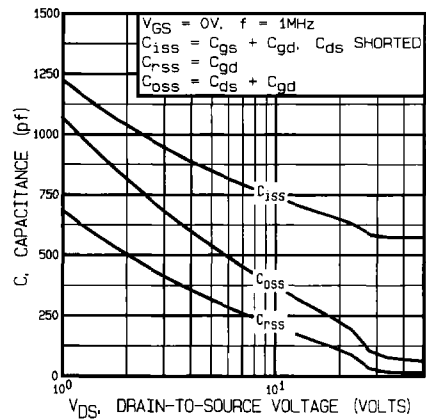


Fig. 5n - Typical Capacitance Vs. Drain-to-Source Voltage
IRF430

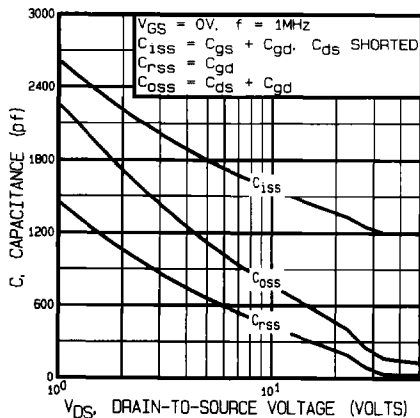


Fig. 5o - Typical Capacitance Vs. Drain-to-Source Voltage
IRF440

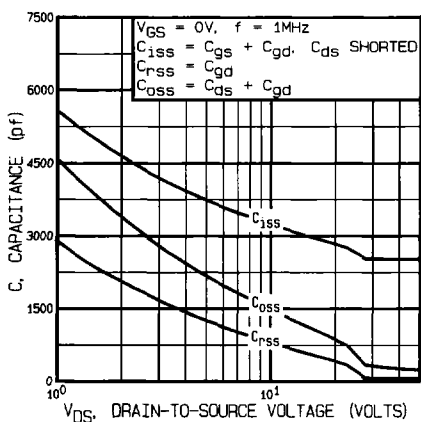


Fig. 5p - Typical Capacitance Vs. Drain-to-Source Voltage
IRF450

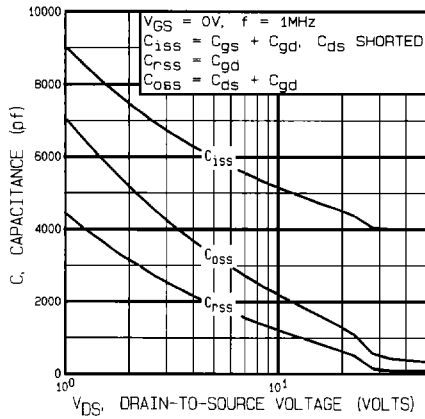


Fig. 5q - Typical Capacitance vs. Drain-to-Source Voltage IRF460

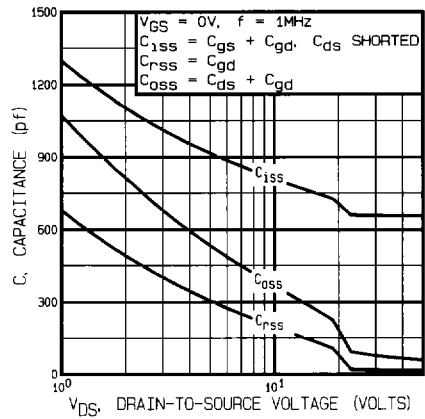


Fig. 5r - Typical Capacitance vs. Drain-to-Source Voltage IRFAC30

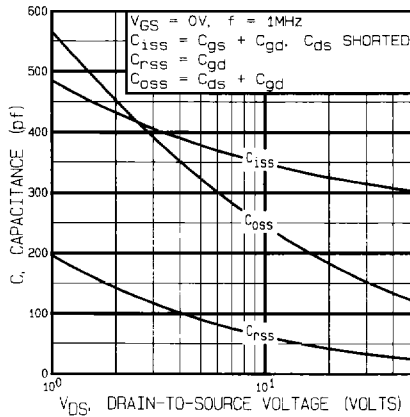


Fig. 5s - Typical Capacitance vs. Drain-to-Source Voltage IRFAC40

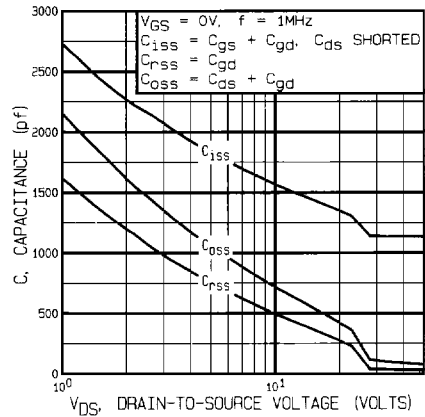


Fig. 5t - Typical Capacitance vs. Drain-to-Source Voltage IRFAE30

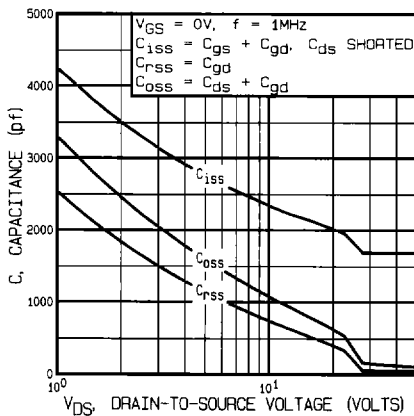


Fig. 5u - Typical Capacitance vs. Drain-to-Source Voltage IRFAE40

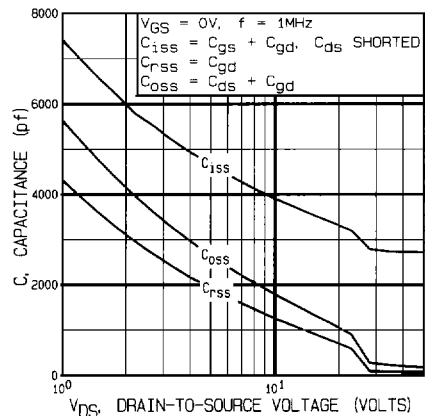


Fig. 5v - Typical Capacitance vs. Drain-to-Source Voltage IRFAE50

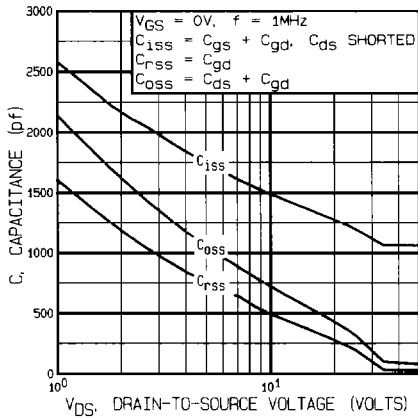


Fig. 5w - Typical Capacitance Vs. Drain-to-Source Voltage IRFAF30

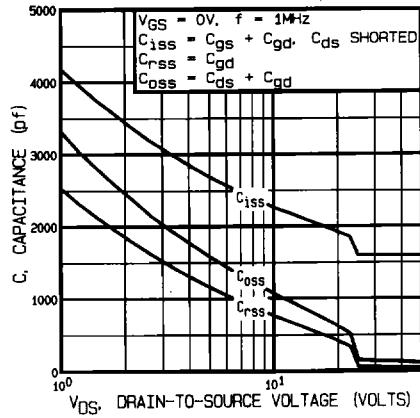


Fig. 5x - Typical Capacitance Vs. Drain-to-Source Voltage IRFAF40

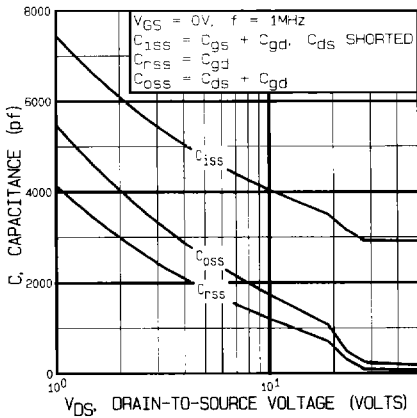


Fig. 5y - Typical Capacitance Vs. Drain-to-Source Voltage IRFAF50

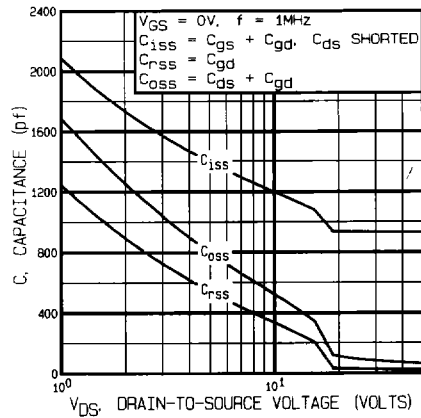


Fig. 5z - Typical Capacitance Vs. Drain-to-Source Voltage IRFAG30

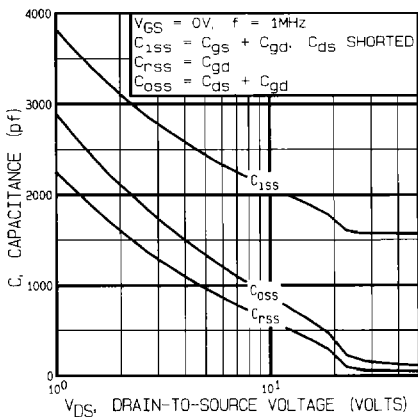


Fig. 5aa - Typical Capacitance Vs. Drain-to-Source Voltage IRFAG40

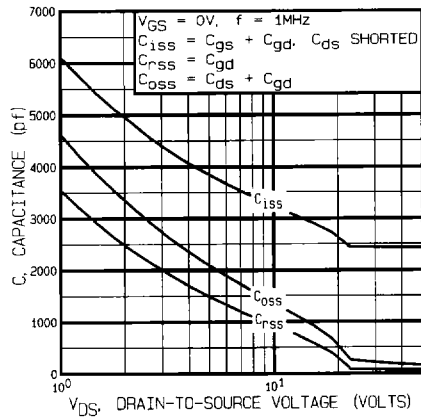


Fig. 5bb - Typical Capacitance Vs. Drain-to-Source Voltage IRFAG50

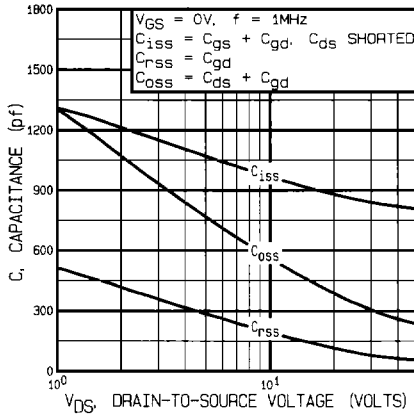


Fig. 5cc - Typical Capacitance Vs. Drain-to-Source Voltage IRF9130

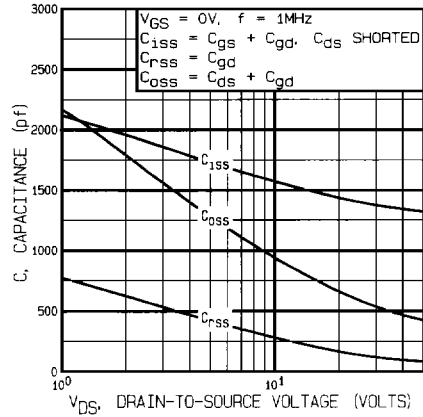


Fig. 5dd - Typical Capacitance Vs. Drain-to-Source Voltage IRF9140

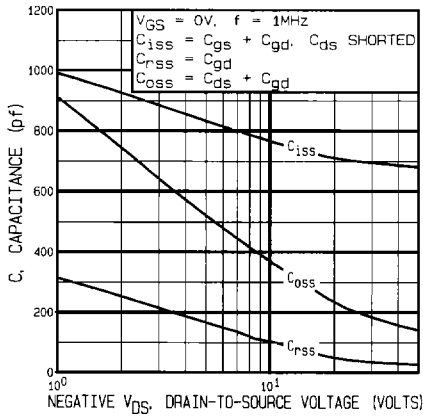


Fig. 5ee - Typical Capacitance Vs. Drain-to-Source Voltage IRF9230

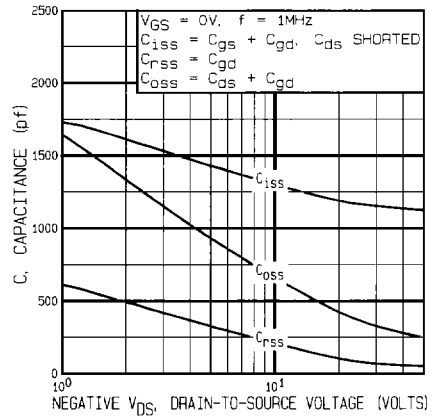


Fig. 5ff - Typical Capacitance Vs. Drain-to-Source Voltage IRF9240

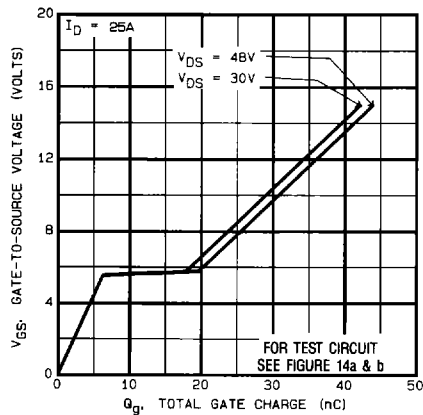


Fig. 6a - Typical Gate Charge Vs. Gate-to-Source Voltage IRF034

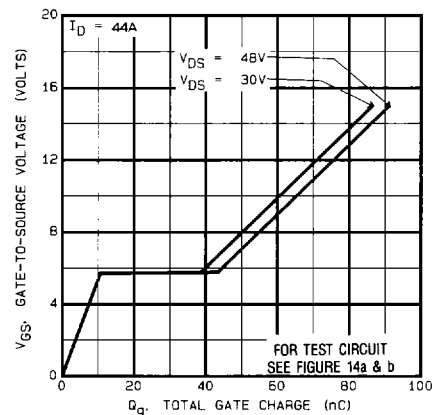


Fig. 6b - Typical Gate Charge Vs. Gate-to-Source Voltage IRF044

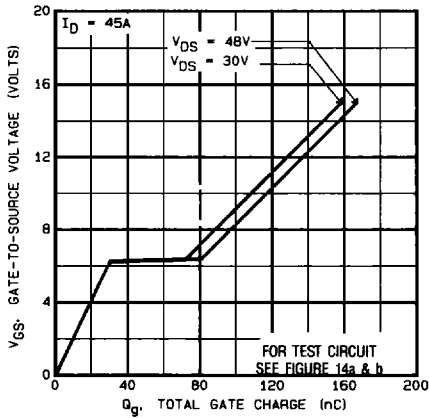


Fig. 6c - Typical Gate Charge Vs. Gate-to-Source Voltage IRF054

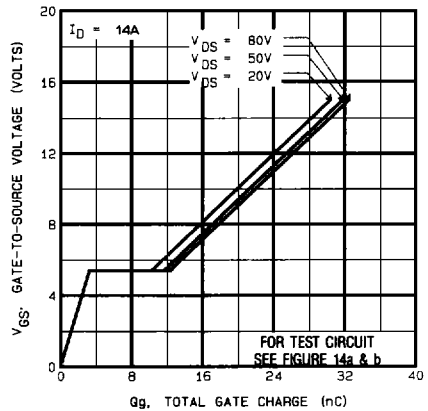


Fig. 6d - Typical Gate Charge Vs. Gate-to-Source Voltage IRF130

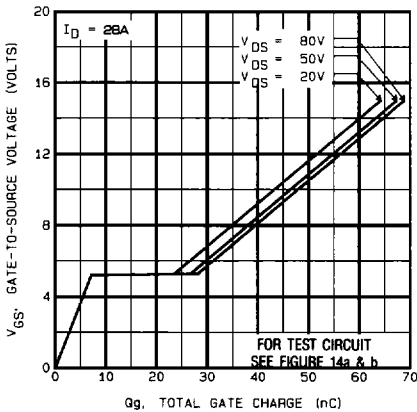


Fig. 6e - Typical Gate Charge Vs. Gate-to-Source Voltage IRF140

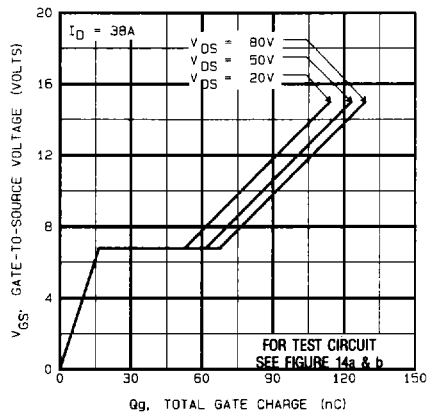


Fig. 6f - Typical Gate Charge Vs. Gate-to-Source Voltage IRF150

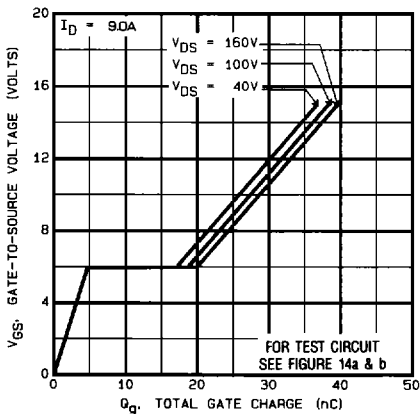


Fig. 6g - Typical Gate Charge Vs. Gate-to-Source Voltage IRF230

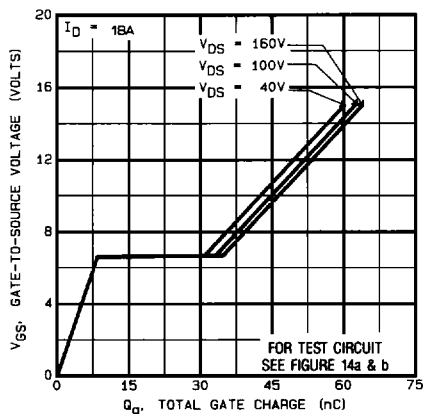


Fig. 6h - Typical Gate Charge Vs. Gate-to-Source Voltage IRF240

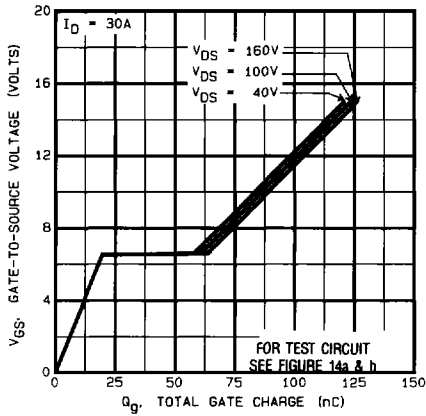


Fig. 6i - Typical Gate Charge Vs. Gate-to-Source Voltage
IRF250

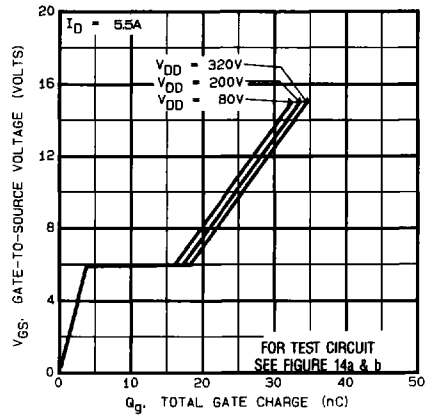


Fig. 6j - Typical Gate Charge Vs. Gate-to-Source Voltage
IRF330

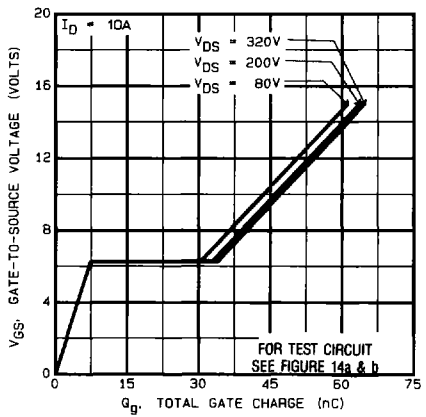


Fig. 6k - Typical Gate Charge Vs. Gate-to-Source Voltage
IRF340

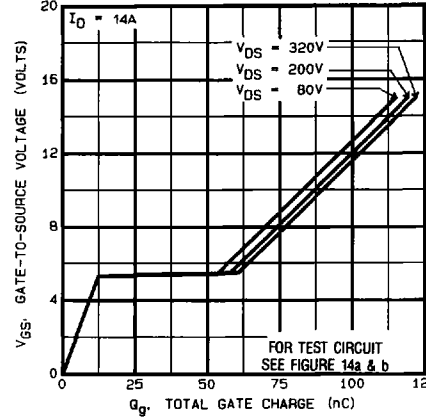


Fig. 6l - Typical Gate Charge Vs. Gate-to-Source Voltage
IRF350

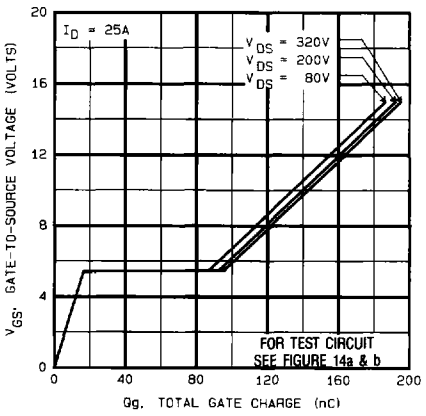


Fig. 6m - Typical Gate Charge Vs. Gate-to-Source Voltage
IRF360

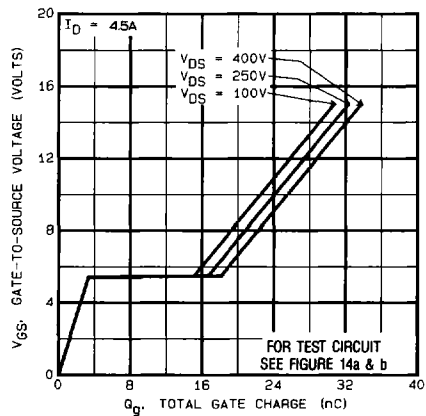


Fig. 6n - Typical Gate Charge Vs. Gate-to-Source Voltage
IRF430

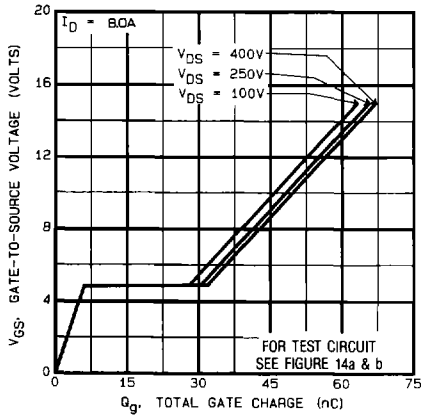


Fig. 6o - Typical Gate Charge Vs. Gate-to-Source Voltage IRF440

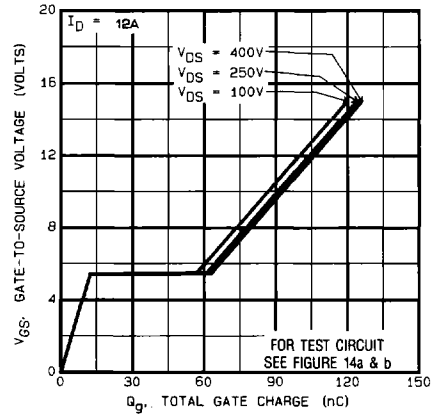


Fig. 6p - Typical Gate Charge Vs. Gate-to-Source Voltage IRF450

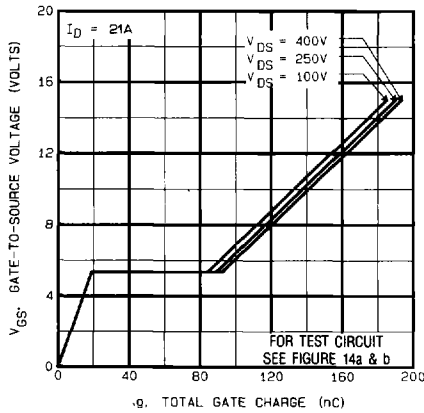


Fig. 6q - Typical Gate Charge Vs. Gate-to-Source Voltage IRF460

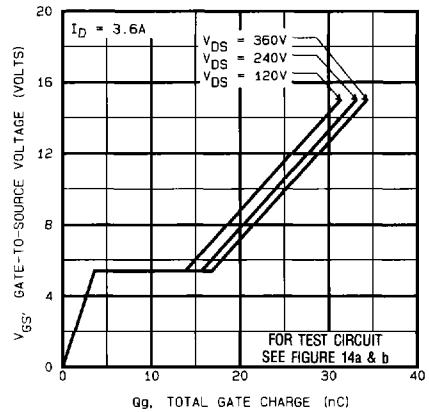


Fig. 6r - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAC30

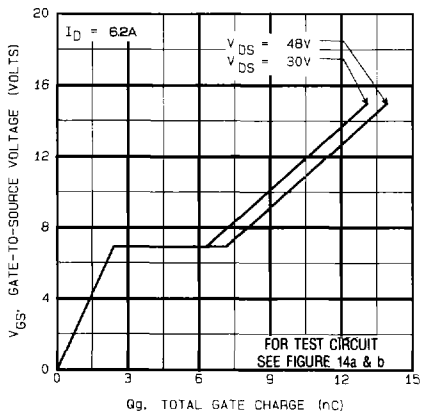


Fig. 6s - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAC40

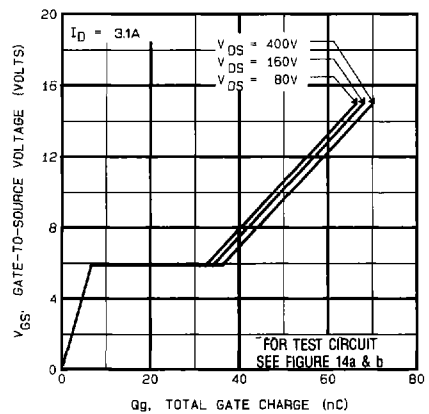


Fig. 6t - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAE30

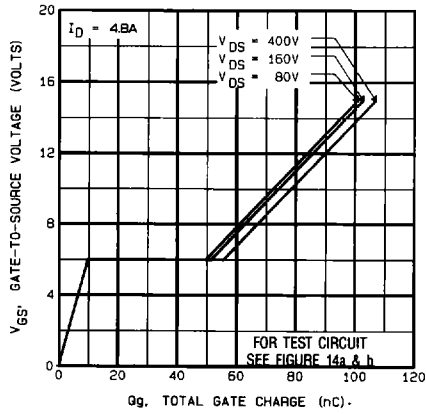


Fig. 6u - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAE40

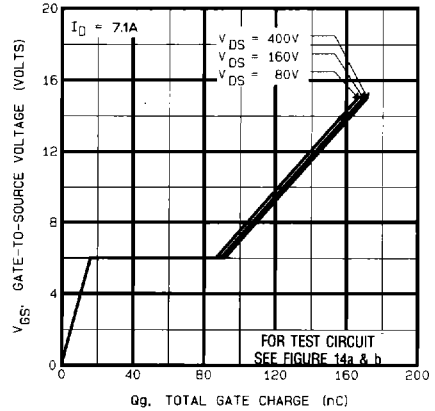


Fig. 6v - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAE50

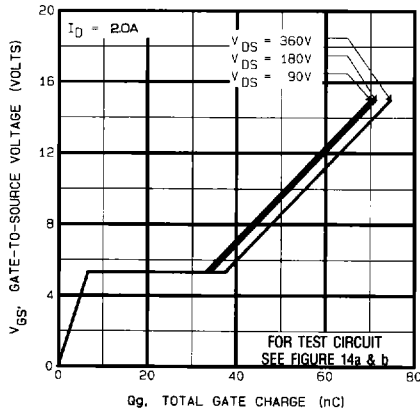


Fig. 6w - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAF30

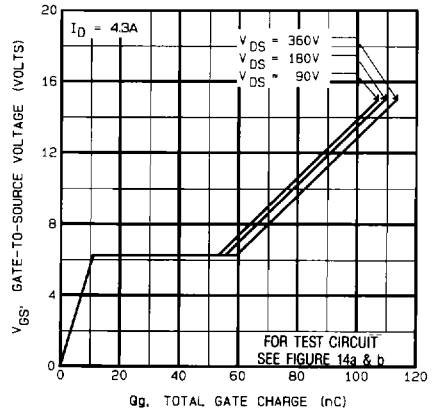


Fig. 6x - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAF40

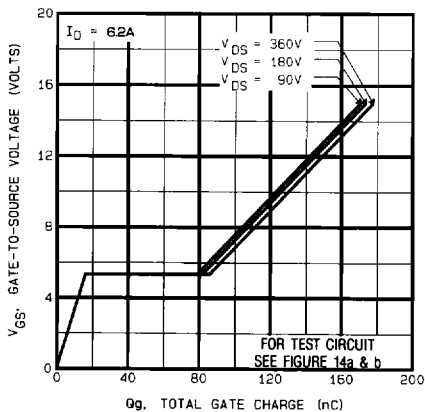


Fig. 6y - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAF50

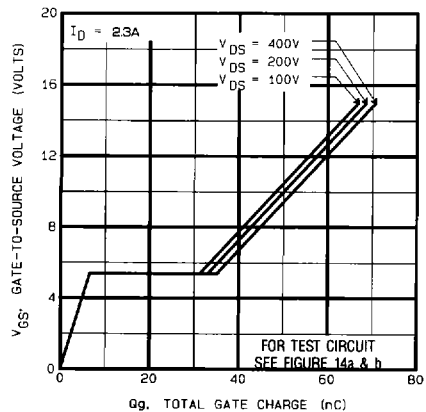


Fig. 6z - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAG30

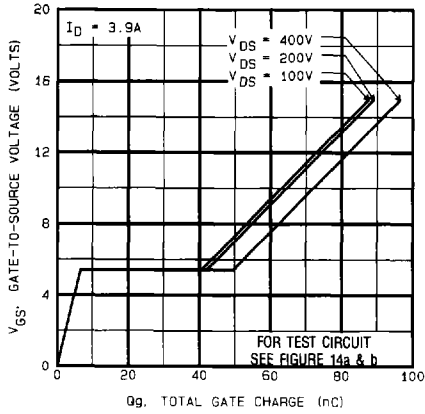


Fig. 6aa - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAG40

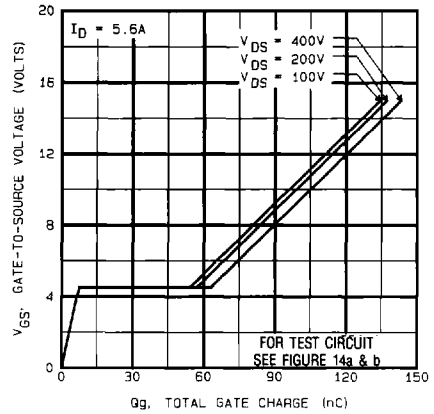


Fig. 6bb - Typical Gate Charge Vs. Gate-to-Source Voltage IRFAG50

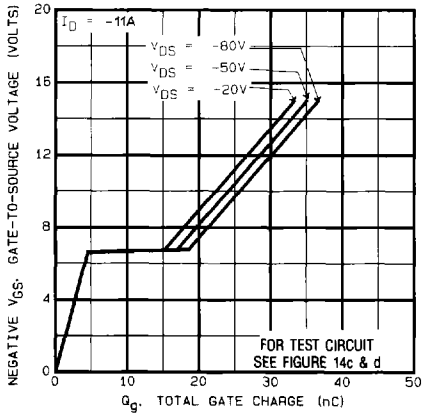


Fig. 6cc - Typical Gate Charge Vs. Gate-to-Source Voltage IRF9130

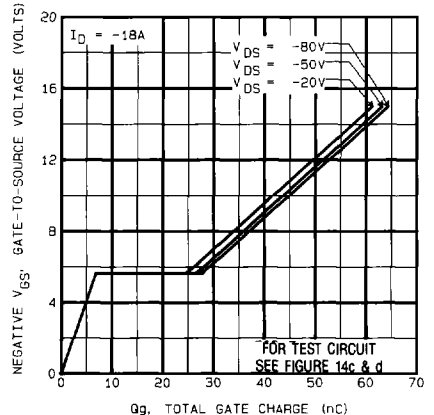


Fig. 6dd - Typical Gate Charge Vs. Gate-to-Source Voltage IRF9140

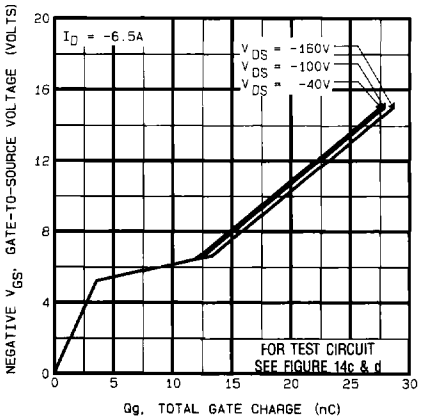


Fig. 6ee - Typical Gate Charge Vs. Gate-to-Source Voltage IRF9230

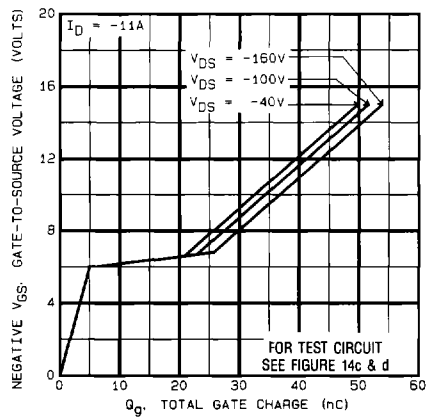
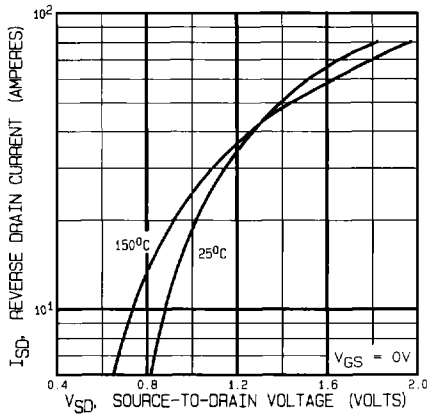
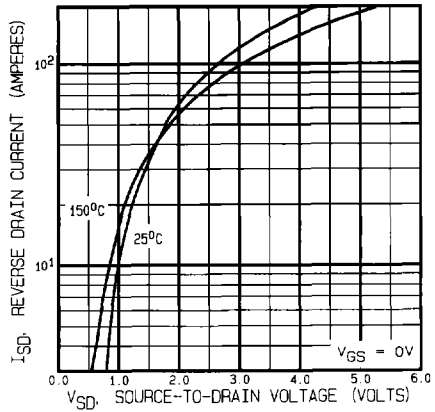
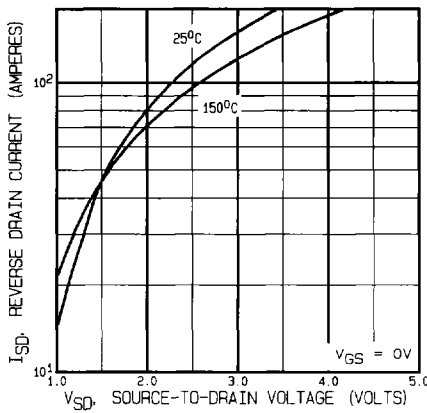
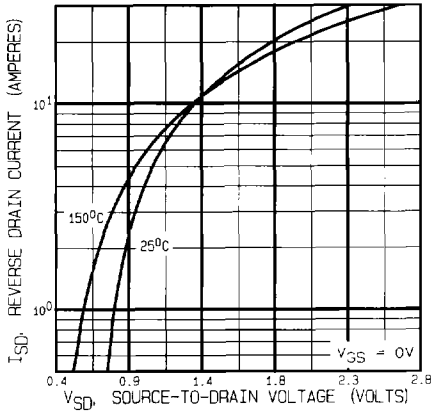
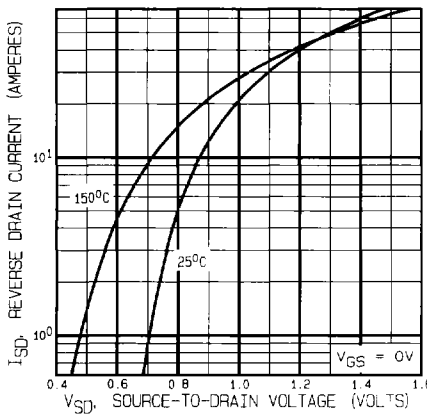
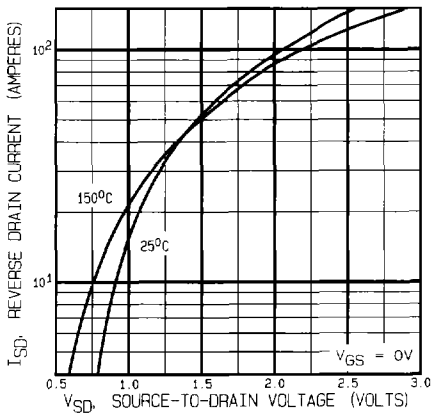


Fig. 6ff - Typical Gate Charge Vs. Gate-to-Source Voltage IRF9240


**Fig. 7a – Typical Source-Drain Diode Forward Voltage
IRF034**

**Fig. 7b – Typical Source-Drain Diode Forward Voltage
IRF044**

**Fig. 7c – Typical Source-Drain Diode Forward Voltage
IRF054**

**Fig. 7d – Typical Source-Drain Diode Forward Voltage
IRF130**

**Fig. 7e – Typical Source-Drain Diode Forward Voltage
IRF140**

**Fig. 7f – Typical Source-Drain Diode Forward Voltage
IRF150**

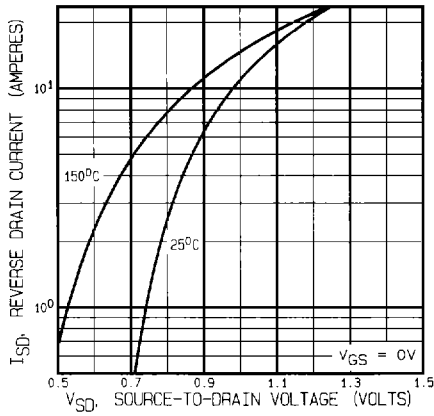


Fig. 7g – Typical Source-Drain Diode Forward Voltage
IRF230

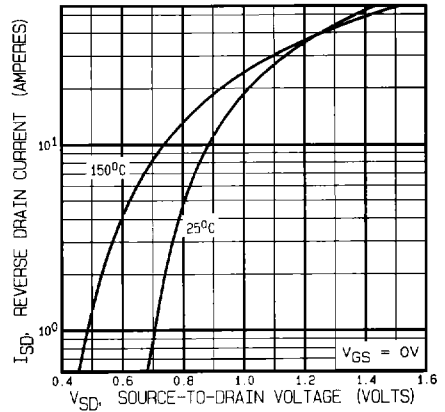


Fig. 7h – Typical Source-Drain Diode Forward Voltage
IRF240

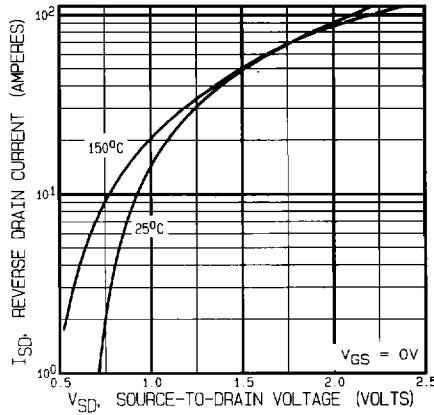


Fig. 7i – Typical Source-Drain Diode Forward Voltage
IRF250

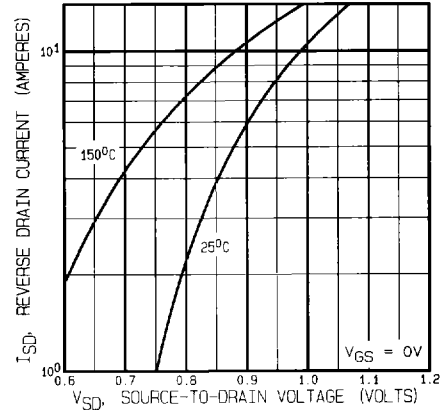


Fig. 7j – Typical Source-Drain Diode Forward Voltage
IRF330

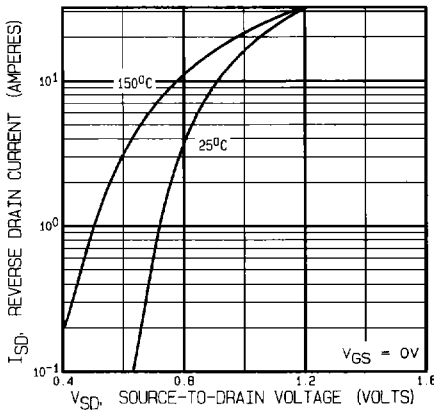


Fig. 7k – Typical Source-Drain Diode Forward Voltage
IRF340

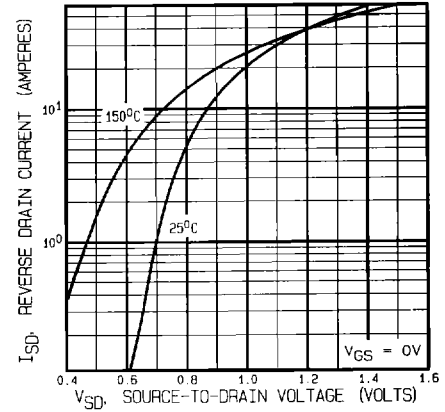


Fig. 7l – Typical Source-Drain Diode Forward Voltage
IRF350

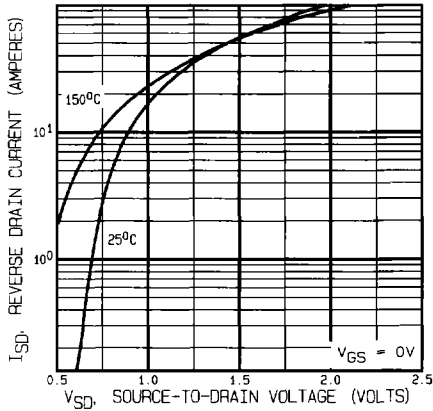


Fig. 7m - Typical Source-Drain Diode Forward Voltage IRF360

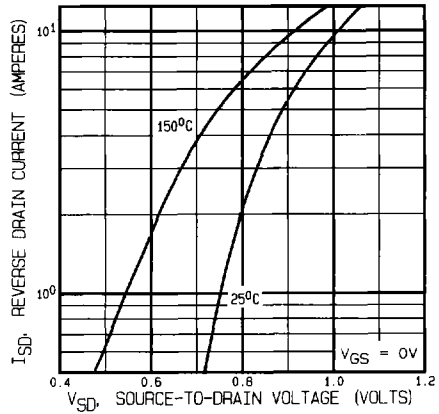


Fig. 7n - Typical Source-Drain Diode Forward Voltage IRF430

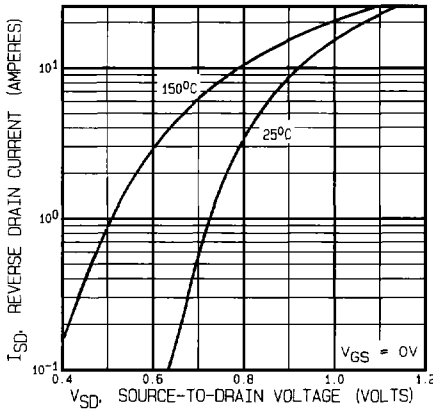


Fig. 7o - Typical Source-Drain Diode Forward Voltage IRF440

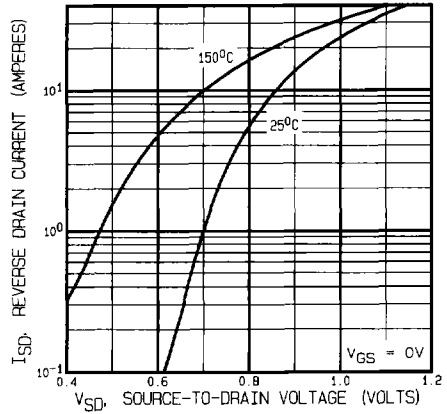


Fig. 7p - Typical Source-Drain Diode Forward Voltage IRF450

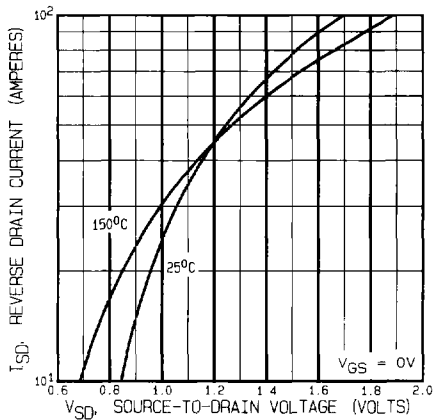


Fig. 7q - Typical Source-Drain Diode Forward Voltage IRF460

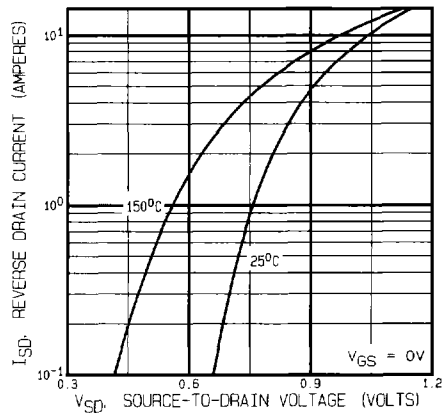


Fig. 7r - Typical Source-Drain Diode Forward Voltage IRFAC30

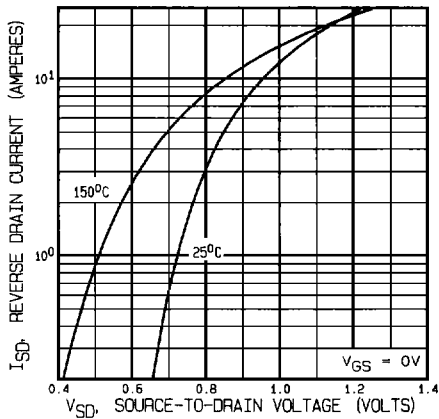


Fig. 7a – Typical Source-Drain Diode Forward Voltage
IRFAC40

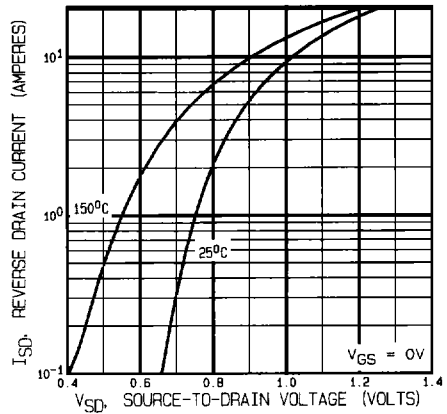


Fig. 7t – Typical Source-Drain Diode Forward Voltage
IRFAE30

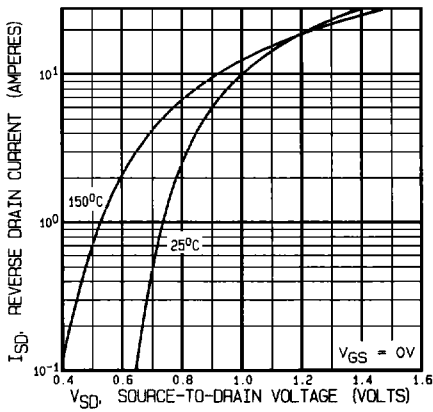


Fig. 7u – Typical Source-Drain Diode Forward Voltage
IRFAE30

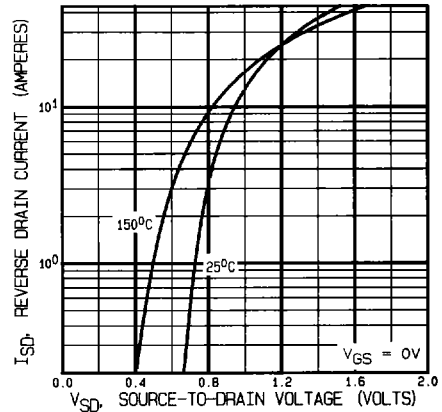


Fig. 7v – Typical Source-Drain Diode Forward Voltage
IRFAE50

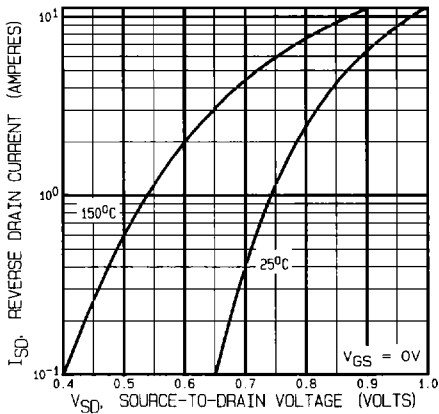


Fig. 7w – Typical Source-Drain Diode Forward Voltage
IRFAF30

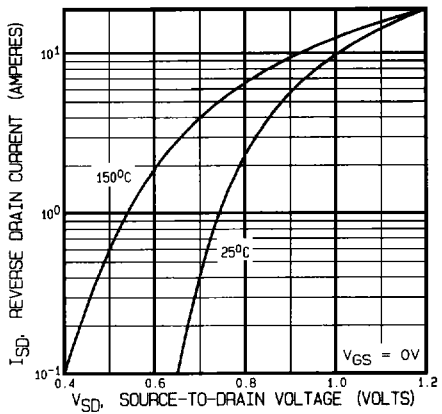


Fig. 7x – Typical Source-Drain Diode Forward Voltage
IRFAF40

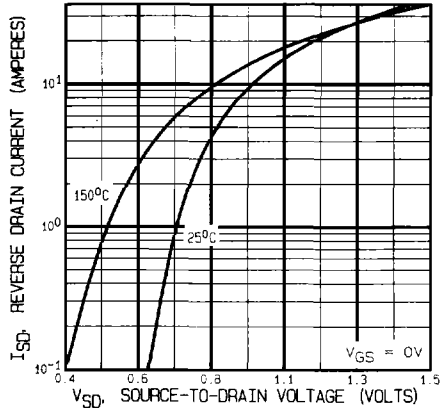


Fig. 7y - Typical Source-Drain Diode Forward Voltage IRFAF50

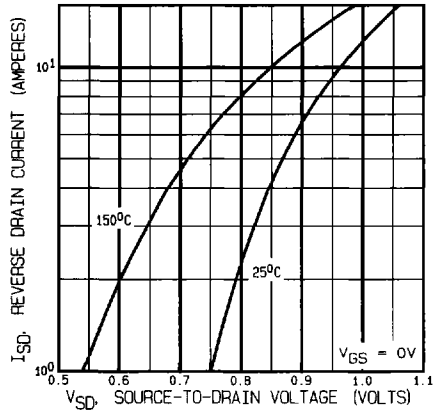


Fig. 7z - Typical Source-Drain Diode Forward Voltage IRFAG30

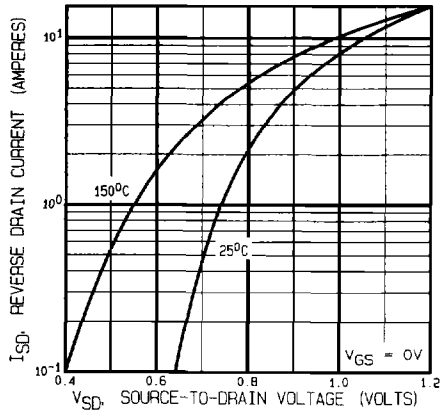


Fig. 7aa - Typical Source-Drain Diode Forward Voltage IRFAG40

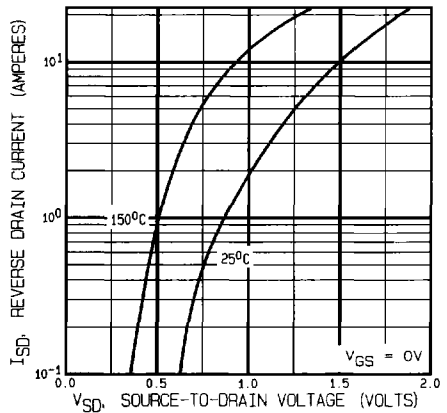


Fig. 7bb - Typical Source-Drain Diode Forward Voltage IRFAG50

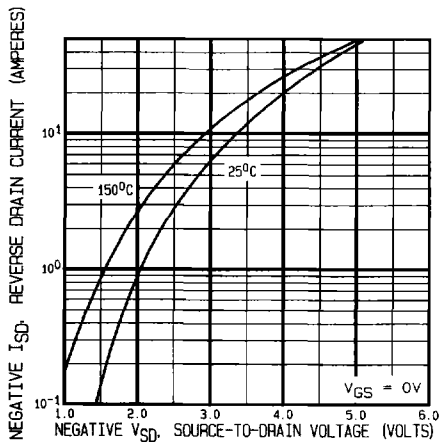


Fig. 7cc - Typical Source-Drain Diode Forward Voltage IRF9130

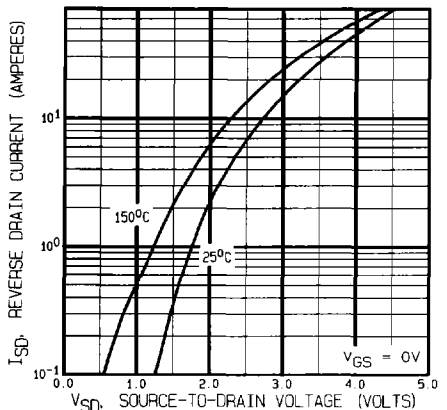


Fig. 7dd - Typical Source-Drain Diode Forward Voltage IRF9140

IRF Series Devices

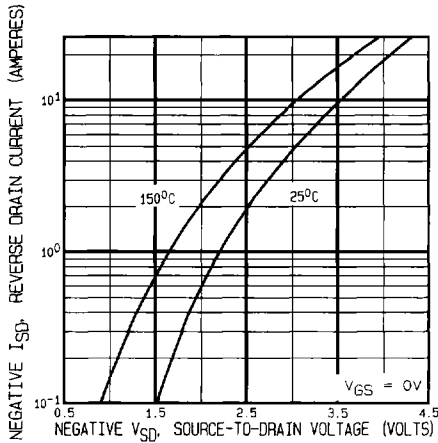


Fig. 7ee - Typical Source-Drain Diode Forward Voltage
IRF9230

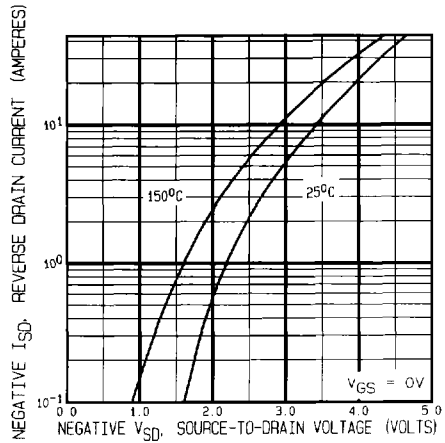


Fig. 7ff - Typical Source-Drain Diode Forward Voltage
IRF9240

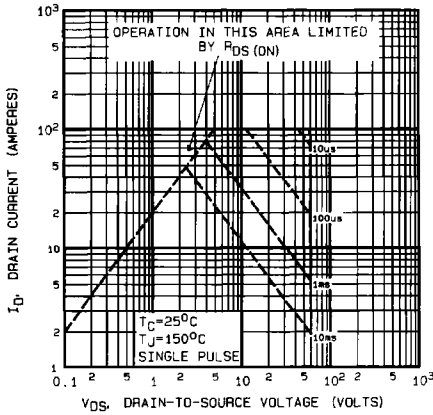


Fig. 8a - Maximum Safe Operating Area
IRF034

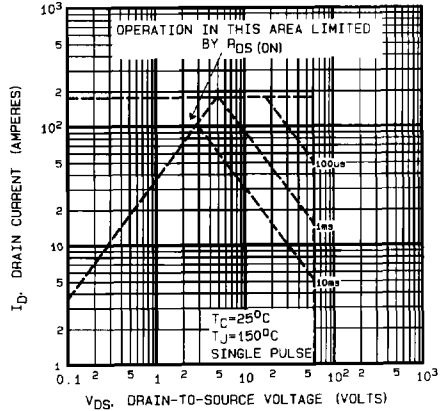


Fig. 8b - Maximum Safe Operating Area
IRF044

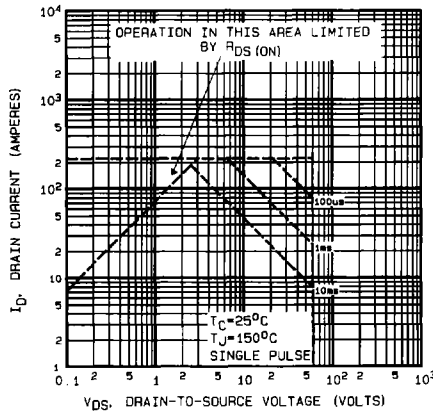


Fig. 8c - Maximum Safe Operating Area
IRF054

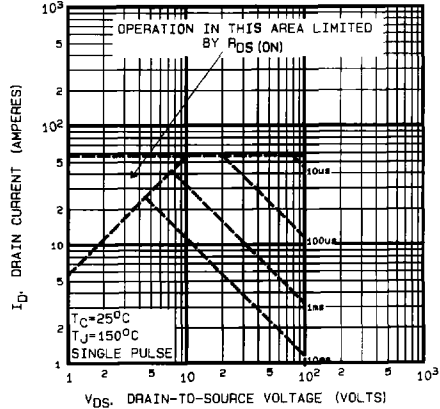


Fig. 8d - Maximum Safe Operating Area
IRF130

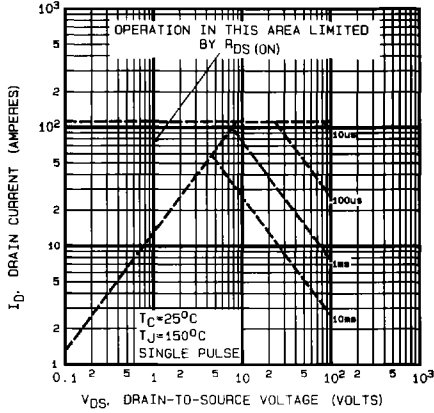


Fig. 8e - Maximum Safe Operating Area IRF140

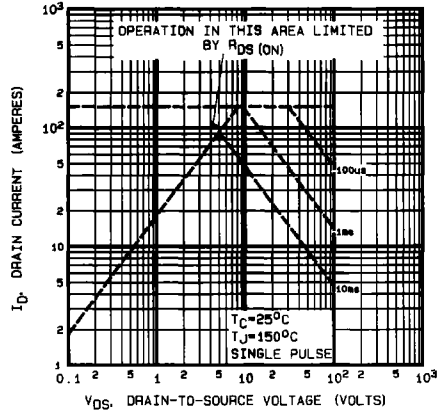


Fig. 8f - Maximum Safe Operating Area IRF150

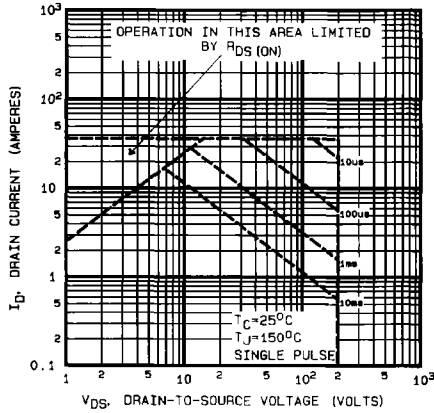


Fig. 8g - Maximum Safe Operating Area IRF230

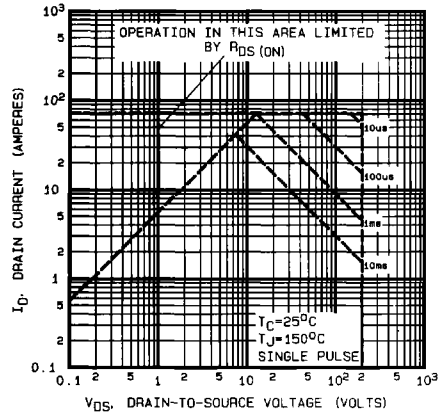


Fig. 8h - Maximum Safe Operating Area IRF240

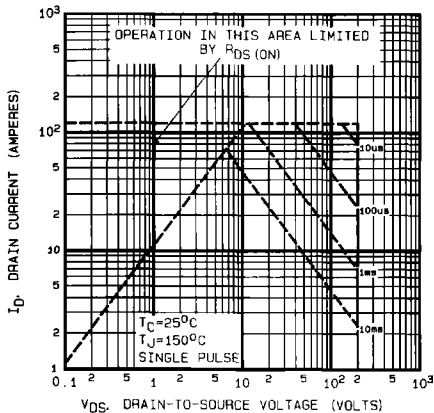


Fig. 8i - Maximum Safe Operating Area IRF250

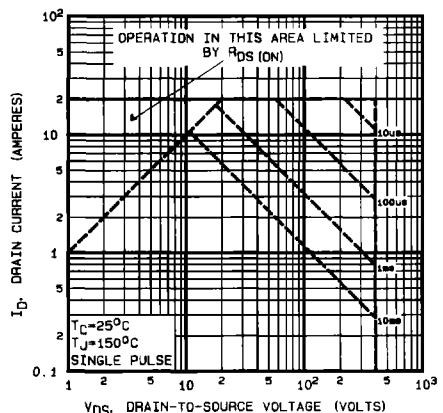


Fig. 8j - Maximum Safe Operating Area IRF330

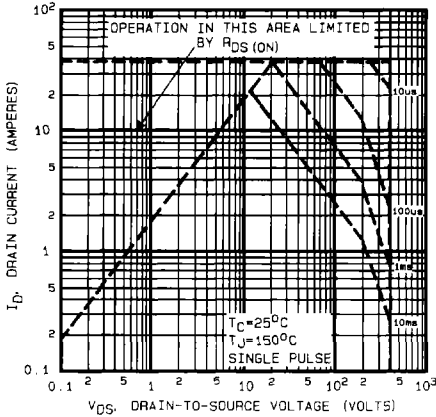


Fig. 8k - Maximum Safe Operating Area
IRF340

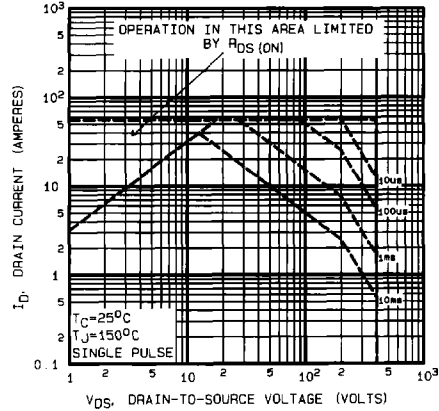


Fig. 8l - Maximum Safe Operating Area
IRF350

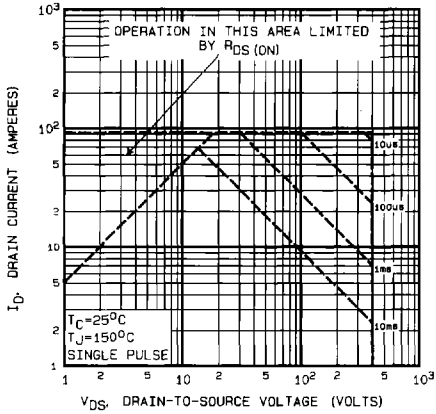


Fig. 8m - Maximum Safe Operating Area
IRF360

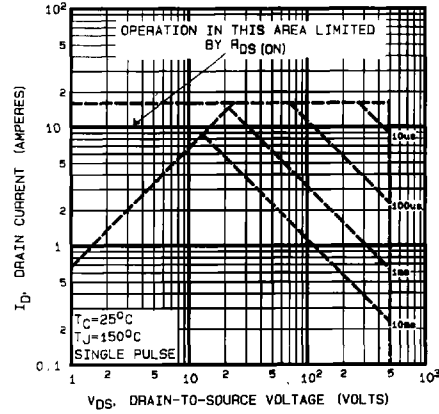


Fig. 8n - Maximum Safe Operating Area
IRF430

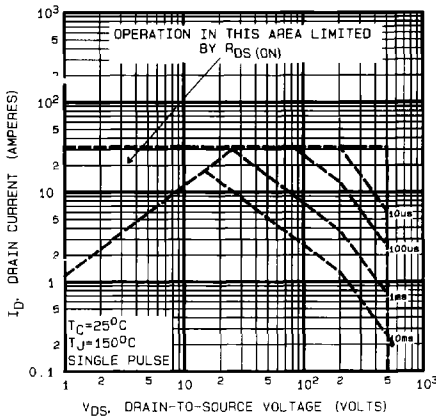


Fig. 8o. - Maximum Safe Operating Area
IRF440

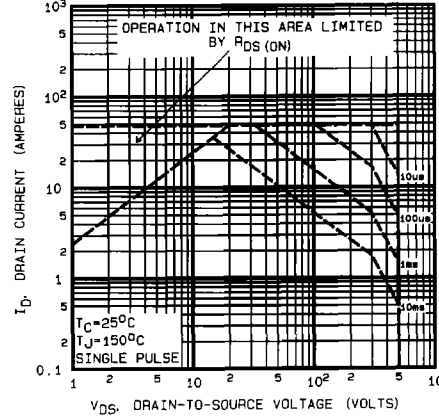


Fig. 8p - Maximum Safe Operating Area
IRF450

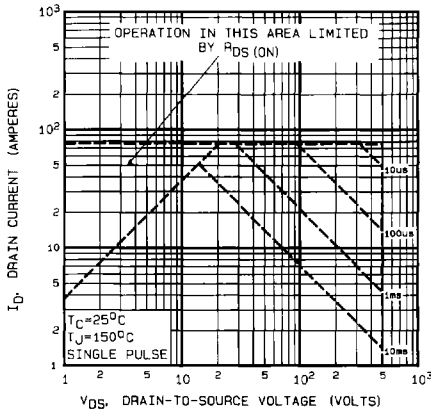


Fig. 8q - Maximum Safe Operating Area IRF460

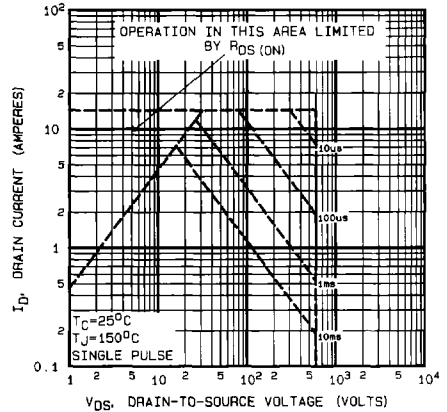


Fig. 8r - Maximum Safe Operating Area IRFAC30

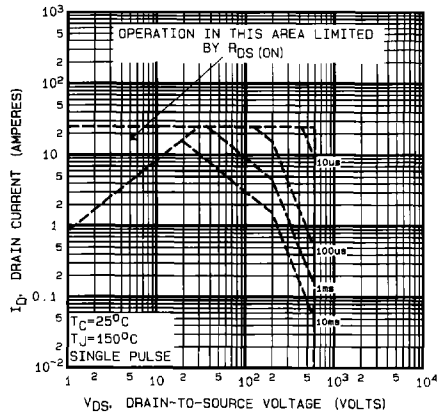


Fig. 8s - Maximum Safe Operating Area IRFAC40

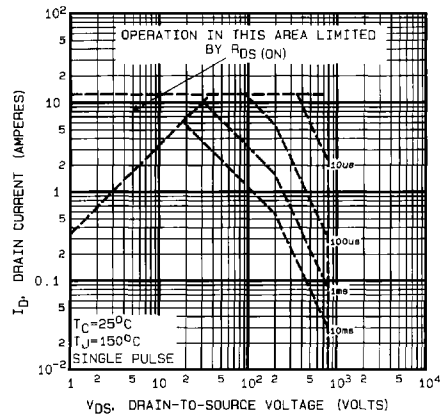


Fig. 8t - Maximum Safe Operating Area IRFAE30

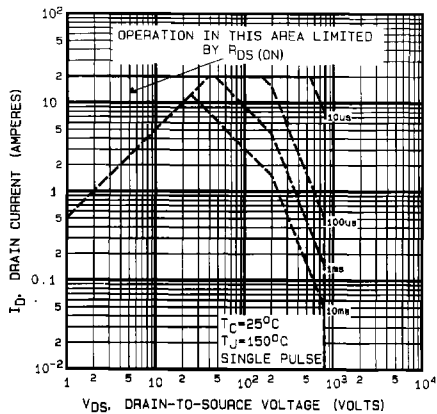


Fig. 8u - Maximum Safe Operating Area IRFAE40

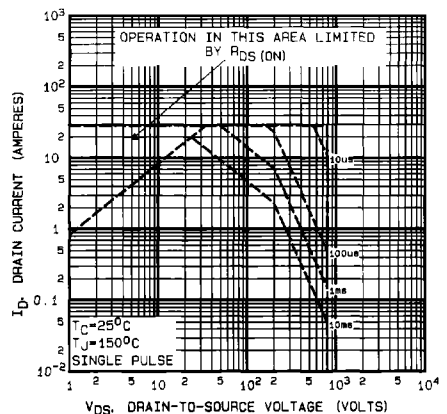


Fig. 8v - Maximum Safe Operating Area IRFAE50

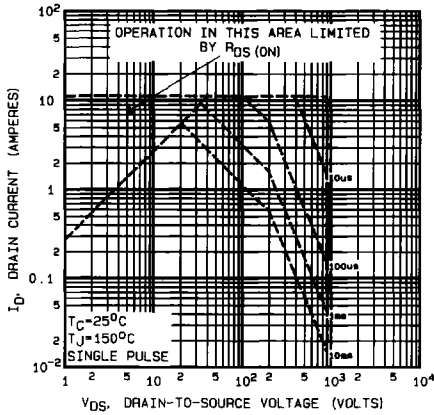


Fig. 8w – Maximum Safe Operating Area IRFAF30

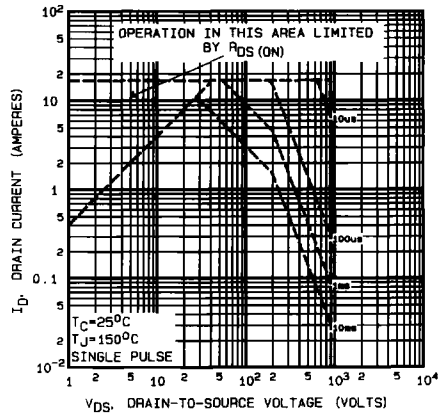


Fig. 8x – Maximum Safe Operating Area IRFAF40

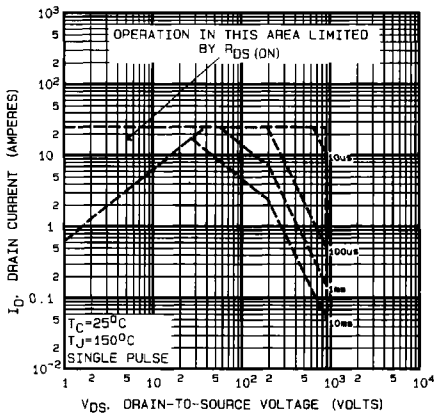


Fig. 8y – Maximum Safe Operating Area IRFAF50

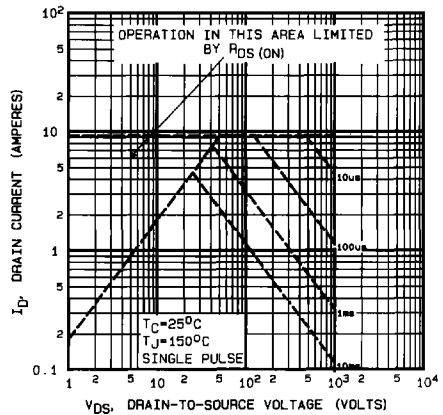


Fig. 8z – Maximum Safe Operating Area IRFAG30

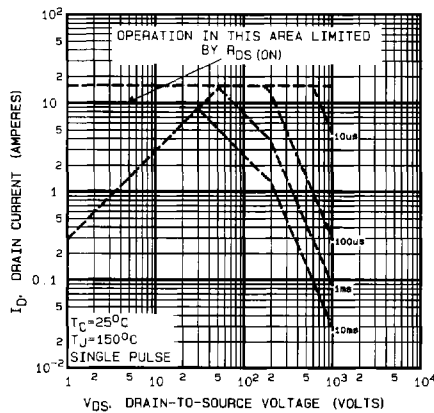


Fig. 8aa – Maximum Safe Operating Area IRFAG40

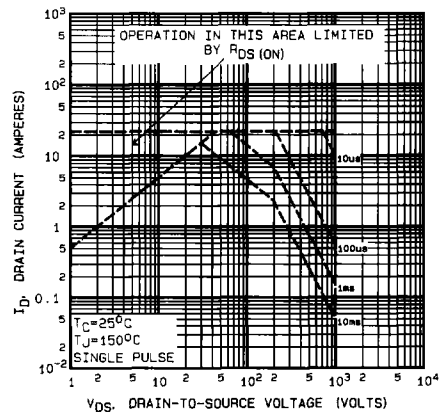


Fig. 8bb – Maximum Safe Operating Area IRFAG50

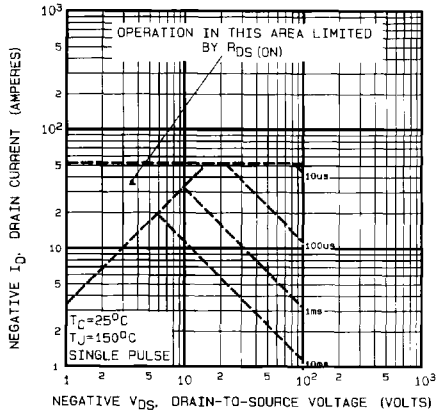


Fig. 8cc – Maximum Safe Operating Area IRF9130

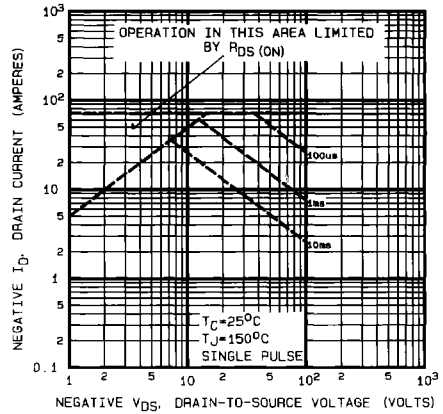


Fig. 8dd – Maximum Safe Operating Area IRF9140

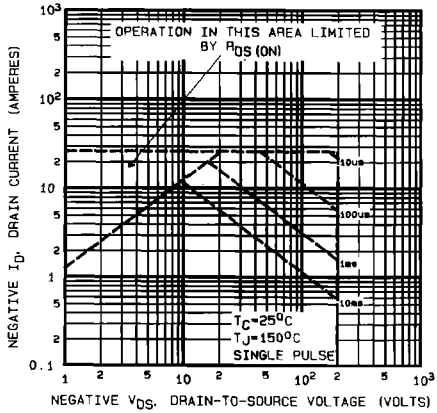


Fig. 8ee – Maximum Safe Operating Area IRF9230

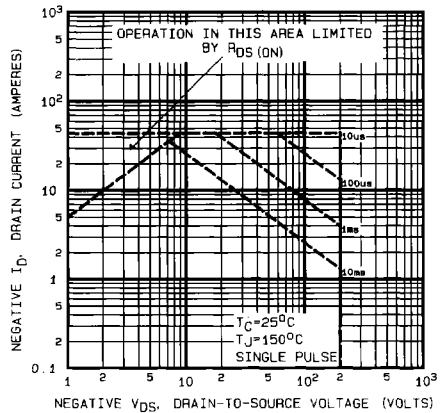


Fig. 8ff – Maximum Safe Operating Area IRF9240

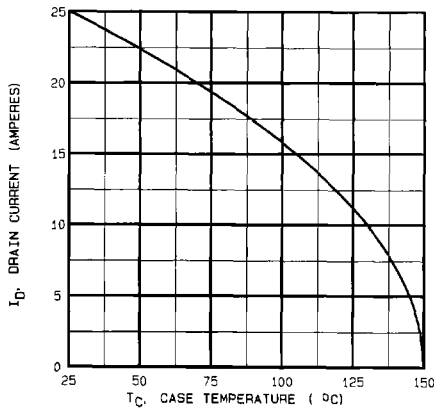


Fig. 9a – Maximum Drain Current Vs. Case Temperature IRF034

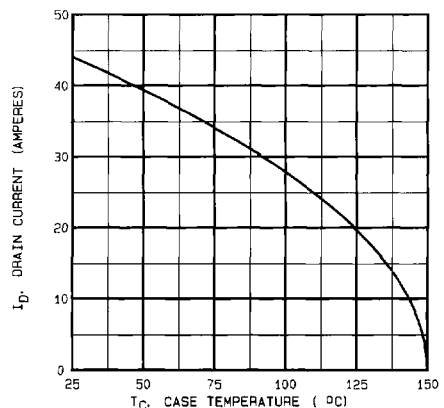


Fig. 9b – Maximum Drain Current Vs. Case Temperature IRF044

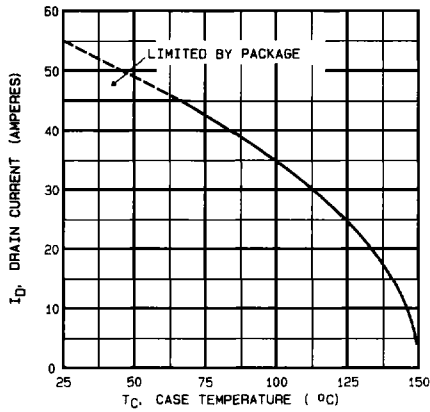


Fig. 9c - Maximum Drain Current Vs. Case Temperature IRF054

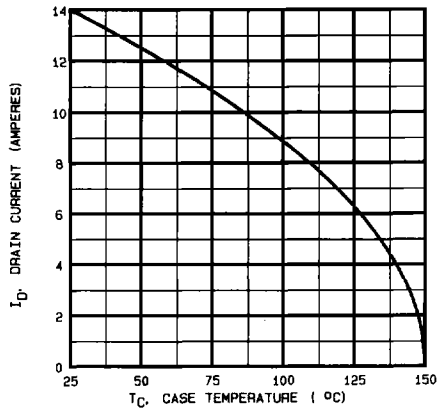


Fig. 9d - Maximum Drain Current Vs. Case Temperature IRF130

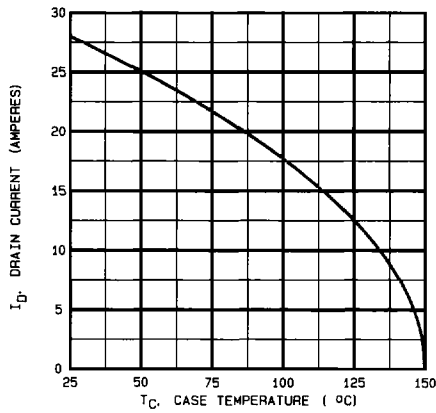


Fig. 9e - Maximum Drain Current Vs. Case Temperature IRF140

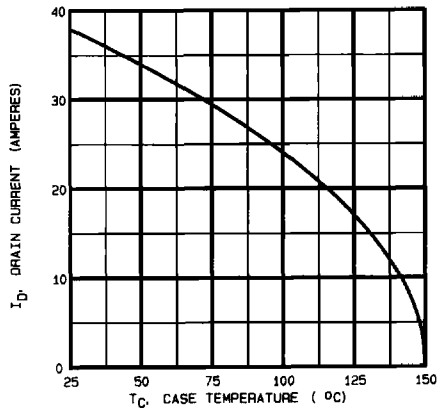


Fig. 9f - Maximum Drain Current Vs. Case Temperature IRF150

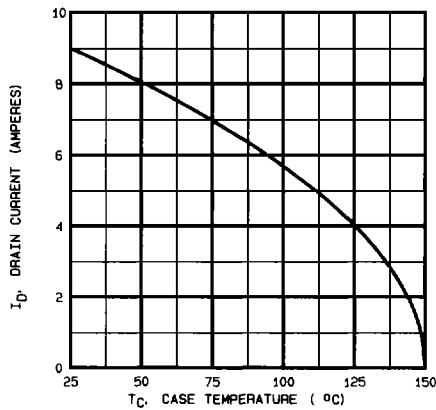


Fig. 9g - Maximum Drain Current Vs. Case Temperature IRF230

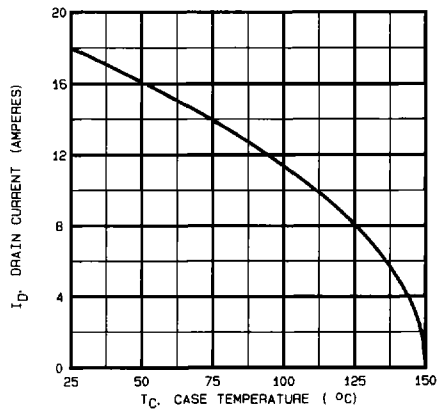


Fig. 9h - Maximum Drain Current Vs. Case Temperature IRF240

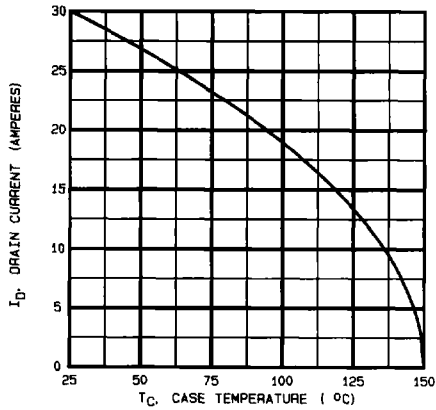


Fig. 9l – Maximum Drain Current Vs. Case Temperature IRF250

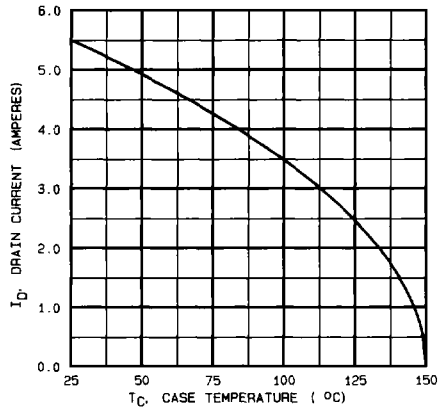


Fig. 9j – Maximum Drain Current Vs. Case Temperature IRF330

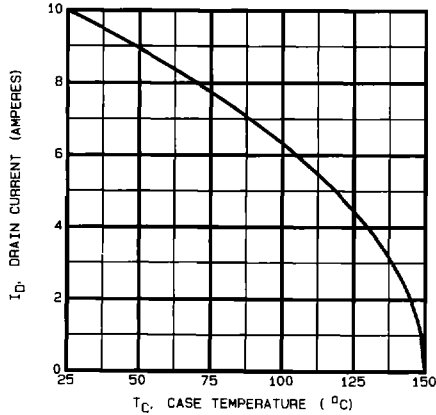


Fig. 9k – Maximum Drain Current Vs. Case Temperature IRF340

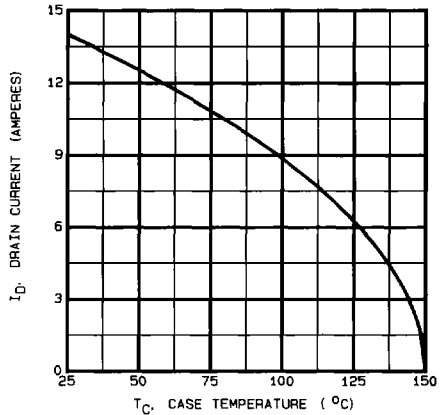


Fig. 9i – Maximum Drain Current Vs. Case Temperature IRF350

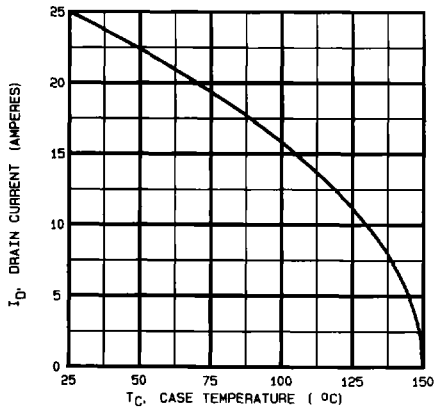


Fig. 9m – Maximum Drain Current Vs. Case Temperature IRF360

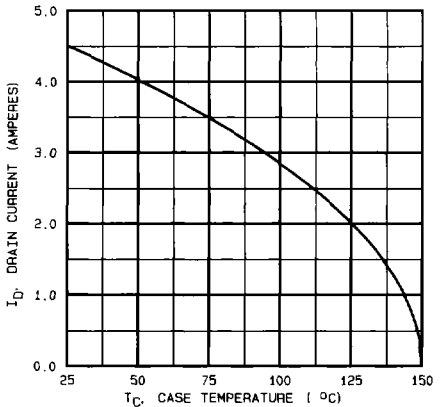


Fig. 9n – Maximum Drain Current Vs. Case Temperature IRF430

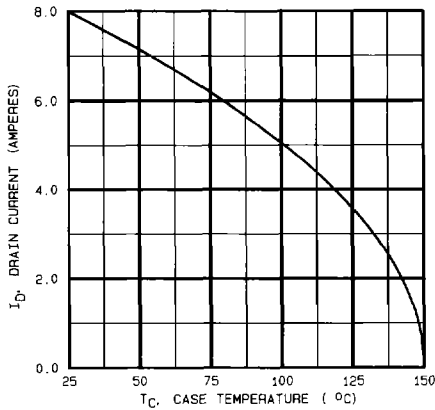


Fig. 9o - Maximum Drain Current Vs. Case Temperature
IRF440

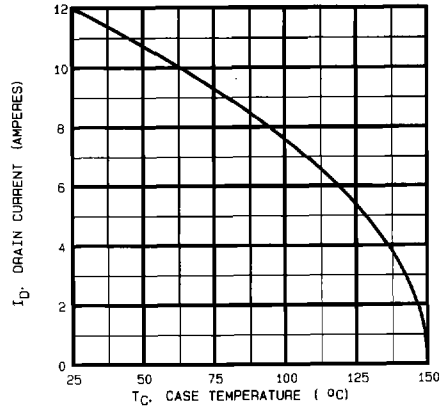


Fig. 9p - Maximum Drain Current Vs. Case Temperature
IRF450

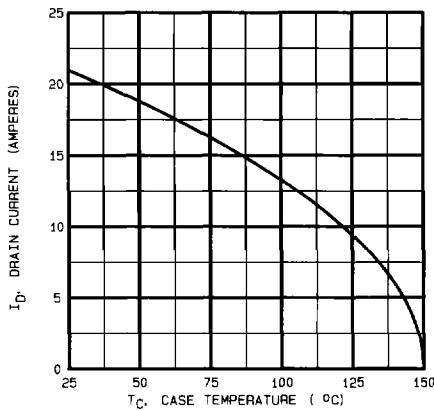


Fig. 9q - Maximum Drain Current Vs. Case Temperature
IRF460

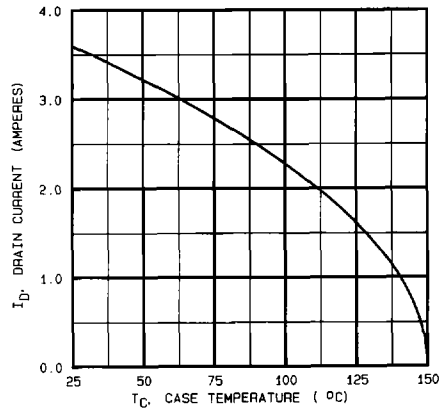


Fig. 9r - Maximum Drain Current Vs. Case Temperature
IRFAC30

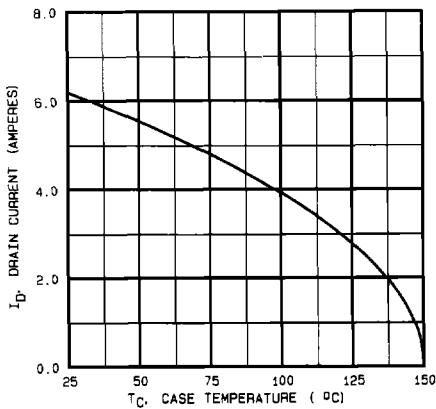


Fig. 9s - Maximum Drain Current Vs. Case Temperature
IRFAC40

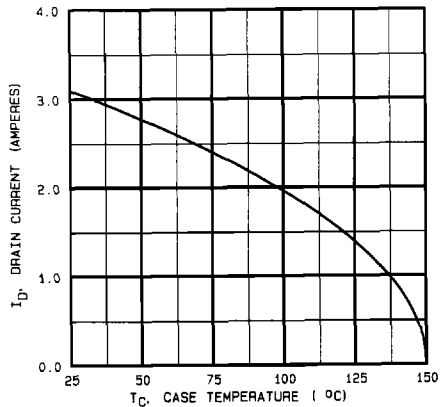


Fig. 9t - Maximum Drain Current Vs. Case Temperature
IRFAE30

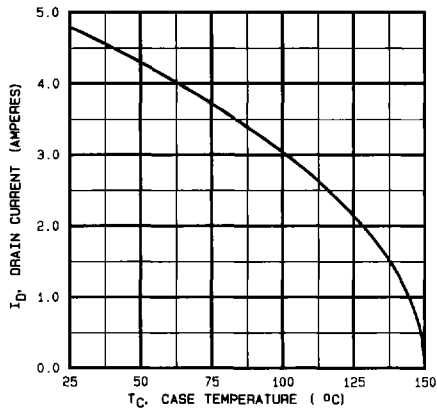


Fig. 9u – Maximum Drain Current Vs. Case Temperature IRFAE40

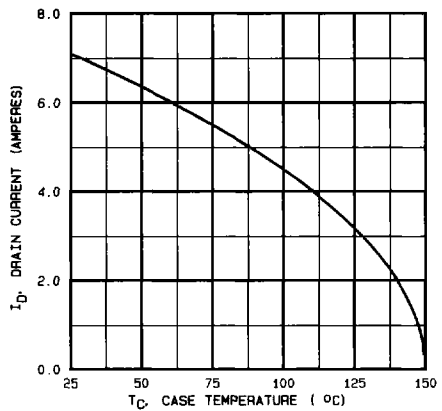


Fig. 9v – Maximum Drain Current Vs. Case Temperature IRFAE50

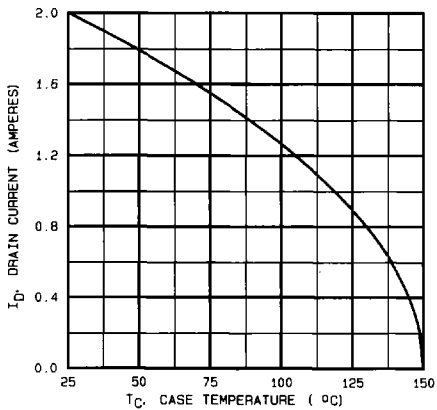


Fig. 9w – Maximum Drain Current Vs. Case Temperature IRFAF30

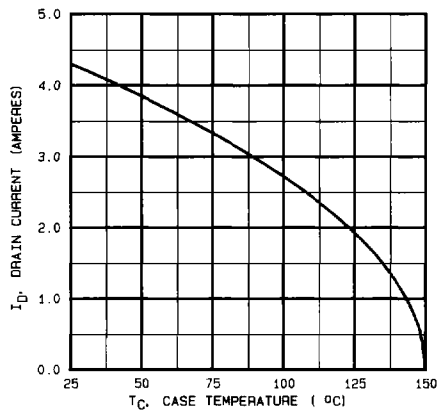


Fig. 9x – Maximum Drain Current Vs. Case Temperature IRFAF40

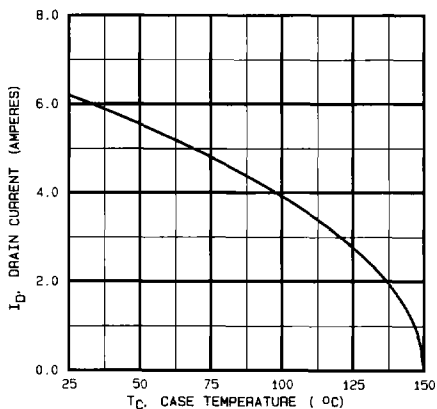


Fig. 9y – Maximum Drain Current Vs. Case Temperature IRFAF50

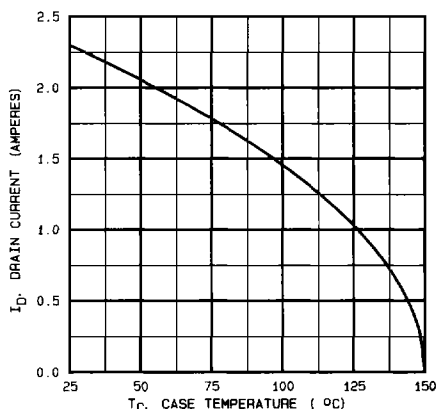


Fig. 9z – Maximum Drain Current Vs. Case Temperature IRFAG30

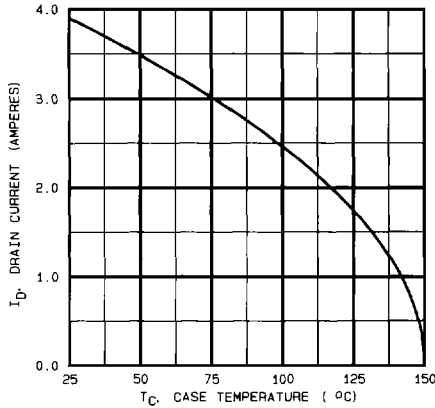


Fig. 9aa – Maximum Drain Current Vs. Case Temperature IRFAG40

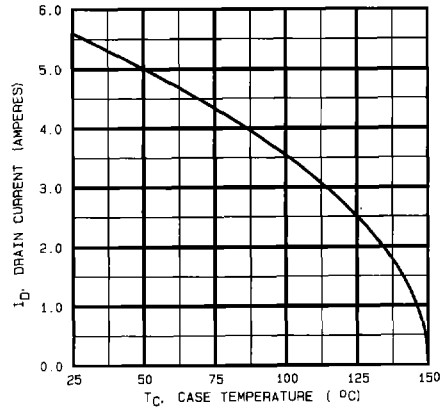


Fig. 9bb – Maximum Drain Current Vs. Case Temperature IRFAG50

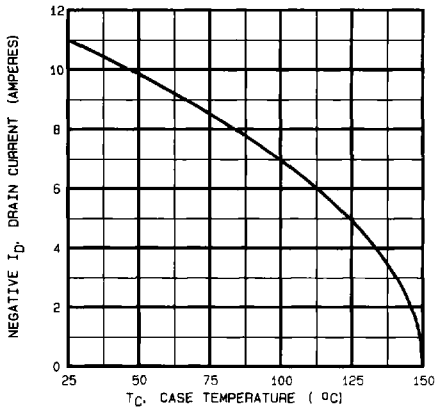


Fig. 9cc – Maximum Drain Current Vs. Case Temperature IRF9130

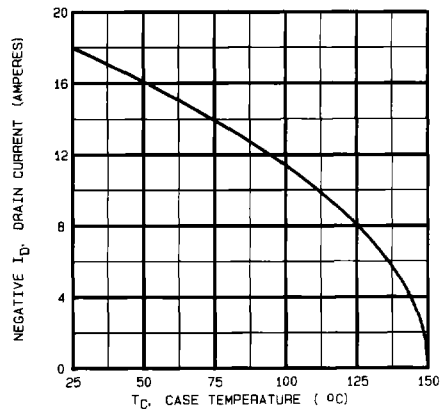


Fig. 9dd – Maximum Drain Current Vs. Case Temperature IRF9140

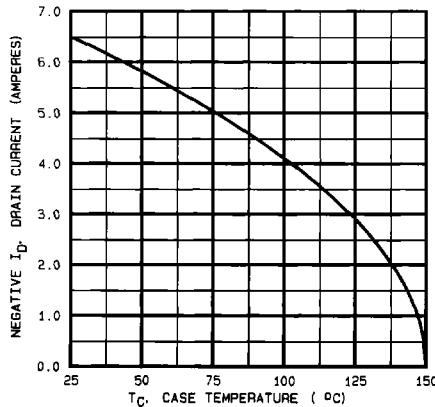


Fig. 9ee – Maximum Drain Current Vs. Case Temperature IRF9230

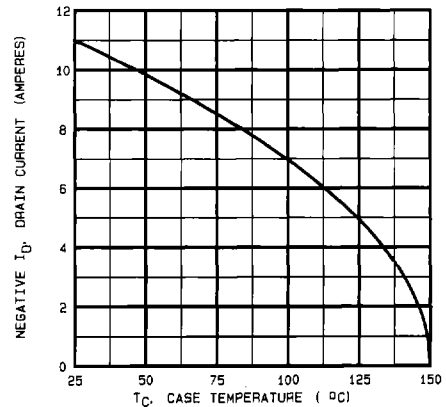


Fig. 9ff – Maximum Drain Current Vs. Case Temperature IRF9240

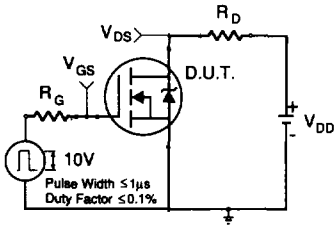


Fig. 10a - Switching Time Test Circuit N-Channel

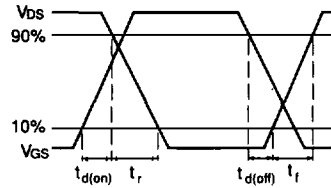


Fig. 10b - Switching Time Waveforms N-Channel

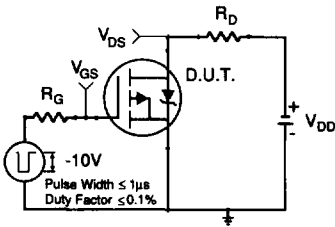


Fig. 10c - Switching Time Test Circuit P-Channel

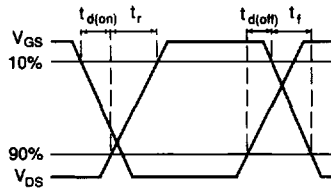


Fig. 10d - Switching Time Waveforms P-Channel



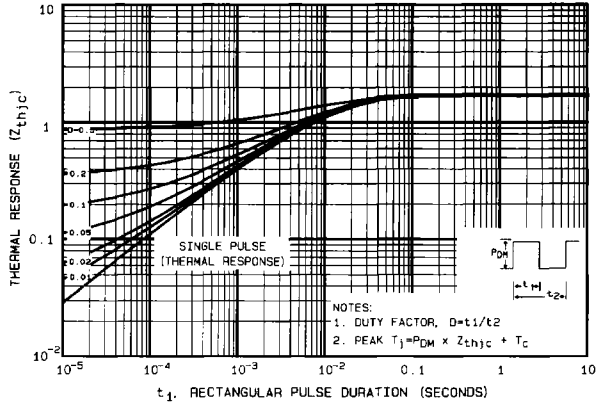


Fig. 11a - Maximum Effective Transient Thermal Impedance, Junction-to-Case Vs. Pulse Duration
IRF034, IRF130, IRF230, IRF330, IRF430, IRFAC30,
IRFAE30, IRFAF30, IRFAG30, IRF9130 & IRF9230

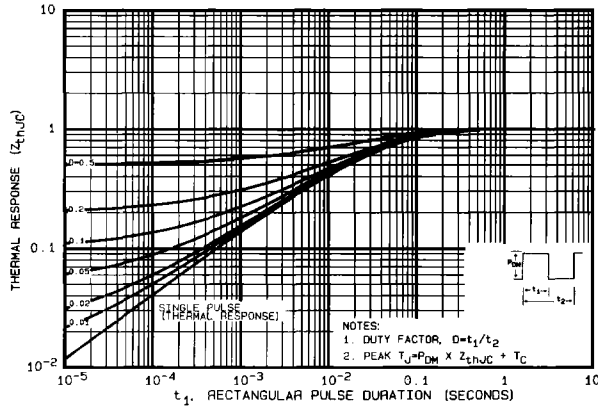


Fig. 11b - Maximum Effective Transient Thermal Impedance, Junction-to-Case Vs. Pulse Duration
IRF044, IRF140, IRF240, IRF340, IRF440, IRFAC40,
IRFAE40, IRFAF40, IRFAG40, IRF9140 & IRF9240

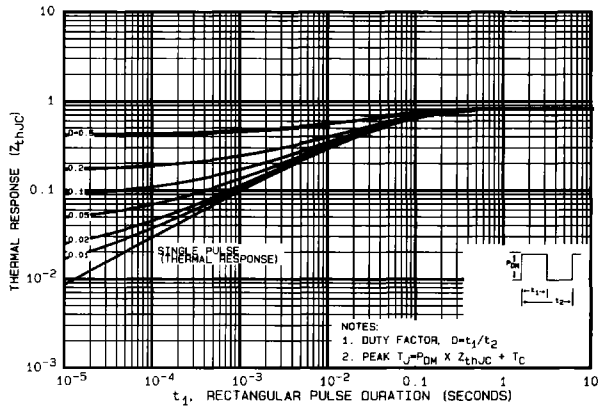


Fig. 11c - Maximum Effective Transient Thermal Impedance, Junction-to-Case Vs. Pulse Duration
IRF054, IRF150, IRF250, IRF350, IRF450, IRFAC50,
IRFAE50, IRFAF50, & IRFAG50

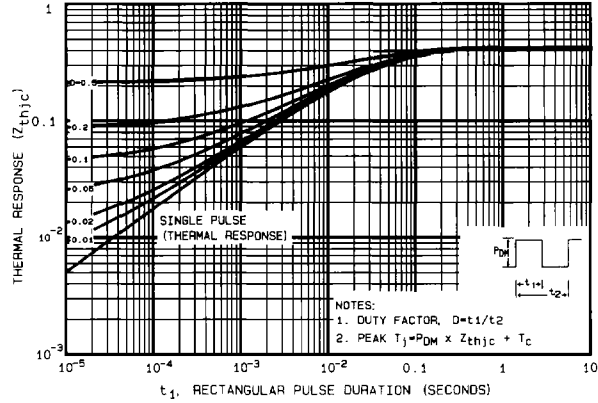


Fig. 11d – Maximum Effective Transient Thermal Impedance, Junction-to-Case Vs. Pulse Duration IRF360 & IRF460

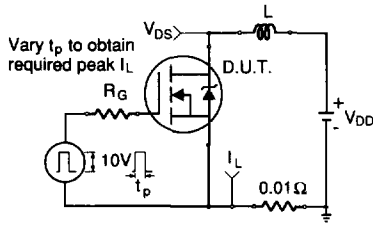


Fig. 12a – Unclamped Inductive Test Circuit N-Channel

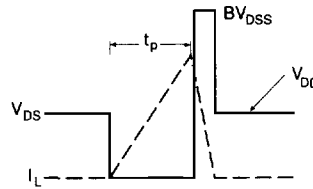


Fig. 12b – Unclamped Inductive Waveforms N-Channel

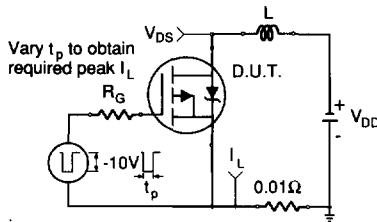


Fig. 12c – Unclamped Inductive Test Circuit P-Channel

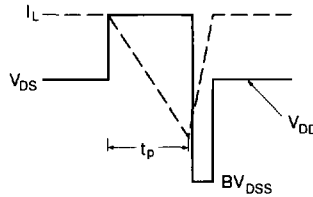


Fig. 12d – Unclamped Inductive Waveforms P-Channel

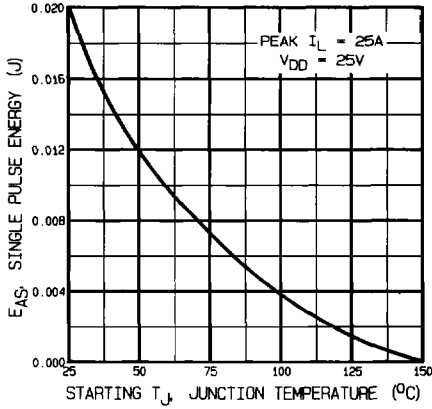


Fig. 13a – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF034

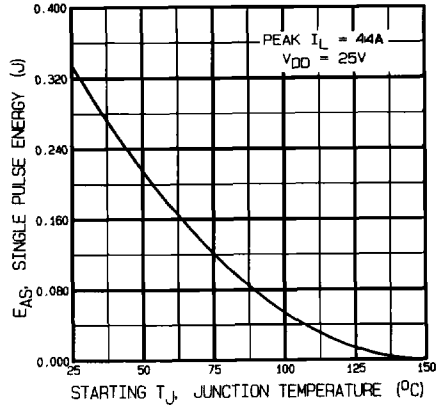


Fig. 13b – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF044

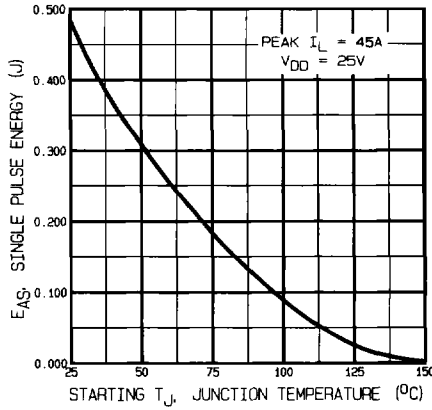


Fig. 13c – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF054

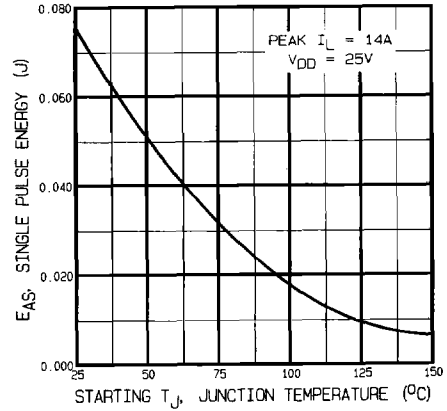


Fig. 13d – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF130

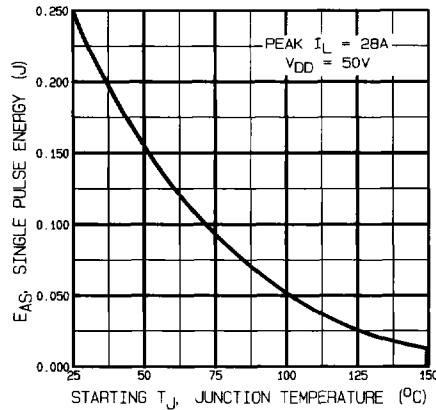


Fig. 13e – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF140

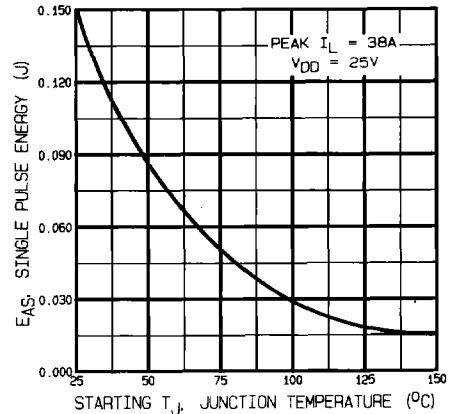


Fig. 13f – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF150

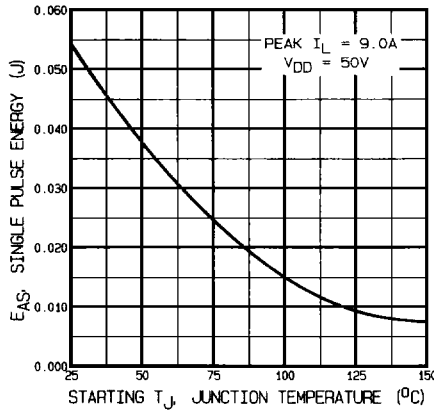


Fig. 13g - Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF230

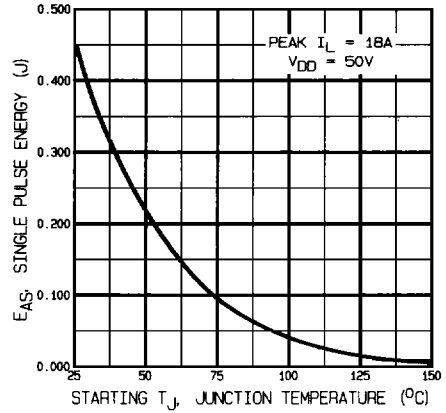


Fig. 13h - Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF240

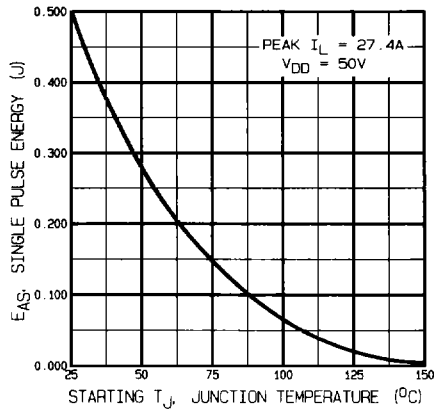


Fig. 13i - Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF250

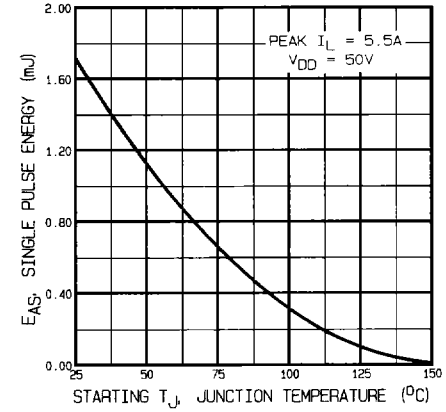


Fig. 13j - Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF330

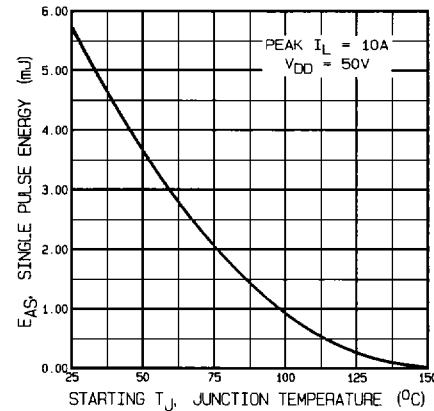


Fig. 13k - Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF340

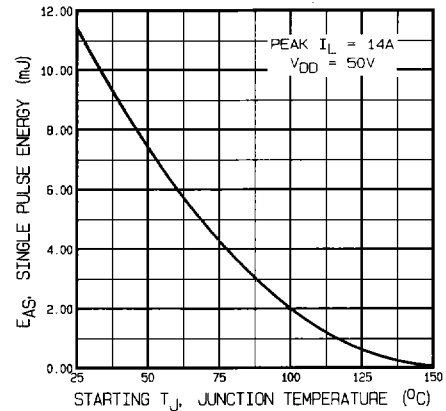


Fig. 13l - Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF350

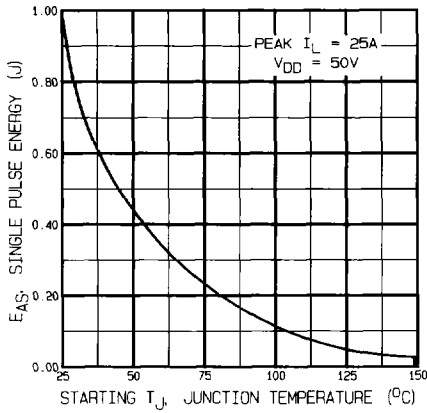


Fig. 13m – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF360

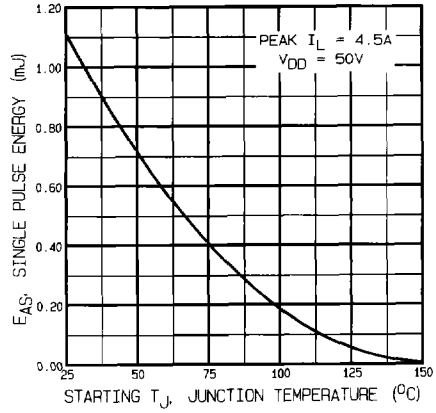


Fig. 13n – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF430

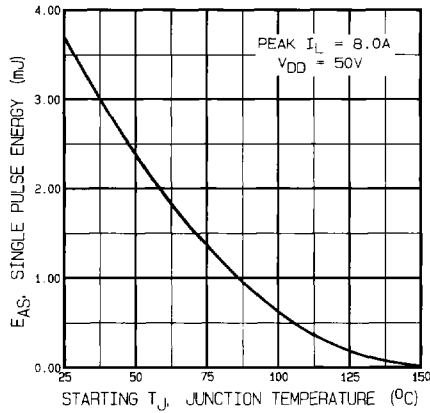


Fig. 13o – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF440

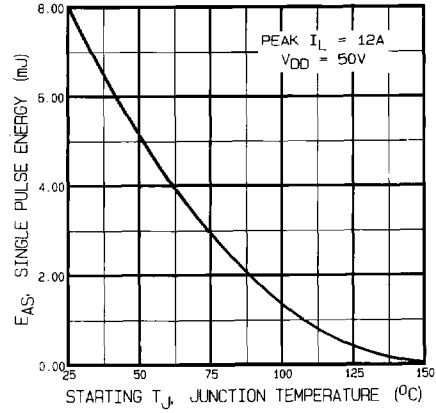


Fig. 13p – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF450

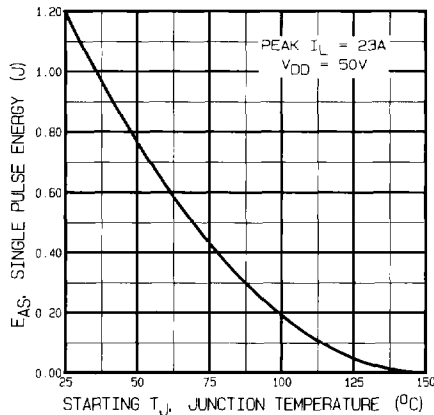


Fig. 13q – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF460

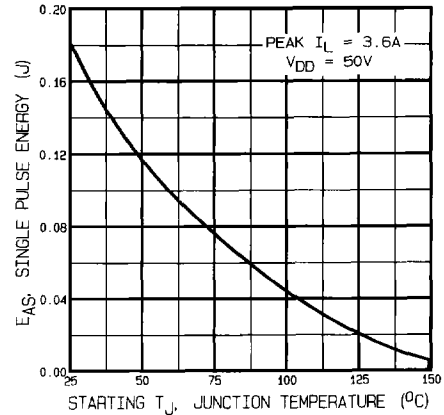


Fig. 13r – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAC30

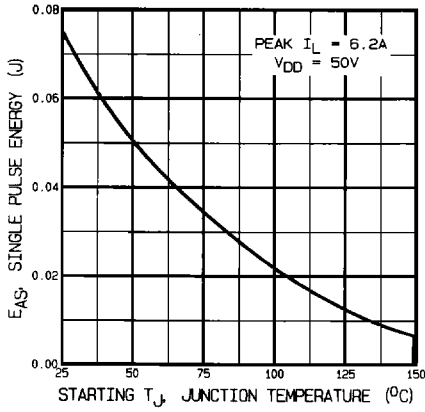


Fig. 13s – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAC40

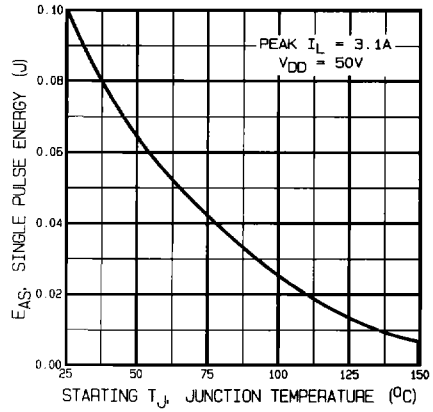


Fig. 13t – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAE30

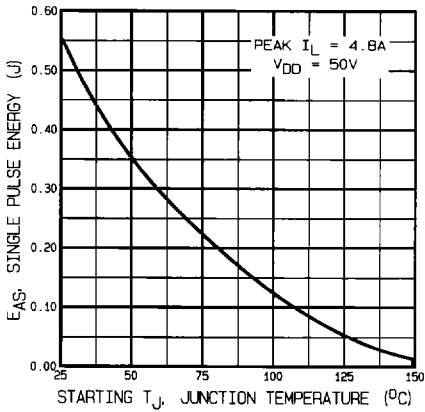


Fig. 13u – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAE40

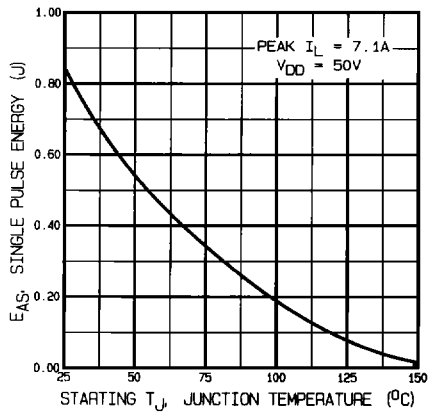


Fig. 13v – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAE50

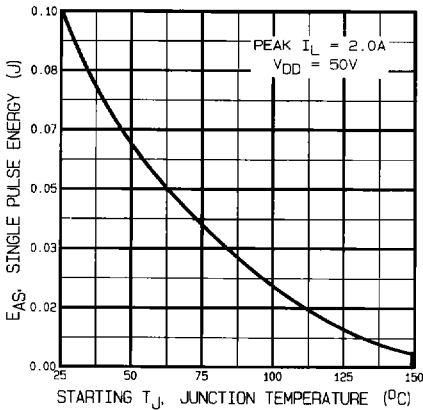


Fig. 13w – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAF30

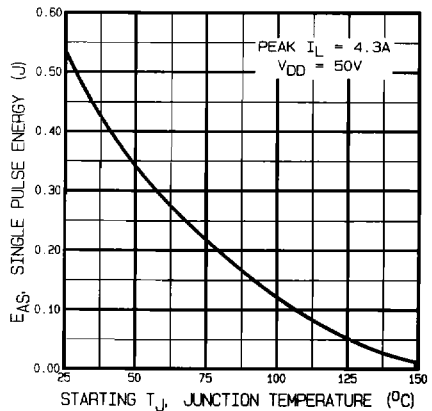


Fig. 13x – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAF40

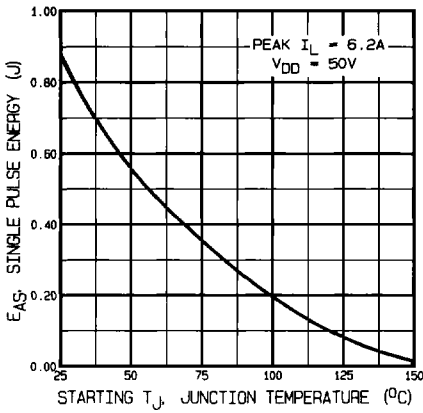


Fig. 13y – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAF50

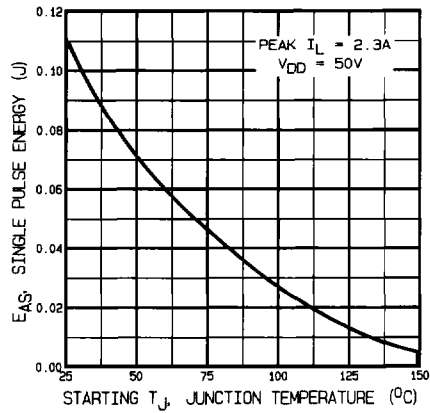


Fig. 13z – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAG30

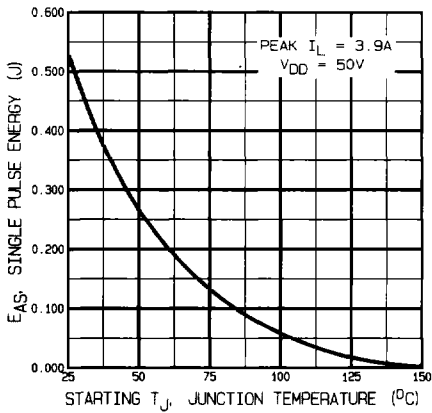


Fig. 13aa – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAG40

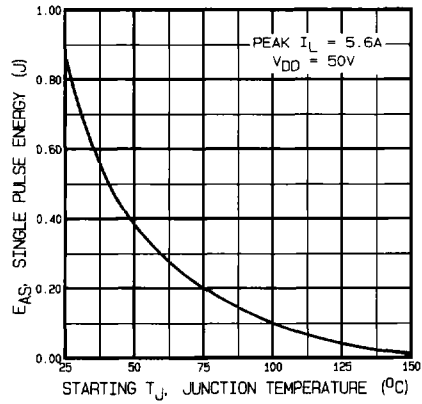


Fig. 13bb – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRFAG50

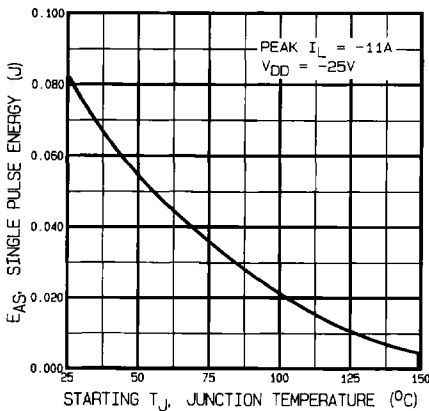


Fig. 13cc – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF9130

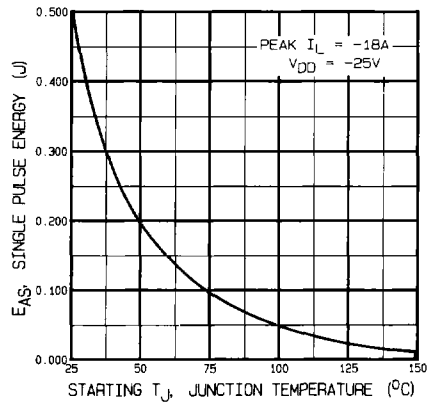


Fig. 13dd – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF9140

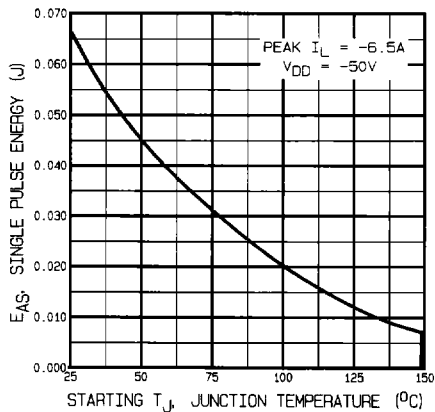


Fig. 13ee – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF9230

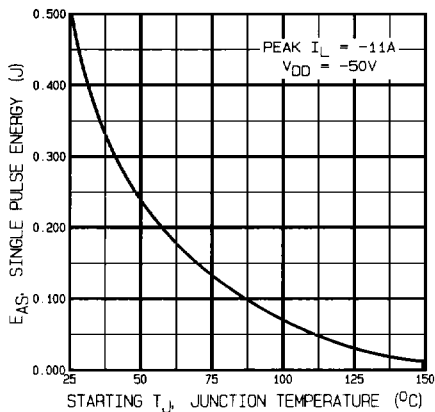


Fig. 13ff – Maximum Avalanche Energy Vs. Starting Junction Temperature, IRF9240

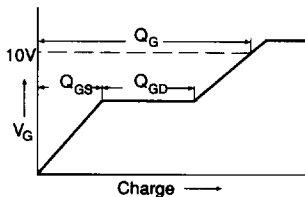


Fig. 14a – Basic Gate Charge Waveform N-Channel

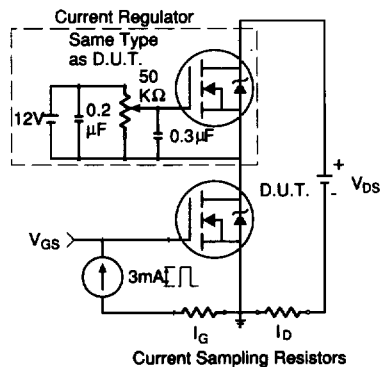


Fig. 14b – Basic Gate Charge Waveform N-Channel

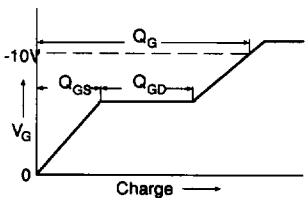


Fig. 14c – Gate Charge Test Circuit P-Channel

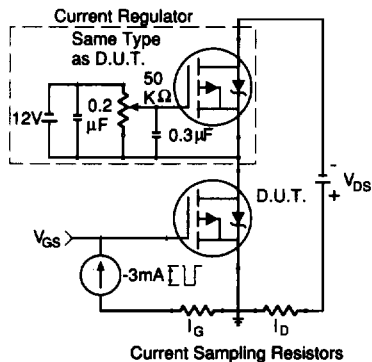


Fig. 14d – Basic Gate Charge Waveform P-Channel

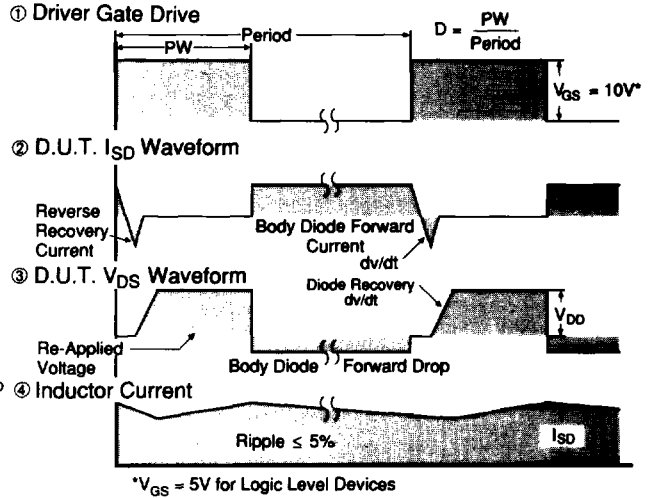
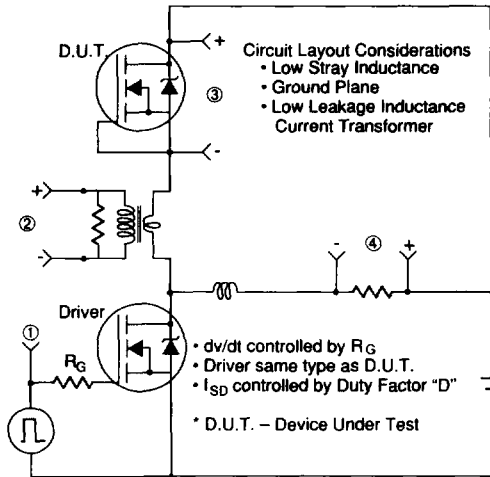


Fig. 15a - Peak Diode Recovery dv/dt Test Circuit N-Channel

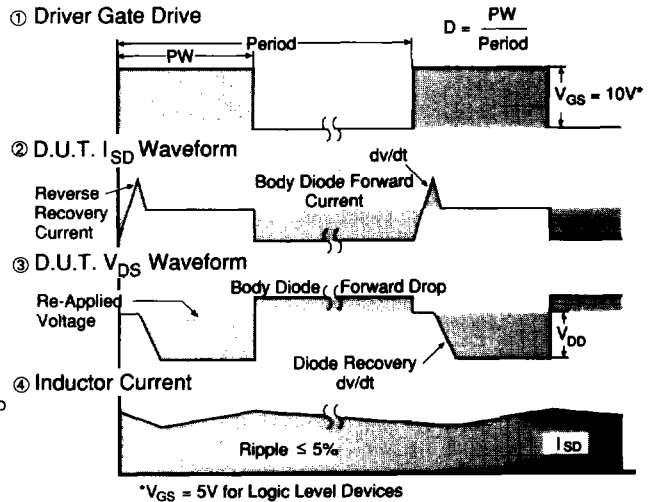
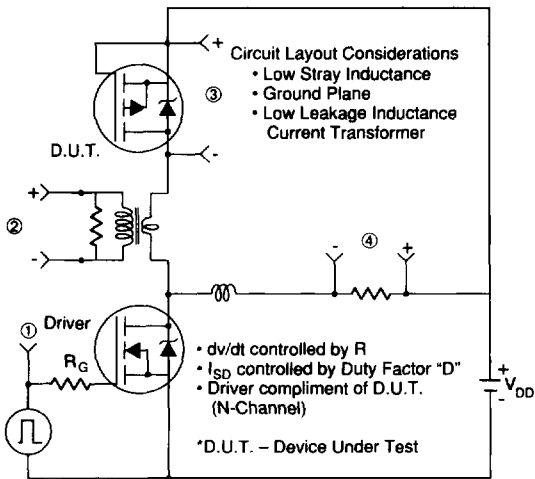


Fig. 15b - Peak Diode Recovery dv/dt Test Circuit P-Channel